JAEGER ELEKTRONIK

SEMICON 1997

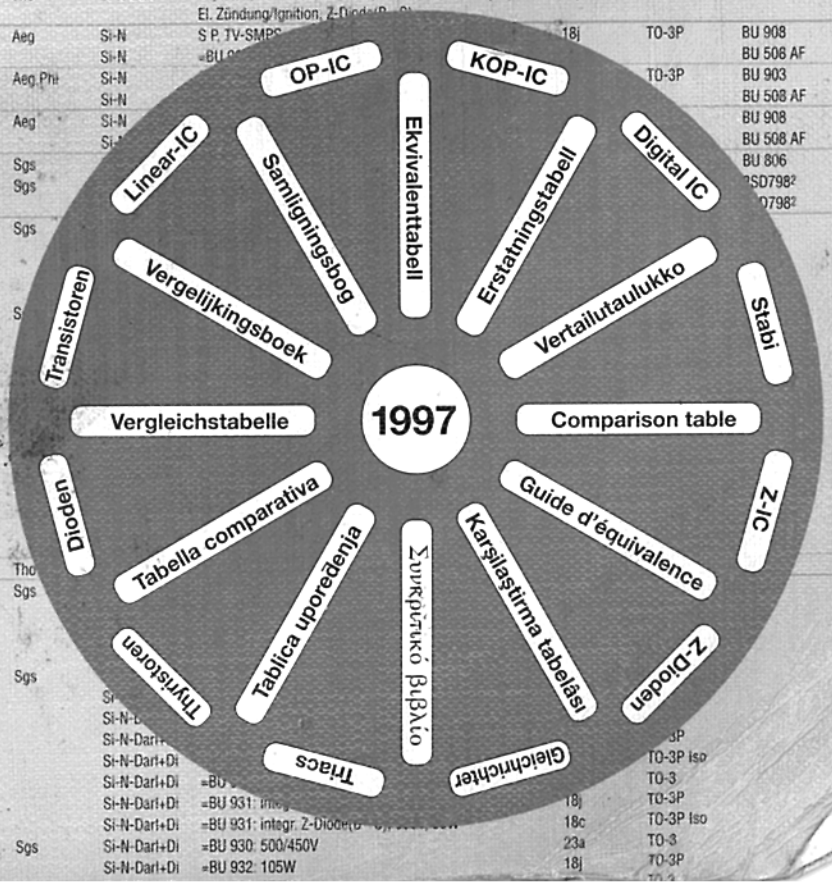
Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	International
K 427-600A,B	Phi	MOS-N-FET-e	VFET, 600/30V, 45W, 80/275ns(2,8A) A: 4,3/17A, <1Ω(6,5A), B: 3,9/16A, <1,2Ω(6,5A)		16c	SOT-199		BUK 727-600, 2SK1463, 2SK1684, 2SK1859
K 428-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 45W, 120/410ns(2,9A) A: 6,8/27A, <0,4Ω(8A), B: 6,1/24A, <0,5Ω(8A)		16c	SOT-199		2SK1206, 2SK1523, 2SK1696, 2SK1832
K 428-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 45W, 160/450ns(2,6A) A: 3,4/14A, <1,5Ω(4A), B: 3/12A, <2Ω(4A)		16c	SOT-199		2SK809A, 2SK1463, 2SK1684, 2SK1859
K 428-1000A,B	Phi	MOS-N-FET-e	VFET, 1000/30V, 45W, 160/450ns(2,5A) A: 2,9/12A, <2Ω(3,5A), B: 2,6/10A, <2,6Ω(3,5A)		16c	SOT-199		BUK 426-1000, 2SK1770
K 436-50A,B	Phi	MOS-N-FET-e	=BUK 426-50A,B: A=50/200A, B=46/184A, 125W		18p	TO-3P		BUZ 346, 2SK1297, 2SK1379, 2SK1514
K 436-60A,B	Phi	MOS-N-FET-e	=BUK 426-60A,B: A=50/200A, B=46/184A, 125W		18p	TO-3P		2SK1297, 2SK1379, 2SK1514, 2SK2096
K 436-100A,B	Phi	MOS-N-FET-e	=BUK 426-100A,B: A=33/132A, B=31/124A, 125W		18p	TO-3P		BUZ 345, 2SK850, 2SK906, 2SK1429, ++

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	International
KSV 3100 ACN-....	Sam	A/D-D/A-IC	8-Bit A/D- + 10-Bit D/A-Converter		40-DIP			-
KSV 3110(CN-....)	Sam	A/D-D/A-IC	8 Bit A/D- + 10 Bit D/A-Conv., Video, TTL In/Out		40-DIP			-
KSV 3208(CN)	Sam	A/D-IC	8 Bit, hi-speed, TV, Video, 20Msps, TTL In/Out		28-DIP			-
KSV 3310	Sam	D/A-IC	10 Bit, TV, Video, 20MHz		28-DIP			-
KSV 3404	Sam							
KSY 13	Sie							

KT

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	Inter
KT								
KT								
KT 208(A....V)	GUS							
KT 209(A....V)	GUS							
KT 814 A,B,G,V	GUS							
KT 815 A,B,G,V	GUS							
KT 816 A,B,G,V	GUS							
KT 817 A,B,G,V	GUS							
KT 818 A,B,G,V	GUS							
KT 819 A,B,G,V	GUS							
KT 3030	Sam							
KT 3031	Sam							
KT 3032	Sam							
KT 3033	Sam							
KT 3040 J	Sam							
KT 3054 J	Sam							
KT 3064 J	Sam							
KT 3107(A....V)	GUS							
KT 3170 J,N	Sam							
KT 5116 J	Sam							
KT 8518	Sam							
KT 8520	Sam							
KT 8521	Sam							
KT 8554(J)	Sam							
KT 8555(J)	Sam							
KT 8557(J)	Sam							
KT 8592(N)	Sam							
KT 8593(N)	Sam							
KTA 200	Kec							
KTA 473	Kec							
KTA 940	Kec							
KTA 950	Kec							
KTA 968(A)	Kec							
KTA 1001	Kec							
KTA 1015	Kec							
KTA 1021	Kec							
KTA 1023	Kec							
KTA 1024	Kec							
KTA 1070	Kec							
KTA 1270	Kec							
KTA 1271	Kec							
KTA 1272	Kec							
KTA 1273	Kec							
KTA 1274	Kec							

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	Inter
BU 806	Phi,Sgs,Tix	Si-N-Darl+Di	TV-HA, 400/200V, 8/15A, 60W, sat<1,5V(5A)		17j	TO-220	BU 806	17j
BU 806 AF		Si-N-Darl+Di	=BU 806: Iso		17c			
BU 806 FI	Tho	Si-N-Darl+Di	=BU 806: Iso, 30W		17c	TO-220Iso		
BU 807	Phi,Sgs,Tix	Si-N-Darl+Di	=BU 806: 330/150V		17j	TO-220	BU 806	17j
BU 807 FI	Tho	Si-N-Darl+Di	=BU 807: Iso, 30W		17c	TO-220Iso		
BU 808 DFI [SGS]	Sgs	Si-N-Darl+Di	=BU 808FI: integr. Damper-Diode		18c	TO-3P Iso		
BU 808 FI [SGS]	Sgs	Si-N-Darl	CTV-HA, 1400/700V, 5/10A, 50W, hFE>25,sat<1,6V(5A)		18c	TO-3P Iso		
BU 808 [Philips]	Phi	Si-N	3Ph.-Motor Drv, 1500/700V, 12/20A, 160W,sat<1V(9V)		23a	TO-3		
BU 810	Sgs	Si-N-Darl+Di	S P, 600/400V, 7/10A, 75W, <0,6/2µs, sat<3V(7A)		17j	TO-220	2SD798	17j
BU 824	Phi	Si-N-Darl+Di	S P, 650/375V, 0,5/1A, 12,5W, hFE>325, <1/2,5µs		13h	TO-202		
BU 826	Phi	Si-N-Darl+Di	S P, 800/375V, 6/8A, 125W, <1,3/2,2µs,sat<2,5V(4A)		18j	TO-3P	BU 826	18j
BU 826 A		Si-N-Darl+Di	=BU 826: 1000/400V		18j	TO-3P		
BU 900	Tho	Si-N-Darl	Tripleton, 650/400V, 8A, 70W, hFE>7000, sat<4V(3A) El. Zündung/Ignition, Z-Diode/		17j	TO-220		
BU 902	Aeg	Si-N	S P, TV-SMPS		18j	TO-3P	BU 908	18j
BU 902 F		Si-N	=BU				BU 508 AF	16c
BU 903	Aeg,Phi	Si-N				TO-3P	BU 903	18j
BU 903 F		Si-N					BU 508 AF	16c
BU 908	Aeg	Si-N					BU 908	18j
BU 908 AF		Si-N					BU 508 AF	16c
BU 910	Sgs						BU 806	17j
BU 911	Sgs						2SD798²	17j
BU 912							2SD798²	17j
BU 920	Sgs							
BU 920 P								
BU 920 PFI								
BU 920 T								
BU 921	S							
BU 921 P								
BU 921 PFI								
BU 921 T								
BU 921 ZP								
BU 921 ZPFI								
BU 921 ZT								
BU 921 ZTFI								
BU 922								
BU 922 P								
BU 922 PFI								
BU 922 T								
BU 926	Tho							18j
BU 930	Sgs							
BU 930 P								
BU 930 Z								
BU 930 ZP								
BU 931	Sgs	Si-N-Darl+Di	=BU 930: 500/450V		18j	TO-3P		
BU 931 P		Si-N-Darl+Di	=BU 930: 105W		18j	TO-3P iso		
BU 931 RPFI		Si-N-Darl+Di				TO-3P iso		
BU 931 Z		Si-N-Darl+Di	=BU			TO-3		
BU 931 ZP		Si-N-Darl+Di	=BU 931:		18j	TO-3P		
BU 931 ZPFI		Si-N-Darl+Di	=BU 931: integr. Z-Diode(		18c	TO-3P Iso		
BU 932	Sgs	Si-N-Darl+Di	=BU 930: 500/450V		23a	TO-3		
BU 932 P		Si-N-Darl+Di	=BU 932: 105W		18j	TO-3P		



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Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
BZY 94/C10....75	Phi	Z-Di	10...75V, 5%, 0,4W	31a	DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5240...67,++
BZY 95/C10....75	Aeg,Phi	Z-Di	10...75V, 5%, 1,5W	34a	DO-1	Z-Diode V	31a	BZW22/..., BZX61/..., ZY..., 2N5925...46
BZY 96/C4V7....10	Phi	Z-Di	4,7...10V, 5%, 1,5W	34a	DO-1	Z-Diode V	31a	BZW22/..., BZX61/..., ZY..., 1N5917...25,++
BZY 97/C3V3....200	Sie,Tho	Z-Di	3,3...200V, 5%, 1,5W	31a	SOD-22	Z-Diode V	31a	BZW22/..., BZX61/..., ZY..., 1N5913...56,++
BZZ								
BZZ 10	Phi	Z-Di	6,15V, 10%, 0,28W	31a	DO-7	Z-Diode 6,2V	31a	BZX55/..., BZX79/..., ZPD..., 1N5233...,++
BZZ 11	Phi	Z-Di	=BZZ 10: 6,55V	31a	DO-7	Z-Diode 6,8V	31a	›BZZ 10
BZZ 12	Phi	Z-Di	=BZZ 10: 7,25V	31a	DO-7	Z-Diode 7,5V	31a	›BZZ 10
BZZ 13	Phi	Z-Di	=BZZ 10: 8,05V	31a	DO-7	Z-Diode 8,2V	31a	›BZZ 10
BZZ 14	Phi	Z-Di	5,6V, 5%, 10W(Tc=50°)	32a	DO-4			BZX 98/C5V6
BZZ 15	Phi	Z-Di	=BZZ 14: 6,2V	32a	DO-4			BZX 98/C6V2
BZZ 16	Phi	Z-Di	=BZZ 14: 6,8V	32a	DO-4			BZX 98/C6V8
BZZ 17	Phi	Z-Di	=BZZ 14: 7,5V	32a	DO-4			BZX 98/C7V5
BZZ 18	Phi	Z-Di	=BZZ 14: 8,2V	32a	DO-4			BZX 98/C8V2
BZZ 19	Phi	Z-Di	=BZZ 14: 9,1V	32a	DO-4			BZX 98/C9V1
BZZ 20	Phi	Z-Di	=BZZ 14: 10V	32a	DO-4			BZX 98/C10
BZZ 21	Phi	Z-Di	=BZZ 14: 11V	32a	DO-4			BZX 98/C11
BZZ 22	Phi	Z-Di	=BZZ 14: 12V	32a	DO-4			BZX 98/C12
BZZ 23	Phi	Z-Di	=BZZ 14: 13V	32a	DO-4			BZX 98/C13
BZZ 24	Phi	Z-Di	=BZZ 14: 15V	32a	DO-4			BZX 98/C15
BZZ 25	Phi	Z-Di	=BZZ 14: 16V	32a	DO-4			BZX 98/C16
BZZ 26	Phi	Z-Di	=BZZ 14: 18V	32a	DO-4			BZX 98/C18
BZZ 27	Phi	Z-Di	=BZZ 14: 20V	32a	DO-4			BZX 98/C20
BZZ 28	Phi	Z-Di	=BZZ 14: 22V	32a	DO-4			BZX 98/C22
BZZ 29	Phi	Z-Di	=BZZ 14: 24V	32a	DO-4			BZX 98/C24
C								
C....	JAP	....-N	›2SC...., z.B./e.g. "C1398"=2SC1398 ‹	Japantypen				
C....	Sam	....-N	›KSC...., z.B./e.g. "C1009"=KSC1009 ‹	Samsung				
C....	Nec	IC	›µPC.... (NEC !)					
C		N-FET	=2SK1375 (SMD-Marking)	35(2mm)	SOT-323			›2SK1375
C		GaAs-N-FET	=2SK649 (Marking)	51				›2SK649
C		C-Di	=HVR 17 (SMD-Marking)	71(2,7mm)	SOD-123			›HVR 17
C		Si-Di	=MA 2S784 (SMD-Marking)	71(1,7mm)	SOD-323			›MA 784
C 1		Si-Di	=HSM 88(A)S (SMD-Marking)	35	SOT-23			›HSM 88(A)S
C 1		Si-Di	=HSM 88(A)SR(SMD-Marking)	35	SOT-23			›HSM 88(A)SR
C 1		Si-Di	=1SS352 (SMD-Marking)	71(1,7mm)	SOD-323			›1SS352
C 1		Si-Di	=1SS368 (SMD-Marking)	71(1,3mm)				›1SS368
C 1(p)		Si-P	=BCW 29 (SMD-Marking)	35	SOT-23			›BCW 29
C 1		Si-N	=BFS 38A (SMD-Marking)	35(2mm)	SOT-323			›BFS 38A
C 1 G		Si-N	=KSC 1632-G (SMD-Marking)	35	SOT-23			›KSC 1632
C 1 G		Si-N	=HN 1C01F-GR (SMD-Marking)	46	SOT-163			›HN 1C01F
C 1 G		Si-N	=HN 1C01FU-GR (SMD-Marking)	46(2mm)	SOT-363			›HN 1C01FU
C 1 L		Si-N	=KSC 1632-L (SMD-Marking)	35	SOT-23			›KSC 1632
C 1 O		Si-N	=KSC 1632-O (SMD-Marking)	35	SOT-23			›KSC 1632
C 1 Y		Si-N	=KSC 1632-Y (SMD-Marking)	35	SOT-23			›KSC 1632
C 1 Y		Si-N	=HN 1C01F-Y (SMD-Marking)	46	SOT-163			›HN 1C01F
C 1 Y		Si-N	=HN 1C01FU-Y (SMD-Marking)	46(2mm)	SOT-363			›HN 1C01FU
C 2		Si-P	=BFQ 32C (Marking)	51				›BFQ 32C
C 2(p)		Si-P	=BCW 30 (SMD-Marking)	35	SOT-23			›BCW 30
C 2		Si-P	=BFQ 32C (Marking)	51				›BFQ 32C
C 2		Si-N	=BFS 38 (SMD-Marking)	35(2mm)	SOT-323			›BFS 38
C 2		Si-Di	=HSM 276S (SMD-Marking)	35	SOT-23			›HSM 276S
C 3		Si-N	=BFS 39 (SMD-Marking)	35(2mm)	SOT-323			›BFS 39
C 3		Si-P	=MMBT 4126 (SMD-Marking)	35	SOT-23			›MMBT 4126
C 3		Si-Di	=1SS226 (SMD-Marking)	35	SOT-23			›1SS226
C 3		Si-Di	=1SS302 (SMD-Marking)	35(2mm)	SOT-323			›1SS302
C 3		Si-Di	=1SS362 (SMD-Marking)	35(1,6mm)	SS Mini			›1SS362
C 3 A		Si-N	=HN 1C03F-A (SMD-Marking)	46	SOT-163			›HN 1C03F
C 3 B		Si-N	=HN 1C03F-B (SMD-Marking)	46	SOT-163			›HN 1C03F
C 3 T		Si-Di	=1PS226 (SMD-Marking)	35	SOT-23			›1PS226
C 4		Si-P	=2SA811 (SMD-Marking)	35	SOT-23			›2SA811
C 4		Si-P	=BCW 29R (SMD-Marking)	35	SOT-23			›BCW 29R
C 4		Si-P	=BFS 40A (SMD-Marking)	35(2mm)	SOT-323			›BFS 40A
C 4		Si-Di	=HSM 88WK (SMD-Marking)	35	SOT-23			›HSM 88WK
C 4		Si-Di	=MC 804 (SMD-Marking)	35	SOT-23			›MC 804
C 5		Si-P	=2SA811-C5 (SMD-Marking)	35	SOT-23			›2SA811
C 5		Si-P	=BCW 30R (SMD-Marking)	35	SOT-23			›BCW 30R
C 5		Si-P	=BFS 40 (SMD-Marking)	35(2mm)	SOT-323			›BFS 40
C 5		GaAs-N-FET-d	=CFY 25-17 (Marking)	51				›CFY 25
C 5		Si-Di	=HSM 107S (SMD-Marking)	35	SOT-23			›HSM 107S
C 5		Si-P	=MMBA 811C5 (SMD-Marking)	35	SOT-23			›MMBA 811
CF 5R		GaAs-FET	=CF 930R (SMD-Marking)	44	SOT-143			›CF 930R
C 6		Si-P	=2SA811-C6 (SMD-Marking)	35	SOT-23			›2SA811
C 6		Si-P	=BFS 41 (SMD-Marking)	35(2mm)	SOT-323			›BFS 41
C 6		GaAs-N-FET-d	=CFY 25-20 (Marking)	51				›CFY 25
C 6		Si-Di	=HSM 198S (SMD-Marking)	35	SOT-23			›HSM 198S
C 6		Si-P	=MMBA 811C6 (SMD-Marking)	35	SOT-23			›MMBA 811
C 7		Si-P	=2SA811-C7 (SMD-Marking)	35	SOT-23			›2SA811
C 7(p)		Si-P	=BCF 29 (SMD-Marking)	35	SOT-23			›BCF 29
C 7		GaAs-N-FET-d	=CFY 25-23 (Marking)	51				›CFY 25
C 7		Si-Di	=HSM 88WA (SMD-Marking)	35	SOT-23			›HSM 88WA
C 7		Si-P	=MMBA 811C7 (SMD-Marking)	35	SOT-23			›MMBA 811
C 8		Si-P	=2SA811-C8 (SMD-Marking)	35	SOT-23			›2SA811
C 8(p)		Si-P	=BCF 30 (SMD-Marking)	35	SOT-23			›BCF 30
C 8		Si-P	=MMBA 811C8 (SMD-Marking)	35	SOT-23			›MMBA 811
C 9		Si-P	=BCF 30R (SMD-Marking)	35	SOT-23			›BCF 30R
C 10	old	C-Di	=BA 101	31a				›BA 101
C 15	old	C-Di	=BA 102	31a				›BA 102
C 15		Si-P	=2SA1612-C15 (SMD-Marking)	35(2mm)	SOT-323			›2SA1612
C 15		Si-P	=2SA811A-C15(SMD-Marking)	35	SOT-23			›2SA811A
C 16		Si-P	=2SA1612-C16 (SMD-Marking)	35(2mm)	SOT-323			›2SA1612

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
C 16		Si-P	=2SA811A-C16(SMD-Marking)		35	SOT-23			›2SA811A
C 17		Si-P	=2SA1612-C17 (SMD-Marking)		35(2mm)	SOT-323			›2SA1612
C 17		Si-P	=2SA811A-C17(SMD-Marking)		35	SOT-23			›2SA811A
C 18		Si-P	=2SA1612-C18 (SMD-Marking)		35(2mm)	SOT-323			›2SA1612
C 18		Si-P	=2SA811A-C18(SMD-Marking)		35	SOT-23			›2SA811A
C 20	old	C-Di	=BA 102		31a				›BA 102
C 20		N-FET	=2SK595-20 (SMD-Marking)		35	SOT-23			›2SK595
C 21		N-FET	=2SK595-21 (SMD-Marking)		35	SOT-23			›2SK595
C 22		N-FET	=2SK595-22 (SMD-Marking)		35	SOT-23			›2SK595
C 23		N-FET	=2SK595-23 (SMD-Marking)		35	SOT-23			›2SK595
C 24		N-FET	=2SK595-24 (SMD-Marking)		35	SOT-23			›2SK595
C 25		Si-P	=2SA1247-C25(SMD-Marking)		35	SOT-23			›2SA1247
C 26		Si-P	=2SA1247-C26(SMD-Marking)		35	SOT-23			›2SA1247
C 27		Si-P	=2SA1247-C27(SMD-Marking)		35	SOT-23			›2SA1247
C 28		Si-P	=2SA1247-C28(SMD-Marking)		35	SOT-23			›2SA1247
C 71		Si-P	=BCW 61A (SMD-Marking)		35	SOT-23			›BCW 61A
C 72		Si-P	=BCW 61B (SMD-Marking)		35	SOT-23			›BCW 61B
C 73		Si-P	=BCW 61C (SMD-Marking)		35	SOT-23			›BCW 61C
C 74		Si-P	=BCW 61D (SMD-Marking)		35	SOT-23			›BCW 61D
C 77		Si-P	=BCF 29R (SMD-Marking)		35	SOT-23			›BCF 29R
C 91		Si-P	=BCV 62 (SMD-Marking)		44	SOT-143			›BCV 62
C 92		Si-P	=BCV 62A (SMD-Marking)		44	SOT-143			›BCV 62A
C 93		Si-P	=BCV 62B (SMD-Marking)		44	SOT-143			›BCV 62B
C 94		Si-P	=BCV 62C (SMD-Marking)		44	SOT-143			›BCV 62C
C 95		Si-P	=BCV 64 (SMD-Marking)		44	SOT-143			›BCV 64
C 96		Si-P	=BCV 64B (SMD-Marking)		44	SOT-143			›BCV 64B
C 106 A	Gen,Mot,Rca	50Hz-Thy	100V, 2,2A(Tc=45°), 4A=, Igt/Ih<0,2/<3mA Mot: Fig. 14e (TO-126)		13e	TO-202	TIC 106 M[4]	17e	TAG 106A, X 0403B, TAG 108A, C 108A,++
C 106 B		50Hz-Thy	=C 106A: 200V		13e	TO-202	TIC 106 M[4]	17e	TAG 106B, X 0403B, TAG 108B, C 108B, ++
C 106 C		50Hz-Thy	=C 106A: 300V		13e	TO-202	TIC 106 M[4]	17e	TAG 106C, X 0403D, TAG 108C, C 108C, ++
C 106 D		50Hz-Thy	=C 106A: 400V		13e	TO-202	TIC 106 M[4]	17e	TAG 106D, X 0403D, TAG 108D, C 108D, ++
C 106 E		50Hz-Thy	=C 106A: 500V		13e	TO-202	TIC 106 M[4]	17e	TAG 106E, X 0403M, TAG 108E, C 108E, ++
C 106 F		50Hz-Thy	=C 106A: 50V		13e	TO-202	TIC 106 M[4]	17e	TAG 106F, X 0403B, TAG 108F, C 108F, ++
C 106 G		50Hz-Thy	=C 106A: 150V		13e	TO-202	TIC 106 M[4]	17e	TAG 106G, X 0403B, TAG 108G, C 108G, ++
C 106 M		50Hz-Thy	=C 106A: 600V		13e	TO-202	TIC 106 M[4]	17e	TAG 106M, X 0403M, TAG 108M, C 108M, ++
C 106 Q		50Hz-Thy	=C 106A: 15V		13e	TO-202	TIC 106 M[4]	17e	TAG 106Q, X 0403B, TAG 108Q, C 108Q, ++
C 106 Y		50Hz-Thy	=C 106A: 30V		13e	TO-202	TIC 106 M[4]	17e	TAG 106Y, X 0403B, TAG 108Y, C 108Y, ++
C 107 A	Gen,Rca	50Hz-Thy	100V, 2A(Tc=45°), 4A=, Igt/Ih<0,5/<3mA		13e	TO-202	TIC 106 M[4]	17e	TAG 107A, X 0403B, C 108A, TAG 108A, ++
C 107 B		50Hz-Thy	=C 107A: 200V		13e	TO-202	TIC 106 M[4]	17e	TAG 107B, X 0403B, C 108B, TAG 108B, ++
C 107 C		50Hz-Thy	=C 107A: 300V		13e	TO-202	TIC 106 M[4]	17e	TAG 107C, X 0403D, C 108C, TAG 108C, ++
C 107 D		50Hz-Thy	=C 107A: 400V		13e	TO-202	TIC 106 M[4]	17e	TAG 107D, X 0403D, C 108D, TAG 108D, ++
C 107 E		50Hz-Thy	=C 107A: 500V		13e	TO-202	TIC 106 M[4]	17e	TAG 107E, X 0403M, C 108E, TAG 108E, ++
C 107 F		50Hz-Thy	=C 107A: 50V		13e	TO-202	TIC 106 M[4]	17e	TAG 107F, X 0403B, C 108F, TAG 108F, ++
C 107 G		50Hz-Thy	=C 107A: 150V		13e	TO-202	TIC 106 M[4]	17e	TAG 107G, X 0403B, C 108G, TAG 108G, ++
C 107 M		50Hz-Thy	=C 107A: 600V		13e	TO-202	TIC 106 M[4]	17e	TAG 107M, X 0403M, C 108M, TAG 108M, ++
C 107 Q		50Hz-Thy	=C 107A: 15V		13e	TO-202	TIC 106 M[4]	17e	TAG 107Q, X 0403B, C 108Q, TAG 108Q, ++
C 107 Y		50Hz-Thy	=C 107A: 30V		13e	TO-202	TIC 106 M[4]	17e	TAG 107Y, X 0403B, C 108Y, TAG 108Y, ++
C 108 A	Gen,Rca	50Hz-Thy	100V, 3,3A(Tc=45°), 5A=, Igt/Ih<0,2/<3mA		13e	TO-202	TIC 106 M[4]	17e	TAG 108A, (TIC 106A, TAG 623-100)[4]
C 108 B		50Hz-Thy	=C 108A: 200V		13e	TO-202	TIC 106 M[4]	17e	TAG 108B, (TIC 106B, TAG 623-200)[4]
C 108 C		50Hz-Thy	=C 108A: 300V		13e	TO-202	TIC 106 M[4]	17e	TAG 108C, (TIC 106C, TAG 623-300)[4]
C 108 D		50Hz-Thy	=C 108A: 400V		13e	TO-202	TIC 106 M[4]	17e	TAG 108D, (TIC 106D, TAG 623-400)[4]
C 108 E		50Hz-Thy	=C 108A: 500V		13e	TO-202	TIC 106 M[4]	17e	TAG 108E, (TIC 106E, TAG 623-500)[4]
C 108 F		50Hz-Thy	=C 108A: 50V		13e	TO-202	TIC 106 M[4]	17e	TAG 108F, (TIC 106F, TAG 623-100)[4]
C 108 G		50Hz-Thy	=C 108A: 150V		13e	TO-202	TIC 106 M[4]	17e	TAG 108G, (TIC 106B, TAG 623-200)[4]
C 108 M		50Hz-Thy	=C 108A: 600V		13e	TO-202	TIC 106 M[4]	17e	TAG 108M, (TIC 106M, TAG 623-600)[4]
C 108 Q		50Hz-Thy	=C 108A: 15V		13e	TO-202	TIC 106 M[4]	17e	TAG 108Q, (TIC 106Y, TAG 623-100)[4]
C 108 Y		50Hz-Thy	=C 108A: 30V		13e	TO-202	TIC 106 M[4]	17e	TAG 108Y, (TIC 106Y, TAG 623-100)[4]
C 116 A	Gen	50Hz-Thy	100V, 8A=, Igt/Ih<25/<30mA		13e	TO-202	TAG 626-600[4]	17e	(TAG625-100, C122A, TIC116A, CS6-02,++)[4]
C 116 B		50Hz-Thy	=C 116A: 200V		13e	TO-202	TAG 626-600[4]	17e	(TAG625-200, C 122B, TIC116B, CS6-02,++)[4]
C 116 C		50Hz-Thy	=C 116A: 300V		13e	TO-202	TAG 626-600[4]	17e	(TAG625-300, C 122C, TIC116C, CS6-04,++)[4]
C 116 D		50Hz-Thy	=C 116A: 400V		13e	TO-202	TAG 626-600[4]	17e	(TAG625-400, C 122D, TIC116D, CS6-04,++)[4]
C 116 E		50Hz-Thy	=C 116A: 500V		13e	TO-202	TAG 626-600[4]	17e	(TAG625-500, C 122E, TIC116E, CS6-06,++)[4]
C 116 F		50Hz-Thy	=C 116A: 50V		13e	TO-202	TAG 626-600[4]	17e	(TAG625-100, C 122F, TIC116F, CS6-02,++)[4]
C 116 M		50Hz-Thy	=C 116A: 600V		13e	TO-202	TAG 626-600[4]	17e	(TAG625-600, C 122M, TIC116M, CS6-06,++)[4]
C 118 A	Gen	50Hz-Thy	100V, 8A=, Igt/Ih<0,2/<6mA		13e	TO-202	TIC 106 M[4]	17e	(TAG628-100, S 4060A)[4]
C 118 B		50Hz-Thy	=C 118A: 200V		13e	TO-202	TIC 106 M[4]	17e	(TAG 628-200, S 4060B, MCR 72-4)[4]
C 118 C		50Hz-Thy	=C 118A: 300V		13e	TO-202	TIC 106 M[4]	17e	(TAG 628-300, S 4060C, MCR 72-5)[4]
C 118 D		50Hz-Thy	=C 118A: 400V		13e	TO-202	TIC 106 M[4]	17e	(TAG 628-400, S 4060D, MCR 72-6)[4]
C 118 E		50Hz-Thy	=C 118A: 500V		13e	TO-202	TIC 106 M[4]	17e	(TAG 628-500, S 4060E, MCR 72-7)[4]
C 118 F		50Hz-Thy	=C 118A: 50V		13e	TO-202	TIC 106 M[4]	17e	(TAG 628-100, S 4060F, MCR 72-2)[4]
C 118 M		50Hz-Thy	=C 118A: 600V		13e	TO-202	TIC 106 M[4]	17e	(TAG 628-600, S 4060M, MCR 72-8)[4]
C 122 A	Mot,Rca	50Hz-Thy	100V, 5A(Tc=75°), 8A=, Igt/Ih<25/<30mA		17e	TO-220	TAG 626-600	17e	TIC116A, BStC1026M, CS6-02, TAG660-100++
C 122 B		50Hz-Thy	=C 122A: 200V		17e	TO-220	TAG 626-600	17e	TIC116B, BStC1026M, CS6-02, TAG660-200++
C 122 C		50Hz-Thy	=C 122A: 300V		17e	TO-220	TAG 626-600	17e	TIC116C, BStC1026M, CS6-04, TAG660-400++
C 122 D		50Hz-Thy	=C 122A: 400V		17e	TO-220	TAG 626-600	17e	TIC116D, BStC1026M, CS6-04, TAG660-400++
C 122 E		50Hz-Thy	=C 122A: 500V		17e	TO-220	TAG 626-600	17e	TIC116E, BStC1033M, CS6-06, TAG660-500++
C 122 F		50Hz-Thy	=C 122A: 50V		17e	TO-220	TAG 626-600	17e	TIC116F, BStC1026M, CS6-02, TAG660-100++
C 122 M		50Hz-Thy	=C 122A: 600V		17e	TO-220	TAG 626-600	17e	TIC116M, BStC1040M, CS6-02, TAG660-600++
C 203 A	Gen	F-Thy	100V, 0,8A(Tc=25°), Igt/Ih<0,2/<5mA		7n	TO-92	BRX 49	7a	BRX 46…49, BRX 51…56, BRY55/…S
C 203 B		F-Thy	=C 203A: 200V		7n	TO-92	BRX 49	7a	BRX 47…49, BRX 52…56, BRY55/…S
C 203 C		F-Thy	=C 203A: 300V		7n	TO-92	BRX 49	7a	BRX 48…49, BRX 53…56, BRY55/…S
C 203 D		F-Thy	=C 203A: 400V		7n	TO-92	BRX 49	7a	BRX 49, BRX 54…56, BRY55/…S
C 203 Y		F-Thy	=C 203A: 30V		7n	TO-92	BRX 49	7a	BRX 44…49, BRX 50…56, BRY55/…S
C 203 YY		F-Thy	=C 203A: 60V		7n	TO-92	BRX 49	7a	BRX 45…49, BRX 51…56, BRY55/…S
C 205 A	Gen,Mot	F-Thy	100V, 1,2A=, Igt/Ih<0,2/<5mA		7n	TO-92	(TIC 106 M)[6]	17e	(BRX 61…66)[4]
C 205 B		F-Thy	=C 205A: 200V		7n	TO-92	(TIC 106 M)[6]	17e	(BRX 62…66)[4]
C 205 C		F-Thy	=C 205A: 300V		7n	TO-92	(TIC 106 M)[6]	17e	(BRX 63…66)[4]
C 205 D		F-Thy	=C 205A: 400V		7n	TO-92	(TIC 106 M)[6]	17e	(BRX 64…66)[4]
C 205 Y		F-Thy	=C 205A: 30V		7n	TO-92	(TIC 106 M)[6]	17e	(BRX 60…66)[4]
C 205 YY		F-Thy	=C 205A: 60V		7n	TO-92	(TIC 106 M)[6]	17e	(BRX 61…66)[4]
C 228 A	Gen,Mot	50Hz-Thy	100V, 35A=, Igt/Ih<40/<75mA		21b	=TO-48			2N3896…3899, MCR3935-3, C35A, TAG35-100
C 228 B		50Hz-Thy	=C 228A: 200V		21b	=TO-48			2N3897…3899, MCR3935-4, C35B, TAG35-200
C 228 C		50Hz-Thy	=C 228A: 300V		21b	=TO-48			2N3898…3899, MCR3935-5, C35C, TAG35-300

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
C 228 D		50Hz-Thy	≈C 228A: 400V		21b	≈TO-48			2N3898…3899, MCR3935-6, C35D, TAG35-400
C 228 E		50Hz-Thy	≈C 228A: 500V		21b	≈TO-48			2N3899, MCR3935-7, C35E, TAG35-500
C 228 F		50Hz-Thy	≈C 228A: 50V		21b	≈TO-48			2N3896…3899, MCR3935-2, C35F, TAG35-100
C 228 M		50Hz-Thy	≈C 228A: 600V		21b	≈TO-48			2N3899, MCR3935-8, C35M, TAG35-600
C 228 U		50Hz-Thy	≈C 228A: 25V		21b	≈TO-48			2N3896…3899, MCR3935-1, C35U, TAG35-100
C 228 A….U 3		50Hz-Thy	≈C228 A…U:		54b	≈TO-48			-
C 229 A….U	Gen,Mot	50Hz-Thy	≈C228 A…U:		29b	TO-203			2N3870…3873, MCR3835…, MCR63…
C 230 A	Gen,Mot	50Hz-Thy	100V, 25A≈, Igt/Ih<25/<50mA		21b	≈TO-48			BStE4126N, BStE4126MN
C 230 B		50Hz-Thy	≈C 230A: 200V		21b	≈TO-48			BStE4126N, BStE4126MN
C 230 C		50Hz-Thy	≈C 230A: 300V		21b	≈TO-48			BStE4126N, BStE4126MN
C 230 D		50Hz-Thy	≈C 230A: 400V		21b	≈TO-48			BStE4126N, BStE4126MN
C 230 E		50Hz-Thy	≈C 230A: 500V		21b	≈TO-48			BStE4133N, BStE4133MN
C 230 F		50Hz-Thy	≈C 230A: 50V		21b	≈TO-48			BStE4126N, BStE4126MN
C 230 M		50Hz-Thy	≈C 230A: 600V		21b	≈TO-48			BStE4140N, BStE4140MN
C 230 U		50Hz-Thy	≈C 230A: 25V		21b	≈TO-48			BStE4126N, BStE4126MN
C 230 A….U 3		50Hz-Thy	≈C230 A…U:		54b	≈TO-48			-
C 231 A….U	Gen,Mot	50Hz-Thy	≈C230 A…U: Igt/Ih<9/<50mA		21b	≈TO-48			-
C 231 A….U 3		50Hz-Thy	≈C230 A…U: Igt/Ih<9/<50mA		54b	≈TO-48			-
C 232 A….U	Gen,Mot	50Hz-Thy	≈C230 A…U:		29b	TO-203			BStE40…N, BStE40…MN
C 233 A….U	Gen,Mot	50Hz-Thy	≈C231 A…U:		29b	TO-203			-
C 500 D	Hfo	LIN-IC	Analogprocessor f. A/D-Converter, 14 Bit		18-DIP				TL 500C
C 501 D	Hfo	LIN-IC	Analogprocessor f. A/D-Converter, 11 Bit		18-DIP				TL 501C
C 502 D	Hfo	LIN-IC	Digitalprocessor, 4,5-Digit Display Driver		20-DIP				TL 502C
C 504 D	Hfo	LIN-IC	Digitalprocessor, 3,5/4,5-Digit Display Driver		28-DIP				-
C 520 D	Hfo	A/D-IC	3-Digit A/D-Converter, Dual-Slope		16-DIP				AD 2020
C 560 D	Hfo	D/A-IC	8-Bit D/A-Converter		16-DIC				(AD 558 JD)
C 565 D	Hfo	D/A-IC	12-Bit D/A-Converter, ≈C 5650D		24-DIC				AD 565 JN, µA 565…
C 570 D	Hfo	A/D-IC	8-Bit A/D-Converter		18-DIC				AD 570
C 571 D	Hfo	A/D-IC	10-Bit A/D-Converter		18-DIC				AD 571, µA 571…
C 574 C	Hfo	A/D-IC	12-Bit A/D-Converter, µP-Interface		28-DIP				-
C 670 C,CGn	Hfo	A/D-IC	8-Bit A/D-Converter		18-DIC				-
C 1398		Si-N	≈BC 237				BC 546	7a	›BC 237
C 1406(G)		Si-Br	Br Rr, 100V, 3,2…4,8A		33		B80C5000	31a	B40C3700/2200, etc
(SSi) C 1710	Sie	Si-Di	›SSi C 1710		27c		BY 255	31a	
(SSi) C 1720	Sie	Si-Di	›SSi C 1720		27c		BY 255	31a	
(SSi) C 1740	Sie	Si-Di	›SSi C 1740		27c		BY 255	31a	
(SSi) C 1760	Sie	Si-Di	›SSi C 1760		27c		BY 255	31a	
(SSi) C 1780	Sie	Si-Di	›SSi C 1780		27c		BY 255	31a	
(SSi) C 2620	Sie	Si-Di	›SSi C 2620		31a		RGP 30 M	31a	
(SSi) C 2630	Sie	Si-Di	›SSi C 2630		31a		RGP 30 M	31a	
C 4160		Si-N	≈BC 237		7e		BC 546	7a	›BC 237
(SSi) C 4610	Sie	Si-Di	›SSi C 4610				RGP 30 M	31a	
(SSi) C 4620	Sie	Si-Di	›SSi C 4620				RGP 30 M	31a	
C 5650 D	Hfo	D/A-IC	10-Bit D/A-Converter, ≈C 565D		24-DIC				-
C 5658 D	Hfo	D/A-IC	8-Bit D/A-Converter		24-DIP				-
C 7136 D	Hfo	A/D-IC	3,5-Digit A/D-Converter		40-DIP				ICL 7136
CA									
CA		Si-N	=2SC3645 (SMD-Marking)		39	SOT-89			›2SC3645
CA		Si-N	=2SD1368-CA (SMD-Marking)		39	SOT-89			›2SD1368
CA		C-Di	=BB 510 (SMD-Marking)		35	SOT-23			›BB 510
CA		Si-N	=BCP 68 (SMD-Marking)		≈39°	SOT-223			›BCP 68
CA		Si-P	=BCW 61RA (SMD-Marking)		35	SOT-23			›BCW 61RA
CA		Si-N	=BCX 68 (SMD-Marking)		39	SOT-89			›BCX 68
CA		Si-N	=BFS 18 (SMD-Marking)		35	SOT-23			›BFS 18
CA		Si-N/P+R	=XN 4314 (SMD-Marking)		46	SOT-363			›XN 4314
CA		Si-N/P+R	=XP 4314 (SMD-Marking)		46(2mm)	SOT-363			›XP 4314
CA		MOS-P-FET-e	=µPA503T (SMD-Marking)		45	SOT-153			›µPA503T
CA 080(A,B)E	Rca	BiMOS-OP-IC	=CA 080…S,T: Fig. ›		8-DIP				TL 080…
CA 080(A,B,C)S,T	Rca	BiMOS-OP-IC	MOS In/Out, ±18V, InOffset=<15…<3mV(A,B,C)		TO-99				TL 080…
CA 081(A,B)E	Rca	BiMOS-OP-IC	=CA 081…S,T: Fig. ›		8-DIP				TL 081…
CA 081(A,B,C)S,T	Rca	BiMOS-OP-IC	MOS In/Out, ±18V, InOffset=<15…<3mV(A,B,C)		TO-99				TL 081…
CA 082(A,B)E	Rca	BiMOS-OP-IC	=CA 082…S,T: Fig. ›		8-DIP				TL 082…
CA 082(A,B,C)S,T	Rca	BiMOS-OP-IC	Dual, MOS In/Out, ±18V, InOffset=<15…<3mV(A,B,C)		TO-99				TL 082…
CA 083(A,B)E	Rca	BiMOS-OP-IC	Dual, MOS In/Out, ±18V, InOffset=<15…<3mV(A,B)		14-DIP				TL 083…
CA 084(A,B)E	Rca	BiMOS-OP-IC	Quad, MOS In/Out, ±18V, InOffset=<15…<3mV(A,B)		14-DIP				TL 087…
CA 101 (A)E,G	Rca	OP-IC	Uni, Serie 101, ±22V, -55…+125°, A=10V/µs		8-DIP,DIC				… 101…
CA 101 (A)S,T	Rca	OP-IC	=CA 101E,G:Fig. ›		TO-99				… 101…
CA 107 E,G	Rca	OP-IC	Uni, Serie 107, ±22V, -55…+125°		8-DIP,DIC				… 107…
CA 107 S,T	Rca	OP-IC	=CA 107…: Fig. ›		TO-99				… 107…
CA 108(A)S,T	Rca	OP-IC	Uni, Serie 108, ±20V, -55…+125°,Offs=0,7(A=0,3)mV		TO-99				… 108…
CA 111 E,G	Rca	KOP-IC	Uni, Serie 111, ±18V, -55…+125°		8-DIP,DIC				… 111…
CA 111 S,T	Rca	KOP-IC	=CA 111E,G: Fig. ›		TO-99				… 111…
CA 124 E,G	Rca	OP-IC	Quad, Serie 124, ±16V, -55…+125°		14-DIP,DIC				… 124…
CA 139(A)E,G	Rca	KOP-IC	Quad, Serie 139, ±18V, -55…+125°, Offs<5mV(A<2mV)		14-DIP,DIC				… 139…
CA 158(A)E,G	Rca	OP-IC	Dual, Serie 158, ±16V, -55…+125°, A=Imprvd. Vers.		8-DIP,DIC				… 158…, … 1558…, … 2904…
CA 158(A)S,T	Rca	OP-IC	=CA 158E,G: -25…+85°		TO-99				… 158…, … 1558…
CA 201 (A)E,G	Rca	OP-IC	=CA 101…: -25…+85°		8-DIP,DIC				… 101…, … 201…
CA 201 (A)S,T	Rca	OP-IC	=CA 101…: -25…+85°		TO-99				… 101…, … 201…
CA 207 E,G	Rca	OP-IC	=CA 107…: -25…+85°		8-DIP,DIC				… 107…, … 207…
CA 207 S,T	Rca	OP-IC	=CA 107…: -25…+85°		TO-99				… 107…, … 207…
CA 208 (A)S,T	Rca	OP-IC	=CA 108…: -25…+85°		TO-99				… 108…, … 208…
CA 211 E,G	Rca	KOP-IC	=CA 111…: -25…+85°		8-DIP,DIC				… 111…, … 211…
CA 211 S,T	Rca	KOP-IC	=CA 111…: -25…+85°		TO-99				… 111…, … 211…
CA 224 E,G	Rca	OP-IC	=CA 124…: -25…+85°		14-DIP,DIC		(LM 324 N)[16]	14-DIP	… 124…, … 224…
CA 239(A)E,G	Rca	KOP-IC	=CA 139…: -25…+85°		14-DIP		(LM 339 N)[16]	14-DIP	… 139…, … 239…
CA 258 E,G	Rca	OP-IC	=CA 158…: -25…+85°		8-DIP,DIC		(4558/8-D)[16]	8-DIP	… 158…, … 258…, … 1558…, … 2904…
CA 258 S,T	Rca	OP-IC	=CA 158…: -25…+85°		TO-99				… 158…, … 258…, … 1558…
CA 270	Rca	LIN-IC	TV, Sync. Dem., Video-Verst./Amp., AGC(+), Ucc=12V		16-QIP				TCA 270 S
CA 301 AS,AT	Rca	OP-IC	=CA 101…: 0…+70°		TO-99				… 101…, … 201…, … 301…
CA 301 (A)E,G	Rca	OP-IC	=CA 101…: 0…+70°		8-DIP,DIC				… 101…, … 201…, … 301…
CA 307 E,G	Rca	OP-IC	=CA 107…: 0…+70°		8-DIP,DIC				… 107…, … 207…, … 307…
CA 307 S,T	Rca	OP-IC	=CA 107…: 0…+70°		TO-99				… 107…, … 207…, … 307…

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
CA 308 E	Rca	OP-IC	=CA 108...: 0...+70°		8-DIP				... 108..., ... 208..., ... 308...
CA 308(A)S,T	Rca	OP-IC	=CA 108...: 0...+70°		TO-99				... 108..., ... 208..., ... 308...
CA 311 E,G	Rca	KOP-IC	=CA 111...: 0...+70°		8-DIP,DIC				... 111..., ... 211..., ... 311...
CA 311 S,T	Rca	KOP-IC	=CA 111...: 0...+70°		TO-99				... 111..., ... 211..., ... 311...
CA 324 E,G	Rca	OP-IC	=CA 124...: 0...+70°		14-DIP,DIC		LM 324 N	14-DIP	... 124..., ... 224..., ... 324...
CA 339(A)E,G	Rca	KOP-IC	=CA 139...: 0...+70°		14-DIP		LM 339 N	14-DIP	... 139..., ... 239..., ... 339...
CA 358 E,G	Rca	OP-IC	=CA 158...: 0...+70°		8-DIP,DIC		4558/8D	8-DIP	... 158..., ... 258..., ... 358..., ... 1458...
CA 358 S,T	Rca	OP-IC	=CA 158...: 0...+70°		TO-99				... 158..., ... 258..., ... 358..., ... 1458...
CA 555(C)E	Rca	LIN-IC	Timer, Ucc=4,5...18V, Iout=0,2A		8-DIP		NE 555 N	8-DIP	›NE 555N
CA 555 S,T	Rca	LIN-IC	=CA 555(C)E: Fig. ›		TO-99				›NE 555N
CA 723(C)E	Rca	Z-IC	+2....37V, 0,15A, -55...+125°		14-DIP		723/14-D	14-DIP	... 723...
CA 723(C)T	Rca	Z-IC	=CA 723(C)E: Fig. ›		TO-100		723/TO	TO-100	... 723...
CA 741 E,F,G,M	Rca	OP-IC	Uni, Serie 741, ±22V, -55...+125°		8-DIP,DIC				... 741...
CA 741 S,T	Rca	OP-IC	=CA 741E,F,G,#: Fig. ›		TO-99				... 741...
CA 741 CE,CF,CG,CM	Rca	OP-IC	=CA 741E,F,G,M: ±18V, 0...+70°		8-DIP,DIC		741/8-D	8-DIP	... 741C...
CA 741 CS,CT	Rca	OP-IC	=CA 741E,F,G,M: ±18V, 0...+70°		TO-99		741/TO	TO-99	... 741C...
CA 747 E,F,G	Rca	OP-IC	Dual, Serie 747, ±22V, -55...+125°		14-DIP,DIC				... 747...
CA 747 T	Rca	OP-IC	=CA 747E,F,G: Fig. ›		TO-100				... 747...
CA 747 CE,CF,CG	Rca	OP-IC	=CA 747E,F,G: ±18V, 0...+70°		14-DIP,DIC		747/14-D	14-DIP	... 747C...
CA 747 CT	Rca	OP-IC	=CA 747E,F,G: ±18V, 0...+70°		TO-100				... 747C...
CA 748 E,F,G	Rca	OP-IC	Uni, Serie 748, ±22V, -55...+125°		8-DIP,DIC				... 748...
CA 748 S,T	Rca	OP-IC	=CA 748E,F,G: Fig. ›		TO-99				... 748...
CA 748 CE,CF,CG	Rca	OP-IC	=CA 748E,F,G: ±18V, 0...+70°		8-DIP,DIC		748/8-D	8-DIP	... 748C...
CA 748 CT	Rca	OP-IC	=CA 748E,F,G: ±18V, 0...+70°		TO-99		748/TO	TO-99	
CA 758(E)	Rca	LIN-IC	PLL FM MPX Stereo-Decoder, Ucc=10...16V		16-DIP		(TCA 4500 A)	16-DIP	LM 1800, MC 1311, ULX 2244, µA 758 C
CA 920(A)E	Rca	LIN-IC	TV, HA Sync., HA-Os		16-DIP		TBA 920 S	16-DIP	TBA 920 S
CA 1190(Q)	Rca	LIN-IC	TV, Sound IF, LF Out		12-QIP+b		TDA 3190	16-DIP	TDA 1190, TDA 3190
CA 1191(E)	Rca	LIN-IC	TV, Sound IF, LF Out		16-DIP		TDA 3190	16-DIP	TDA 1190, TDA 3190
CA 1310(A)E	Rca	LIN-IC	PLL FM MPX Stereo-Decoder, Ucc=8...16V		14-DIP				A 290D, LM 1310, MC 1310, SN 76115
CA 1352	Rca	LIN-IC	TV, Video(pos./neg.) IF, AGC(neg.)		14-DIP				MC 1352
CA 1391 E	Rca	LIN-IC	TV, HA Sync. Processor, pos. Signal Input		8-DIP				MC 1391
CA 1394 E	Rca	LIN-IC	=CA 1391: neg. Signal Input		8-DIP				MC 1394
CA 1398 E	Rca	LIN-IC	CTV, Chroma Processor		14-DIP				-
CA 1458 E,G,M	Rca	OP-IC	Dual, Serie 158, ±18V, 0...+70°		8-DIP,DIC		4558/8-D	8-DIP	... 158..., ... 1458..., ... 1558..., ...4558...
CA 1458 S,T	Rca	OP-IC	=CA 1458E,G,M:Fig. ›		TO-99		4558/8-D	8-DIP	... 158..., ... 1458..., ... 1558..., ...4558...
CA 1524(E)	Rca	LIN-IC	SMPS/PWM Controller, 100mA, -25...+125°		16-DIP				›SG 1524
CA 1558 E,G,M	Rca	OP-IC	Dual, Serie 158, ±22V, -55...+125°		8-DIP,DIC				... 158..., ... 1558...
CA 1558 S,T	Rca	OP-IC	=CA 1558E,G,M: Fig. ›		TO-99				... 158..., ... 1558...
CA 1724	Rca	Si-N	4x NPN Trans., 40V, 1A, 38/185ns, Usat<0,5V(0,5A)		14-DIP				DH 3724, FPQ 3724, MPQ 3724, SP 3724
CA 1725	Rca	Si-N	=CA 1724: 50V		14-DIP				DH 3725, FPQ 3725, MPQ 3725, SP 3725
CA 2002	Rca	LIN-IC	LF Out, 28V, 3,5A, 8W(14,4V/2Ω)		17/5Pin	TO-220/5V	TDA 2003	17/5Pin	TDA 2002 V
CA 2002 M	Rca	LIN-IC	=CA 2002:		17/5Pin	TO-220/5H	TDA 2003	17/5Pin	TDA 2002 H
CA 2004	Rca	LIN-IC	LF Out, 28V, 3,5A, 12W(24V/4Ω)		17/5Pin	TO-220/5			-
CA 2004 M	Rca	LIN-IC	=CA 2004:		17/5Pin	TO-220/5			-
CA 2111(A)E	Rca	LIN-IC	TV, FM Sound IF, Quadratur Detector		14-DIP				LM 2111, MC 1357(P), ULN 2111(A)
CA 2111(A)Q	Rca	LIN-IC	=CA 2111(A)E:		14-QIP				LM 2111, MC 1357(P), ULN 2111(A)
CA 2136 A	Rca	LIN-IC	FM/TV, Sound IF, Quadratur Detector		14-DIP				LM 1841, ULN 2136A
CA 2524(E)	Rca	LIN-IC	=CA 1524: -40...+85°		16-DIP				›SG 2524
CA 2904 E,G	Rca	OP-IC	Dual, Serie 158, ±13V, -55...+125°		8-DIP				... 158..., ... 1558..., ... 2904...
CA 3000	Rca	LIN-IC	Diff.-Verst./DC Amp., ±6V, -55...+125°		TO-100				-
CA 3001	Rca	LIN-IC	Video-,Breitband-/Wideband/Verst./Amplifier, ±6V		TO-101				HA 1110
CA 3002	Rca	LIN-IC	IF-, Video-Verst./Amp., ±8V, -55...+125°		TO-100				-
CA 3004	Rca	LIN-IC	HF-Verst./RF Amp., ±6V, -55...+125°		TO-101				-
CA 3005	Rca	LIN-IC	HF-Verst./RF Amp., ±6V, -55...+125°		TO-101				-
CA 3006	Rca	LIN-IC	HF-Verst./RF Amp., ±6V, -55...+125°		TO-101				-
CA 3007	Rca	LIN-IC	Audio-Verst./Amp., ±6V, -55...+125°		TO-101				-
CA 3008(A)	Rca	OP-IC	=CA 3029(A): -55...+125°		14-FLP				-
CA 3010(A)	Rca	OP-IC	=CA 3029(A): -55...+125°		TO-101				-
CA 3011	Rca	LIN-IC	TV/CATV, Breitbandverst./Wideband Amp., ...20MHz		TO-100				LM 3011
CA 3012	Rca	LIN-IC	TV/CATV, Breitbandverst./Wideband Amp., ...20MHz		TO-100				-
CA 3013	Rca	LIN-IC	TV/CATV, Breitbandverst./Wideband Amp., ...20MHz		TO-100				-
CA 3014	Rca	LIN-IC	TV/CATV, Breitbandverst./Wideband Amp., ...20MHz		TO-100				-
CA 3015(A)	Rca	OP-IC	=CA 3030(A): -55...+125°		TO-101				-
CA 3016(A)	Rca	OP-IC	=CA 3030(A): -55...+125°		14-FLP				-
CA 3018	Rca	Si-N	2x NPN + 1x NPN Darl. Trans., 20V, 0,05A, >300MHz		TO-101				-
CA 3018 A	Rca	Si-N	=CA 3018: 30V		TO-101				-
CA 3019	Rca	LIN-IC	6-Di-Array(2xDi + 1xDi-Br), S, 25mA, 1,8pF(2V)		TO-100				-
CA 3020	Rca	LIN-IC	Breitband-/Wideband Amp., PQ=0,5W(9V)		TO-101				-
CA 3020 A	Rca	LIN-IC	=CA 3020: PQ=1W(12V)		TO-101				-
CA 3021	Rca	OP-IC	Wideband, Video, AM/FM IF, 2,4MHz, +18V,-55...+125°		TO-101				CA 3022, CA 2023
CA 3022	Rca	OP-IC	Wideband, Video, AM/FM IF, 7,5MHz, +18V,-55...+125°		TO-101				CA 3023
CA 3023	Rca	OP-IC	Wideband, Video, AM/FM IF, 16MHz, +18V, -55...+125°		TO-101				-
CA 3026	Rca	LIN-IC	=CA 3054: Fig. ›		TO-101				-
CA 3028 AF,BF	Rca	LIN-IC	Diff.-Verst./Amp., ...120MHz, -55...125°		8-DIC				-
CA 3028 S,T	Rca	LIN-IC	=CA 3028AF,BF: Fig. ›		TO-99				-
CA 3029(A)	Rca	OP-IC	Uni, ±10V, 0...+70°, A=verbess./improved Version		14-DIP				CA 3037
CA 3030(A)	Rca	OP-IC	Uni, ±20V, 0...+70°, A=verbess./improved Version		14-DIP				CA 3038
CA 3031	Rca	OP-IC	Uni, Serie 712, +14/-7V, -55...+125°		TO-99				... 702..., MC 1712...
CA 3032	Rca	OP-IC	=CA 3031: 0...+70°		TO-99				... 702..., MC 1712...
CA 3033(A)	Rca	OP-IC	Uni, ±13V, -55...+125°, A=verbess./improved Version		14-DIP				-
CA 3035(V1)	Rca	LIN-IC	Breitb./Wideb. Amp., 129dB(40kHz), V1=Formed Leads		TO-100				-
CA 3036	Rca	Si-N	2x Darl.-Trans., 30V, 0,05A, >150MHz, hFE>1000		TO-100				-
CA 3037(A)	Rca	OP-IC	=CA 3029(A): -55...+125°		14-DIC				-
CA 3038(A)	Rca	OP-IC	=CA 3030(A): -55...+125°		14-DIC				-
CA 3039	Rca	LIN-IC	6-Di-Array, S, 5V, 25mA, 1ns, 0,65pF(2V)		TO-101				-
CA 3040	Rca	LIN-IC	Video-,Breitband-/Wideband/Verst./Amp., ...200MHz		TO-101				-
CA 3041	Rca	LIN-IC	FM/TV, Sound IF, Dem., LF Amp. f. Röhren-/Tube Out		14-QIP				-
CA 3042	Rca	LIN-IC	FM/TV, Sound IF, Dem., LF Amp. f. Transistor Out		14-QIP				-
CA 3045(F)	Rca	LIN-IC	5x NPN Trans., 20/15V, 0,05A, ...120MHz, -55...+125°		14-DIC				HA 1127, LM 4045
CA 3046	Rca	LIN-IC	=CA 3045: -40...+85°		14-DIP				LM 3046, TBA 331, µA 3046
CA 3047(A)	Rca	OP-IC	Uni, ±13V, 0...+70°		14-DIP				-
CA 3048	Rca	LIN-IC	Quad, Uni AC Verst./Amp., 16V, 300kHz		16-DIP				-
CA 3049 T	Rca	LIN-IC	=CA 3102E: Fig. ›		TO-101				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
CA 3050	Rca	LIN-IC	Dual Diff.-Verst./Amp., 20V, 0,05A, -55…+125°		14-DIC			-
CA 3051	Rca	LIN-IC	=CA 3050: -40…+85°		14-DIP			-
CA 3052	Rca	LIN-IC	Quad, Uni AC Verst./Amp., LF In, +16V, 300kHz		16-DIP			-
CA 3053 F	Rca	LIN-IC	Diff.-Verst./Amp., …120MHz, -55…125°		8-DIC			-
CA 3053 S,T	Rca	LIN-IC	=CA 3053F: Fig. ›		TO-99			-
CA 3054	Rca	LIN-IC	Dual, Breitband/Wideband Diff. Amp., …120MHz		14-DIP			TBA 341
CA 3058	Rca	LIN-IC	Nullspg.-/Zero-Voltage Sw. f. 50/60/400Hz Thy Ctrl		14-DIC			-
CA 3059	Rca	LIN-IC	Nullspg.-/Zero-Voltage Sw. f. 50/60/400Hz Thy Ctrl		14-DIP			-
CA 3060 AD,BD	Rca	OP-IC	=CA 3060D: ±18V		14-DIC			-
CA 3060 D	Rca	OP-IC	3x Transconductance OP (OTA), ±7V, -55…+125°		14-DIC			-
CA 3060 E	Rca	OP-IC	=CA 3060D: ±18V, -40…+85°		14-DIP			-
CA 3064	Rca	LIN-IC	TV, Autom. Feinabstimmung/Fine Tuning		TO-100			-
CA 3064 E	Rca	LIN-IC	=CA 3064: Fig. ›		14-DIP			-
CA 3065(E)	Rca	LIN-IC	TV Sound IF, FM IF, Dem, LF Drv		14-QIP			AN 241, HA 1125, KA 2101, LA 1365, LM 3065, MC 1358, TA 7176, ULN 2165
CA 3068	Rca	LIN-IC	TV, Video IF, Sound IF, Video Amp., AGC		20-QIP			-
CA 3070	Rca	LIN-IC	CTV, Chroma-System, VCO, Hue Control		16-DIP			-
CA 3071	Rca	LIN-IC	CTV, Chroma-System, Chroma Verst./Amp.		14-DIP			-
CA 3072	Rca	LIN-IC	CTV, Chroma-System, Color Matrix		14-DIP			-
CA 3075	Rca	LIN-IC	HiFi, FM IF Limiter, Demodulator, LF Preamp.		14-QIP			LM 3075
CA 3076	Rca	LIN-IC	Breitband/Wideband FM IF Limiter		TO-99			-
CA 3078 A(E,S,T)	Rca	OP-IC	=CA 3078E: ±18V, -55…+125°					-
CA 3078 E	Rca	OP-IC	Uni, lo-power, ±7V, 0…+70°		8-DIP			-
CA 3078 S,T	Rca	OP-IC	=CA 3078(A)E: Fig. ›		TO-99			-
CA 3079	Rca	LIN-IC	Nullspg.-/Zero-Voltage Sw. f. 50/60/400Hz Thy Ctrl		14-DIP			-
CA 3080(S)	Rca	OP-IC	=CA 3080E: Fig. ›		TO-99			-
CA 3080 A, AS	Rca	OP-IC	=CA 3080E: -55…+125°					-
CA 3080 E	Rca	OP-IC	Transconductance OP(OTA), ±18V, 75V/µs, 0…+70°		8-DIP			-
CA 3081(F)	Rca	LIN-IC	7xNPN Trans.-Array, Common Emit., 20V, 0,1A, 0,75W		16-DIP,DIC			-
CA 3082(F)	Rca	LIN-IC	7xNPN Trans.-Array, Common Coll., 20V, 0,1A, 0,75W		16-DIP,DIC			-
CA 3083	Rca	LIN-IC	5x NPN Trans. Array, 20/15V, 0,1A, 450MHz		16-DIP			MB 5331
CA 3084(E)	Rca	LIN-IC	PNP-Trans.-Array, 40V, 10mA		14-DIP			-
CA 3085(S)	Rca	Z-IC	1,8…26V, 12mA, -55…+125°		TO-99			-
CA 3085 A(S)	Rca	Z-IC	=CA 3085(S): 1,7…36V, 100mA		TO-99			-
CA 3085 B(S)	Rca	Z-IC	=CA 3085(S): 1,7…46V, 100mA		TO-99			-
CA 3085(A,B)E,F	Rca	Z-IC	=CA 3085(A,B)(S): Fig. ›		8-DIP,DIC			-
CA 3086(F)	Rca	LIN-IC	5xNPN Trans. Array, 20/15V, 0,05A, 550MHz, F=Keram		14-DIP,DIC			LM 3086, TBA 331, µA 3086
CA 3088 E	Rca	LIN-IC	AM Radio, Ucc=6…16V		16-DIP			-
CA 3089(E,N)	Rca	LIN-IC	TV, Sound IF, FM IF, AGC, AFC		16-DIP			LM 3089, TCA 3089, TDA 1200(A)
CA 3090(A)	Rca	LIN-IC	FM MPX Stereo-Decoder, Ucc=10…16V		16-DIP			-
CA 3090 (A)Q	Rca	LIN-IC	=CA 3090(A)		16-QIP			-
CA 3091 D	Rca	LIN-IC	4-Quadrant Multiplier, 18V, -55…+125°		14-DIC			-
CA 3093 E	Rca	LIN-IC	3x NPN-Trans., 2x Z-Diode, 1x Diode		16-DIP			-
CA 3094 AE	Rca	OP-IC	=CA 3094E: ±18V		8-DIP			-
CA 3094 BE	Rca	OP-IC	=CA 3094E: ±22V		8-DIP			-
CA 3094 E	Rca	OP-IC	S, hi-power, progr., ±12V, -55…+125°		8-DIP			-
CA 3094 S,T	Rca	OP-IC	=CA 3094(A,B)E: Fig. ›		TO-99			-
CA 3096 AE,E	Rca	LIN-IC	3x NPN(45/35V)-/2x PNP(40/40V)-Trans., AE=<Usat		16-DIP			-
CA 3096 CE	Rca	LIN-IC	=CA 3096AE,E: 24/24V		16-DIP			-
CA 3097 E	Rca	LIN-IC	Thyristor/PUT/NPN-/PNP-Trans.-Array		16-DIP			-
CA 3098 E	Rca	KOP-IC	Dual Input Schmitt Trigger, progr, 16V, -55…+125°		8-DIP			-
CA 3098 S,T	Rca	KOP-IC	=CA 3098E: Fig. ›		TO-99			-
CA 3099 E	Rca	KOP-IC	progr., Flip-Flop Memory, 16V, -55…+125°		14-DIP			-
CA 3100 E	Rca	OP-IC	Wideband, Video, hi-speed, 38MHz, +18V, -40…+85°		8-DIP			-
CA 3100 S,T	Rca	OP-IC	=CA 3100E: -55…+125°		TO-99			-
CA 3102 E	Rca	LIN-IC	Dual, Breitband/Wideband Diff. Amp., …500MHz		14-DIP			-
CA 3105(M)	Rca	OP-IC	Power-OP, 28V, 3,5A, 15W, 0…+125°, M=Horiz. Mount		17/5Pin	TO-220/5		-
CA 3118 AT	Rca	LIN-IC	=CA 3118T: 50/40V		TO-101			-
CA 3118 T	Rca	LIN-IC	4x NPN Trans. Array, 40/30V, 0,05A, >300MHz		TO-101			-
CA 3120 E	Rca	LIN-IC	TV, Signal Processor		16-DIP			-
CA 3121 E	Rca	LIN-IC	CTV, Chroma-Verst./Amp., Chroma Demodulator		16-DIP			-
CA 3123 E	Rca	LIN-IC	AM Radio, Ucc=9V		14-DIP			-
CA 3125 E	Rca	LIN-IC	CTV, Chroma Demodulator		14-DIP			-
CA 3126 Q	Rca	LIN-IC	CTV, Chroma Processor		16-QIP			-
CA 3127 E	Rca	LIN-IC	5x NPN-Trans.-Array, VHF, 20/15V, 20mA, >1GHz		14-DIP			-
CA 3128 Q	Rca	LIN-IC	CTV, PAL Chroma Processor		16-QIP			-
CA 3130(A,B)E	Rca	BiMOS-OP-IC	MOS In/Out, +16V, -55…+125°,InOffs<15(A<5, B<2mV)		8-DIP			-
CA 3130(A,B)S,T	Rca	BiMOS-OP-IC	=CA 3130(A,B)E: Fig. ›		TO-99			-
CA 3134 EM	Rca	LIN-IC	TV Sound IF, Dem, LF Out, 5W(30V/16Ω)		16-DIP+d			-
CA 3134 QM	Rca	LIN-IC	=CA 3134EM:		16-QIP+d			-
CA 3135 E	Rca	LIN-IC	CTV, Luminance Processor		16-DIP			-
CA 3136 P	Rca	LIN-IC	CTV, Video PLL Synchron Demodulator		16-DIP+c			-
CA 3137 E	Rca	LIN-IC	CTV, Chroma Demodulator		16-DIP			-
CA 3138 AE	Rca	Si-N	=CA 3138: 25V		14-DIP			-
CA 3138 E	Rca	Si-N	4x NPN Trans., 20V, 1A, 106/857ns, Usat<0,4V(0,5A)		14-DIP			-
CA 3139 E	Rca	LIN-IC	TV, Autom. Feinabstimmung/Fine Tuning		14-DIP			-
CA 3139 Q	Rca	LIN-IC	=CA 3139E: Fig. ›		14-QIP			-
CA 3140(A,B)E	Rca	BiMOS-OP-IC	MOS In,±18(B=±22)V,-55…+125°, Offs<15(A<5, B<2mV)		8-DIP			-
CA 3140(A,B)S,T	Rca	BiMOS-OP-IC	=CA 3140(A,B)E: Fig. ›		TO-99			-
CA 3141 E	Rca	LIN-IC	10-Di-Array, 30V, 25mA, 50ns(2mA), UF<1V(1mA)		16-DIP			-
CA 3142 E	Rca	LIN-IC	TV, Signal Processor		16-DIP			-
CA 3143 E	Rca	LIN-IC	CTV, Luminance Processor		14-DIP			-
CA 3144 E	Rca	LIN-IC	CTV, Luminance Processor		16-DIP			-
CA 3145 E	Rca	LIN-IC	CTV, Chroma-Verst./Amp., Chroma Demodulator		16-DIP			-
CA 3146 AE	Rca	LIN-IC	=CA 3146E: 50/40V		14-DIP			-
CA 3146 E	Rca	LIN-IC	5x NPN-Trans.-Array, 40/30V, 0,05A, >300MHz		14-DIP			-
CA 3151 E	Rca	LIN-IC	CTV, Chroma Processor, Demodulator		24-DIP			-
CA 3152 E	Rca	BiMOS-OP-IC	MOS In, TV Tuning Band Select, 4xKOP, 18V, 0…+70°		18-DIP			-
CA 3153 E	Rca	LIN-IC	TV, Video IF, Dem., Video-Verst./Amp., AGC		16-DIP			-
CA 3154 E	Rca	LIN-IC	TV, HA Sync. Signal Processor, AGC		16-DIP			-
CA 3156 E	Rca	LIN-IC	CTV, Video/Chroma Processor		16-DIP			-
CA 3157 E	Rca	LIN-IC	TV, HA/VA Digital Sync.-System		14-DIP			-
CA 3158 E	Rca	LIN-IC	CTV, Chroma-System, VCO, Hue Control		16-DIP			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
CA 3159 E	Rca	LIN-IC	TV, HA Processor, AGC Detector		16-DIP			-
CA 3160(A,B)E	Rca	BiMOS-OP-IC	MOS In/Out, ±18V, -55…+125°,InOffs<15(A<5, B<2mV)		8-DIP			-
CA 3160(A,B)S,T	Rca	BiMOS-OP-IC	=CA 3160(A,B)E:Fig. ›		TO-99			-
CA 3161 E	Rca	LIN-IC	BCD ›7-Segment Decoder, +7V		16-DIP			-
CA 3162 E	Rca	A/D-IC	Dual Slope, 3-Digit MPX BCD Display Output, 7V		16-DIP			-
CA 3163 E	Rca	LIN-IC	VHF/UHF-Teiler/Prescaler, ...1GHz, 1:256, 1:64		14-DIP			-
CA 3164 E	Rca	BiMOS-IC	Detector, Alarm System, Ucc=7…11V		14-DIP			-
CA 3165 E	Rca	LIN-IC	Näherungsschalter/Proximity Detector, 2 Outputs		8-DIP			-
CA 3165 E1	Rca	LIN-IC	=CA 3165E: 5 Outputs		14-DIP			-
CA 3166 E	Rca	BiMOS-OP-IC	MOS In, TV Tuning Band Select, AFT Mode Switch,35V		18-DIP			-
CA 3168 E	Rca	LIN-IC	2-Digit BCD ›7-Segment Decoder, +6V		24-DIP			-
CA 3169(M)	Rca	LIN-IC	Solenoid/Motor Driver, 17V, 2,5/3A, M=Horiz. Mount		17/5Pin	TO-220/5		-
CA 3170 E	Rca	LIN-IC	CTV, Chroma-System, VCO, Hue Control		16-DIP			-
CA 3172 E	Rca	LIN-IC	CTV, Chroma Demodulator		14-DIP			-
CA 3179 E	Rca	ECL-IC	VHF/UHF-Teiler/Prescaler, 1,25GHz, 1:256, 1:64		14-DIP			-
CA 3183 AE	Rca	LIN-IC	=CA 3183E: 50/40V		16-DIP			-
CA 3183 E	Rca	LIN-IC	5x NPN-Trans.-Array, 40/30V, 0,075A		16-DIP			-
CA 3189 E	Rca	LIN-IC	HiFi, FM IF, Dem., LF Inp, AFC, AGC(progr.)		16-DIP			TCA 3189, LM 3189N
CA 3190 E	Rca	LIN-IC	TV, HA/VA Digital Sync.-System		14-DIP			-
CA 3191 E	Rca	LIN-IC	TV, Video IF, Sync. Separator, AGC(pos./neg.)		16-DIP			-
CA 3192 E	Rca	LIN-IC	TV, Video IF, Dem., Video-Verst./Amp., AFT		16-DIP			-
CA 3193 AE,AS,AT	Rca	BiMOS-OP-IC	=CA 3193E: ±18V, -25…+85°					-
CA 3193 BE,BS,BT	Rca	BiMOS-OP-IC	=CA 3193E: ±22V, -55…+125°					-
CA 3193 E	Rca	BiMOS-OP-IC	Bipolar In/Out, hi-prec, ±18V, 0…+70°		8-DIP			-
CA 3193 S,T	Rca	BiMOS-OP-IC	=CA 3193E: Fig. ›		TO-99			-
CA 3194 E	Rca	LIN-IC	CTV, PAL Luminance/Chroma Processor		24-DIP			-
CA 3195	Rca	LIN-IC	PLL FM MPX Stereo-Decoder, Ucc=10…16V		16-DIP			-
CA 3199 E	Rca	ECL-IC	VHF/UHF-Teiler/Prescaler, 1,3GHz, 1:4		8-DIP			-
CA 3201 E	Rca	LIN-IC	CTV, Chroma Processor, Demodulator		24-DIP			-
CA 3202 E	Rca	LIN-IC	TV, HA/VA Digital Sync.-System		14-DIP			-
CA 3207 E	Rca	BiMOS-IC	Sequencer Driver f. FLT, Ucc=55V		22-DIP			-
CA 3208 E	Rca	BiMOS-IC	Segment Latch-Driver f. FLT, Ucc=55V		22-DIP			-
CA 3209 E	Rca	LIN-IC	HiFi, FM IF, Demodulator, AGC(progr.)		16-DIP			-
CA 3210 E	Rca	LIN-IC	TV, HA/VA Digital Sync.-System		24-DIP			-
CA 3211 E	Rca	LIN-IC	VHF/UHF-Teiler/Prescaler, 1GHz, 1:256		18-DIP			-
CA 3215 E	Rca	LIN-IC	Video Disk, FM IF, PLL Detector Limiter		16-DIP			-
CA 3216 E	Rca	LIN-IC	CTV, Chroma Processor		24-DIP			-
CA 3217 E	Rca	LIN-IC	CTV, Chroma/Luminance Processor		28-DIP			-
CA 3219 E	Rca	LIN-IC	Quad Power NAND Driver, Logic Interface		16-DIP			-
CA 3221 E	Rca	LIN-IC	CTV, Chroma-Verst./Amp., Demodulator (NTSC)		16-DIP			-
CA 3223 E	Rca	LIN-IC	TV, HA/VA Digital Sync.-System		24-DIP			-
CA 3227 E	Rca	LIN-IC	5x NPN-Trans.-Array, VHF, 12/8V, 20mA, >3GHz		16-DIP			-
CA 3228(E)	Rca	LIN-IC	Speed-Control System		24-DIP			-
CA 3240(A)E	Rca	BiMOS-OP-IC	=CA 3140(A)E: Dual		8-DIP			-
CA 3240(A)E1	Rca	BiMOS-OP-IC	=CA 3140(A)E: Dual		14-DIP			-
CA 3246 E	Rca	LIN-IC	5x NPN-Trans.-Array, VHF, 12/8V, 20mA, >3GHz		14-DIP			-
CA 3260(A,B)E	Rca	BiMOS-OP-IC	=CA 3160(A,B)E: Dual		8-DIP			-
CA 3260(A,B)S,T	Rca	BiMOS-OP-IC	=CA 3160(A,B)E: Dual		TO-99			-
CA 3280	Rca	OP-IC	Dual, Variable, ±18V, InOffset<3mV, 0…+70°		16-DIP			-
CA 3280 A	Rca	OP-IC	=CA 3280: InOffset<0,5mV, -55…+125°		16-DIP			-
CA 3290(A,B)E	Rca	BiMOS-OP-IC	MOS In,±18(B=±22)V,-55…+125°, Offs<20(A<10,B<6mV)		8-DIP			-
CA 3290(A)E1	Rca	BiMOS-OP-IC	=CA 3290(A,B)E: Fig. ›		14-DIP			-
CA 3290(A,B)S,T	Rca	BiMOS-OP-IC	=CA 3290(A,B)E: Fig. ›		TO-99			-
CA 3300(D)	Rca	CMOS-A/D-IC	6 Bit, hi-speed, Video, 15MHz		18-DIC			-
CA 3302...	Rca	KOP-IC	=LM 3302...		14-DIP			›LM 3302...
CA 3308(D)	Rca	CMOS-A/D-IC	8 Bit, hi-speed, Video, 15MHz		24-DIC			-
CA 3401 E,G	Rca	OP-IC	Quad, +18V, 5MHz, -55…+125°		14-DIP,DIC			MC 3401...
CA 3420 E,AE,BE	Rca	BiMOS-OP-IC	PMOS In, 22V, -55…+125°, InOffs.<10mV(A<5, B<2mV)		8-DIP			-
CA 3420(A,B)S,T	Rca	BiMOS-OP-IC	=CA 3420E...: Fig. ›		TO-99			-
CA 3440 E,AE,BE	Rca	BiMOS-OP-IC	PMOS In(10pA), lo-power, ±12,5V, -55…+125° InOffs.<10mV (A<5mV, B<2mV)		8-DIP			-
CA 3440(A,B)S,T	Rca	BiMOS-OP-IC	=CA 3440E...: Fig. ›		TO-99			-
CA 3493 AE,AS,AT	Rca	BiMOS-OP-IC	=CA 3493E: ±18V, -25…+85°					-
CA 3493 BE,BS,BT	Rca	BiMOS-OP-IC	=CA 3493E: ±22V, -55…+125°					-
CA 3493 E	Rca	BiMOS-OP-IC	Bipolar In/Out, hi-prec, ±18V, 0…+70°		8-DIP			-
CA 3493 S,T	Rca	BiMOS-OP-IC	=CA 3493E: Fig. ›		TO-99			-
CA 3524(E)	Rca	LIN-IC	=CA 1524: 0…+70°		16-DIP			›SG 3524
CA 3600 E	Rca	MOS-IC	6x N-FET/3x P-FET, 15V, 10mA		14-DIP			-
CA 6078 AS,AT	Rca	OP-IC	lo-power, lo-volt(>±0,75V), ±18V, -55…+125°		TO-99			-
CA 6741 CS,CT	Rca	OP-IC	=CA 6741S,T: ±18V, 0…+70°		TO-99			... 741C...
CA 6741 S,T	Rca	OP-IC	Serie 741, lo-noise, ±22V, -55…+125°		TO-99			... 741...
CA 7607 E	Rca	LIN-IC	TV, Video IF System f.SAW Filter, AGC(f.FET Tuner)		16-DIP			-
CA 7611 E	Rca	LIN-IC	TV, Video IF System f.SAW Filter, AGC(f.NPN Tuner)		16-DIP			-
CAC		Si-N	=BC 868 (SMD-Marking)		39	SOT-89		›BC 868
CB....CC								
CB		Si-N	=2SC3646 (SMD-Marking)		39	SOT-89		›2SC3646
CB		Si-N	=2SD1368-CB (SMD-Marking)		39	SOT-89		›2SD1368
CB		Si-P	=BCW 61RB (SMD-Marking)		35	SOT-23		›BCW 61RB
CB		Si-N	=BCX 68-10 (SMD-Marking)		39	SOT-89		›BCX 68-10
CB		Si-N	=BFS 19 (SMD-Marking)		35	SOT-23		›BFS 19
CB		Si-N/P+R	=XN 4315 (SMD-Marking)		46	SOT-163		›XN 4315
CB		Si-N/P+R	=XP 4315 (SMD-Marking)		46(2mm)	SOT-363		›XP 4315
CB		MOS-P-FET-e	=µPA573T (SMD-Marking)		45(2mm)	SOT-353		›µPA573T
CBC		Si-N	=BC 868-... (SMD-Marking)		39	SOT-89		›BC 868
CBG		Si-N	=2SC3324-GR (SMD-Marking)		35	SOT-23		›2SC3324
CBL		Si-N	=2SC3324-BL (SMD-Marking)		35	SOT-23		›2SC3324
CBN		Si-N	=2SC4132-N (SMD-Marking)		39	SOT-89		›2SC4132
CBP		Si-N	=2SC4132-P (SMD-Marking)		39	SOT-89		›2SC4132
CBQ		Si-N	=2SC4132-Q (SMD-Marking)		39	SOT-89		›2SC4132
CBR		Si-N	=2SC4132-R (SMD-Marking)		39	SOT-89		›2SC4132
CC		Si-P	=2SA1122-C (SMD-Marking)		35	SOT-23		›2SA1122
CC		Si-P	=2SA1364-C (SMD-Marking)		39	SOT-89		›2SA1364

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
CC		Si-N	=2SC3647 (SMD-Marking)		39 SOT-89			›2SC3647
CC		Si-N	=2SD1368-CC (SMD-Marking)		39 SOT-89			›2SD1368
CC		Si-P	=BCW 61RC (SMD-Marking)		35 SOT-23			›BCW 61RC
CC		Si-N	=BCX 68-16 (SMD-Marking)		39 SOT-89			›BCX 68
CC		Si-N	=BF 544 (SMD-Marking)		35 SOT-23			›BF 544
CC 6168 F		Si-N	≈BF 254			BF 255	7d	›BF 254
CC 6168 G		Si-N	≈BC 239			BC 550	7a	›BC 239
CC 6225(F)		Si-N	≈BF 255			BF 255	7d	›BF 255
CC 6227(F)		Si-N	≈BF 254			BF 255	7d	›BF 254
CC 62266		Si-N	≈BF 254			BF 255	7d	›BF 254
CC 62276		Si-N	≈BF 254			BF 255	7d	›BF 254
CC A		Si-N	=2SC3326A (SMD-Marking)		35 SOT-23			›2SC3326A
CC B		Si-N	=2SC3326B (SMD-Marking)		35 SOT-23			›2SC3326B
CCC		Si-N	=BC 868-... (SMD-Marking)		39 SOT-89			›BC 868
CCS 2001(G)		Si-N	≈BF 254			BF 255	7d	›BF 254
CCS 2004(B,D)		Si-N	≈BC 238			BC 546	7a	›BC 238
CCS 2006(G)		Si-N	≈BF 255			BF 255	7d	›BF 255
CCS 2008(G,GF)		Si-N	≈BF 254			BF 255	7d	›BF 254
CCS 2053(EFG)		Si-N	≈BC 337			BC 337	7a	›BC 338
CCU-06A		MOS-IC	FB		40-DIP			
CCU 2000....200x	Itt	HMOS-µC-IC	TV, 8 Bit, 96x8 Bit RAM, 3,875kB ROM		40-DIP			-
CCU 2030....203x	Itt	HMOS-µC-IC	TV, 8 Bit, 120x8 Bit RAM, 6,5kB ROM		40-DIP			-
CCU 2050....205x ...	Itt	HMOS-µC-IC	TV, 8 Bit, 256x8 Bit RAM, 8kB ROM		40-DIP			-
CCU 2070....207x ...	Itt	HMOS-µC-IC	TV, 8 Bit, 256x8 Bit RAM, 16kB ROM		40-DIP			-
CCU 3000....	Itt	CMOS-IC	TV, Zentralprozessor/Central Processor					-
CCU-N6 10CR525		MOS-IC	FB		40-DIP			-
CD								
CD 0000		Ge-Di	≈1N34		31a	AA 133, 1N4148	31a	›1N34
CD		Si-P	=2SA1122-D (SMD-Marking)		35 SOT-23			›2SA1122
CD		Si-P	=2SA1364-D (SMD-Marking)		39 SOT-89			›2SA1364
CD		Si-P	=2SA1366-D (SMD-Marking)		35 SOT-23			›2SA1366
CD		Si-N	=2SC3648 (SMD-Marking)		39 SOT-89			›2SC3648
CD		Si-P	=BCW 61RD (SMD-Marking)		35 SOT-23			›BCW 61RD
CD		Si-N	=BCX 68-25 (SMD-Marking)		39 SOT-89			›BCX 68-25
CD(s)		Si-N	=BSS 81B (SMD-Marking)		35 SOT-23			›BSS 81B
CD 0014		Si-Di	≈BAV 20			BA 159	31a	›BAV 20
CD 0014 N(NA,NG)		Si-N	≈BC 337			BC 337	7a	›BC 337
CD 021		Si-Di	≈BA 127		31a	1N4148	31a	›BA 127
CD 0089		Si-Di	≈BA 100		31a	1N4148	31a	›BA 100
CD 0099		Si-Di	≈BA 100		31a	1N4148	31a	›BA 100
CD 0140		Z-Di	7,5V		31a	Z-Diode 7,5V	31a	BZW22/..., BZX61/..., ZYP..., 1N5236,++
CD 624		Si-Di	≈RGP 30		31a	BYW 96 E	31a	›RGP 30 G....M
CD 951		Si-P	≈BC 309		7e TO-92	BC 560	7a	›BC 309
CD 1602		Si-P	≈BC 309			BC 560	7a	›BC 309
CD 3226 E	Rca	CMOS-IC	µComp. ›Video Disk Interface Digital Buffer(DAXI)		14-DIP			-
CD 4000....4599	Rca	CMOS-Logic	Standard CMOS-Logic 4000-Serie			›4xxx (C-MOS)		... 4000 ... 4xxx (CMOS)
CD 5000 D		Si-N	≈BF 255		2a	BF 255	7d	›BF 255
CD 9000		Si-P	≈BC 307		2a	BC 556	7a	›BC 307
CD 15000 C,D		Si-N	≈BC 237		2a	BC 546	7a	›BC 237
CD 15000 E		Si-N	≈BF 254		2a	BF 255	7d	›BF 254
CDC		Si-N	=BC 868-... (SMD-Marking)		39 SOT-89			›BC 868
CDC 8002		Si-N	≈BC 639			BC 639	7c	›BC 639
CDC 9002		Si-P	≈BC 640			BC 640	7c	›BC 640
CDD 5000		Ge-Di	≈AA 119		31a	AA 119	31a	›AA 119
CDG 00		Si-Di	≈BA 216		31a	1N4148	31a	›BA 216
CDG 20		Si-Di	≈1N4148		31a	1N4148	31a	›1N4148
CDG 21		Ge-Di	≈AA 119		31a	AA 119	31a	›AA 119
CDG 22		Ge-Di	≈AA 119		31a	AA 119	31a	›AA 119
CDG 23		Si-Di	≈BA 127		31a	1N4148	31a	›BA 127
CDG 24		Si-Di	≈BA 216		31a	1N4148	31a	›BA 216
CDG 25		Si-Di	≈BA 127		31a	1N4148	31a	›BA 127
CDG 26		Si-Di	≈BA 127		31a	1N4148	31a	›BA 127
CDG 27		Si-Di	≈BA 216		31a	1N4148	31a	›BA 216
CDT 1310	Itt	Ge-P	LF,S P, 40/35/35V, 5A, 45W		23a TO-3			AL 102, AUY 28, 2N1539...43, 2N1544...48
CDT 1311	Itt	Ge-P	=CDT 1310: 60/55/30V		23a TO-3			AL 102, AUY 28, 2N1540...43, 2N1545...48
CDT 1312	Itt	Ge-P	=CDT 1310: 80/65/35V		23a TO-3			AL 102, AUY 28, 2N1541...43, 2N1546...48
CDT 1313	Itt	Ge-P	=CDT 1310: 100/80/50V		23a TO-3			AL 102, AUY 37, 2N1542...43, 2N1547...48
CDT 1315	Stc	Ge-P	LF,S P, 100/75V, 8A, 45W		23a TO-3			AL 100, AUY 37, 2N2290, 2N2293
CDT 1319	Stc	Ge-P	LF,S P, 40/35/35V, 5A, 45W		23a TO-3			AL 102, AUY 28, 2N1539...43, 2N1544...48
CDT 1320	Stc	Ge-P	=CDT 1319: 60/50/35V		23a TO-3			AL 102, AUY 28, 2N1540...43, 2N1545...48
CDT 1321	Stc	Ge-P	=CDT 1319: 80/65/35V		23a TO-3			AL 102, AUY 28, 2N1541...43, 2N1546...48
CDT 1322	Stc	Ge-P	=CDT 1319: 100/75/35V		23a TO-3			AL 102, AUY 37, 2N1542...43, 2N1547...48
CDT 1349(A)	Clv	Ge-P	≈2N2063...2064		23a TO-3			›2N2063...2064
CDT 1350(A)	Clv	Ge-P	≈2N2065...2066		23a TO-3			›2N2065...2066
CE....CK								
CE		Si-P	=2SA1122-E (SMD-Marking)		35 SOT-23			›2SA1122
CE		Si-P	=2SA1364-E (SMD-Marking)		39 SOT-89			›2SA1364
CE		Si-P	=2SA1366-E (SMD-Marking)		35 SOT-23			›2SA1366
CE		Si-N	=2SC3649 (SMD-Marking)		39 SOT-89			›2SC3649
CE		Si-P	=BCP 69 (SMD-Marking)		≈39° SOT-223			›BCP 69
CE		Si-P	=BCX 69 (SMD-Marking)		39 SOT-89			›BCX 69
CE(s)		Si-N	=BSS 79B (SMD-Marking)		35 SOT-23			›BSS 79B
CE 1 A3Q	Nec	Si-N+Di+R	Rb=1k, Rbe=10kΩ, Z-Di(C ›B), 60/60±10V, ±2/3A, 1W hi-hFE>1000		9b (SP-8)			-
CE 1 F3P	Nec	Si-N+Di+R	=CE 1A3Q: Rb=2,2k, Rbe=10kΩ		9b (SP-8)			-
CE 1 N2R	Nec	Si-N+Di+R	=CE 1A3Q: Rb=0,68k, Rbe=10kΩ		9b (SP-8)			-
CE 2 A3Q...N2R	Nec	Si-N+Di+R	=CE 1A3Q...N2R: ohne/without. Z-Di		9b (SP-8)			-
CEC		Si-P	=BC 869 (SMD-Marking)		39 SOT-89			›BC 869
CEN		Si-N	=2SC4505-N (SMD-Marking)		39 SOT-89			›2SC4505
CEO		Si-N	=2SC3325-O (SMD-Marking)		35 SOT-23			›2SC3325
CEP		Si-N	=2SC4505-P (SMD-Marking)		39 SOT-89			›2SC4505

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
CEQ		Si-N	=2SC4505-Q (SMD-Marking)		39 SOT-89			›2SC4505
CEY		Si-N	=2SC3325-Y (SMD-Marking)		35 SOT-23			›2SC3325
CF		Si-P	=2SA1366-F (SMD-Marking)		35 SOT-23			›2SA1366
CF		Si-N	=2SC3650 (SMD-Marking)		39 SOT-89			›2SC3650
CF		Si-P	=BCX 69-10 (SMD-Marking)		39 SOT-89			›BCX 69-10
CF(s)		Si-N	=BSS 79C (SMD-Marking)		35 SOT-23			›BSS 79C
CF 1		GaAs-FET	=CF 910 (SMD-Marking)		44 SOT-143			›CF 910
CF 3		GaAs-FET	=CF 912 (SMD-Marking)		44 SOT-143			›CF 912
CF 4		GaAs-FET	=CF 922 (SMD-Marking)		44 SOT-143			›CF 922
CF 5		GaAs-FET	=CF 930 (SMD-Marking)		44 SOT-143			›CF 930
CF 100	Aeg	GaAs-N-FET-d	Dual-Gate, UHF, ...2GHz, 10/6V, 80mA, Gp=21dB(800M)		25g SOT-103			-
CF 121	Aeg	GaAs-N-FET-d	=CF 100: integr. Gateschutz-Dioden/Gate Protection		25g SOT-103			-
CF 221	Aeg	GaAs-N-FET-d	Dual-Gate, UHF, ...2GHz, 10/6V, 80mA, Gp=17dB(800M)		25o SOT-103			-
CF 300	Aeg	GaAs-N-FET-d	Dual-Gate, UHF, ...2GHz, 10/6V, 80mA, Gp=23dB(800M)		25g SOT-103			-
CF 400	Aeg	GaAs-N-FET-d	Dual-Gate, UHF, ...2GHz, 10/6V, 80mA, Gp=17dB(800M)		25o SOT-103			-
CF 739	Sie	GaAs-N-FET-d	SMD, Dual-Gate, VHF/UHF/SATV, 10/6V, 80mA Idss=6...60ma, Up<2,5V, F=1,8/Gp=17dB(1750MHz)		44g SOT-143			-
CF 750	Sie	GaAs-N-FET	Dual-Gate, Wideband, 8/5V, 80mA, 0,4...3GHz Idss=50mA, F=1,9/Gp=9dB(1800MHz)		44 SOT-143			-
CF 910	Aeg	GaAs-N-FET-d	=CF 100: SMD		44g SOT-143			-
CF 912	Aeg	GaAs-N-FET-d	=CF 121: SMD		44g SOT-143			-
CF 922	Aeg	GaAs-N-FET-d	=CF 221: SMD		44g SOT-143			-
CF 930	Aeg	GaAs-N-FET-d	=CF 300: SMD		44g SOT-143			-
CF 930R	Aeg	GaAs-N-FET-d	=CF 300: SMD		44-? SOT-143			-
CF 940	Aeg	GaAs-N-FET-d	=CF 400: SMD		44g SOT-143			-
CF 2386	Tdy	N-FET	Uni, 25V, 0,5W, Idss<9mA, Up<-8V		2a TO-5			BF 244...245, BFW 10, 2N3819, 2N4222, ++
CFK 10	Aeg	GaAs-N-FET-d	Dual-Gate, UHF, ...2GHz, 10/6V, 50mA, Gp=21dB(800M)		51(G2DSG1) SOT-173			-
CFK 12	Aeg	GaAs-N-FET-d	=CFK 10: integr. Gateschutz-Dioden/Gate Protection		51(G2DSG1) SOT-173			-
CFK 22	Aeg	GaAs-N-FET-d	=CFK 10: int. Gateschutz/protect., Gp=17dB(800MHz)		51(G2DG1S) SOT-173			-
CFK 30	Aeg	GaAs-N-FET-d	Dual-Gate, UHF, ...2GHz, 10/6V, 80mA, Gp=30dB(800M)		51(G2DSG1) SOT-173			-
CFK 40	Aeg	GaAs-N-FET-d	Dual-Gate, UHF, ...2GHz, 10/6V, 80mA, Gp=17dB(800M)		51(G2DG1S) SOT-173			-
CFM 13026	Tsc	N-FET	Uni, 40V, Idss<50mA, Up<-7V		2a TO-18			BF 348, BFT 10, 2N4091...4092
CFQ		Si-N	=2SD2150-Q (SMD-Marking)		39 SOT-89			›2SD2150
CFR		Si-N	=2SD2150-R (SMD-Marking)		39 SOT-89			›2SD2150
CFS		Si-N	=2SD2150-S (SMD-Marking)		39 SOT-89			›2SD2150
CFX 13	Phi	GaAs-FET	Mikro-W., 5/6V, 100mA, F<3dB/Gp=6,5dB(12GHz)		52 (SGSD) SOT-100			-
CFX 14	Phi	GaAs-FET	=CFX 13: F<3dB/Gp=6dB(16GHz)		52 (SGSD) SOT-100			-
CFX 21	Phi	GaAs-FET	Mikro-W., 8/6V, 110mA, Up=-4V, Gp>11dB(11GHz)		52 (SGSD) SOT-100			-
CFX 30	Phi	GaAs-FET	Mikro-W., 15/12V, 130mA, Up=-2,5V, Gp>7dB(11GHz)		62f (11x3,4mm)			-
CFX 31	Phi	GaAs-FET	Mikro-W., 15/12V, 250mA, Up=-4V, Gp>7dB(11GHz)		62f (11x3,4mm)			-
CFX 32	Phi	GaAs-FET	Mikro-W., 15/12V, 500mA, Up=-4V, Gp>7dB(8,5GHz)		62f (11x3,4mm)			-
CFX 33	Phi	GaAs-FET	Mikro-W., 15/12V, 600mA, Up=-4V, Gp>5dB(8,5GHz)		62f (11x3,4mm)			-
CFY 10	Sie	GaAs-N-FET-d	Mikro-W., 5/5V, 100mA, F<1,8dB/Gp>9,5dB(6GHz)		52 (SDSG) SOT-100			-
CFY 11	Sie	GaAs-FET	Mikro-W.,5/5V, 100mA, Up=-2,5V, F<2,2/Gp>9dB(6GHz)		52 (SDSG) SOT-100			-
CFY 12	Sie	GaAs-FET	Mikro-W.,5/5V, 100mA, Up=-2,5V, F<2,7/Gp>7,5dB(6G)		52 (SDSG) SOT-100			-
CFY 13	Sie	GaAs-FET	=CFY 11:		51 (SDSG) SOT-173			-
CFY 14	Sie	GaAs-FET	=CFY 12:		51 (SDSG) SOT-173			-
CFY 15	Sie	GaAs-FET	=CFY 10		52 (SDSG) SOT-100			-
CFY 16	Sie	GaAs-FET	=CFY 10		52 (SDSG) SOT-100			-
CFY 17	Sie	GaAs-FET	=CFY 10:		51 (SDSG) SOT-173			-
CFY 18	Sie	GaAs-FET	=CFY 10: F<1,2dB/Gp>10dB(6GHz)		51 (SDSG) SOT-173			-
CFY 19	Sie	GaAs-N-FET-d	Mikro-W., 5/5V, 100mA, F<1,8db/Gp>9,5dB(6GHz)		51 (SDSG) SOT-173			-
CFY 20	Sie	GaAs-FET	Dual-Gate, F=1,8dB/Gp=16,5dB(4GHz)		52 SOT-100			-
CFY25(-17,-20,-25)	Sie	GaAs-N-FET-d	Mikro-W., 7/5V, 80mA, Idss=15...60mA, Up=0,3...3V -17: F<1,7/Gp>9dB(12GHz), -20: F<2/Gp>8,5dB(12GHz) -25: F<2,3/Gp>8,5dB(12GHz)		51 (SDSG) SOT-173			-
CFY 30	Sie	GaAs-N-FET-d	SMD, Mikro-W., 7/5V, 80mA, Idss=20...80mA Up=0,5...4V, F<1,6(4GHz), Gp=8,9dB(6GHz)		44 (GSDS) SOT-143			-
CFY 35(-20,-23)	Sie	GaAs-N-FET-d	Mikro-W., 6/5V, 60mA, Idss=10...45mA, Up=0,2...2,5V -20: F<2/Gp>8dB(12GHz), -23: F<2,3dB(12GHz)		≈44(GSDS)			-
CFY 65(-12,-14)	Sie	GaAs-N-FET-d	Min, Mikro-W.(HEMT), 5,5/4V, 70mA, Idss=10...70mA Up<2,5V, -12: F<1,2/Gp>10dB, -14: F<1,4dB(12GHz)		51 (SDSG) SOT-173			-
CFY 66	Sie	GaAs-N-FET	Min,Mikro-W., 3,5/3V, 60mA, F=0,7/Gp=10,5dB(12GHz)		51 (SDSG) SOT-173			-
CFY 75(-13,-15)	Sie	GaAs-N-FET-d	SMD, UHF Inp ...20GHz, 5/4V, 70mA, Idss=10...70mA Up=0,2...2,5V, -13: F<1,3/Gp>9,5dB(12GHz) -15: F<1,5/Gp>9dB(12GHz)		≈44 (GSDS)			-
CFY 76-08	Sie	GaAs-N-FET	SMD, Mikro-W.(HEMT-FET), 3,5/3V, 60mA F=0,7/Gp=10,5dB(12GHz)		≈44 (GSDS)			-
CFY 77(-08,-10)	Sie	GaAs-N-FET-d	SMD, Mikro-W.(HEMT), 3,5/3V, 60mA, Idss=10...60mA Up=0,2...2V, -08: F<0,8/Gp>10dB(12GHz) -10: F<1/Gp>9,5dB(12GHz)		≈44			-
CG		Si-P	=2SA1163-GR (SMD-Marking)		35 SOT-23			›2SA1163
CG		Si-P	=2SA1587-GR (SMD-Marking)		35 SOT-23			›2SA1587
CG		Si-N	=2SC3651 (SMD-Marking)		39 SOT-89			›2SC3651
CG		Si-P	=BCX 69-16 (SMD-Marking)		39 SOT-89			›BCX 69-16
CG		Si-P	=BCX 71RG (SMD-Marking)		35 SOT-23			›BCX 71RG
CG(s)		Si-N	=BSS 81C (SMD-Marking)		35 SOT-23			›BSS 81C
CG 1	Gie	Si-Di	TV Damper-Di, 1400V, 1,5A, Uf<1,1V(1A), <15µs		31a SOD-57	BY 228	31a	BY 228, BY 448
CG 2	Gie	Si-Di	=CG 1: 2A, Uf<1,1V(2A)		31a SOD-57	BY 228	31a	BY 228, BY 448
CG 3	Gie	Si-Di	=CG 1: 3A, Uf<1,2V(3A)		31a SOD-64	BY 228	31a	BY 228
CG 61 H		Ge-Di	≈AA 133		31a	AA 133	31a	›AA 133
CG 64 H		Ge-Di	≈1N34			AA 133	31a	›1N34
CGC		Si-P	=BC 869-... (SMD-Marking)		39 SOT-89			›BC 869
CGG		Si-N	=2SC3426-GR (SMD-Marking)		35 SOT-23			›2SC3426
CGL		Si-N	=2SC3426-BL (SMD-Marking)		35 SOT-23			›2SC3426
CGP		Si-N	=2SC5053-P (SMD-Marking)		39 SOT-89			›2SC5053
CGQ		Si-N	=2SC5053-Q (SMD-Marking)		39 SOT-89			›2SC5053
CGR		Si-N	=2SC5053-R (SMD-Marking)		39 SOT-89			›2SC5053
CGY		Si-N	=2SC3426-Y (SMD-Marking)		35 SOT-23			›2SC3426
CGY 10...14	Aeg	(GaAs)-Di	Gunn Di., UHF		SOD-31			-
CGY 20...50	Sie	GaAs-FET	UHF, Breitbandverst./Wideband Amplifier					-
CH		Si-Di	=1SS351 (SMD-Marking)		35 SOT-23			›1SS351
CH		Si-P	=2SB1002-CH (SMD-Marking)		39 SOT-89			›2SB1002

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
CH		Si-N	=2SC4272 (SMD-Marking)		39	SOT-89			›2SC4272
CH		Si-P	=BCX 69-25 (SMD-Marking)		39	SOT-89			›BCX 69
CH(s)		Si-P	=BSS 80B (SMD-Marking)		35	SOT-23			›BSS 80B
CHC		Si-P	=BC 869-... (SMD-Marking)		39	SOT-89			›BC 869
CHO		Si-N	=2SC3437-O (SMD-Marking)		35	SOT-23			›2SC3437
CHO		Si-N	=2SC4667-O (SMD-Marking)		35(2mm)	SOT-323			›2SC4667
CHR		Si-N	=2SC3437-R (SMD-Marking)		35	SOT-23			›2SC3437
CHR		Si-N	=2SC4667-R (SMD-Marking)		35(2mm)	SOT-323			›2SC4667
CHY		Si-N	=2SC3437-Y (SMD-Marking)		35	SOT-23			›2SC3437
CHY		Si-N	=2SC4667-Y (SMD-Marking)		35(2mm)	SOT-323			›2SC4667
CI		Si-N	=2SC4080 (SMD-Marking)		39	SOT-89			›2SC4080
CI		Si-N	=2SD1777 (SMD-Marking)		44	SOT-143			›2SD1777
CIC 7641		LIN-IC	›TA 7641BP		16-DIP				›TA 7641BP
CIC 9185		LIN-IC	›KA 2412A		14-DIP				KA 2412A, LS 285A
CJ		Si-P	=2SB1002-CJ (SMD-Marking)		39	SOT-89			›2SB1002
CJ		Si-N	=2SC4390 (SMD-Marking)		39	SOT-89			›2SC4390
CJ		MOS-N-FET-d	=2SK1067 (SMD-Marking)		35(2mm)	SOT-323			›2SK1067
CJ		MOS-N-FET-d	=2SK543 (SMD-Marking)		35	SOT-23			›2SK543
CJ(s)		Si-P	=BSS 80C (SMD-Marking)		35	SOT-23			›BSS 80C
CK		Si-N	=2SC4520 (SMD-Marking)		39	SOT-89			›2SC4520
CK		Si-N	=2SD999-CK (SMD-Marking)		39	SOT-89			›2SD999
CK		Si-P	=BCX 71RK (SMD-Marking)		35	SOT-23			›BCX 71RK
CK		Si-P+R	=XN 6114 (SMD-Marking)		46	SOT-163			›XN 6114
CK		Si-P+R	=XP 6114 (SMD-Marking)		46(2mm)	SOT-363			›XP 6114
CK 300		IC	Digital-Uhr/Digital Clock		28-DIP				-
CL....CR									
CL		Si-P	=2SA1163-BL (SMD-Marking)		35	SOT-23			›2SA1163
CL		Si-P	=2SA1342 (SMD-Marking)		35	SOT-23			›2SA1342
CL		Si-P	=2SA1587-BL (SMD-Marking)		35(2mm)	SOT-323			›2SA1587
CL		Si-P	=2SA1677 (SMD-Marking)		35(2mm)	SOT-323			›2SA1677
CL		Si-N	=2SC4521 (SMD-Marking)		39	SOT-89			›2SC4521
CL		Si-N	=2SD999-CL (SMD-Marking)		39	SOT-89			›2SD999
CL(s)		Si-P	=BSS 82B (SMD-Marking)		35	SOT-23			›BSS 82B
CL 055(A....D)	Mic	Si-P	LF Drv25/20V, 1/1,5A, 0,625W, 120MHz	{CL066	7e	TO-92	BC 327	7a	BC 327...328, BC 636, BC 638, 2SB1116,++
CL 055...P		Si-P	=CL 055...: 0,75W		30e	TO-237	(2SA1593)[5]	30j	2SB968, 2SB1181...82, (BD 506, BD 508),++[6]
CL 066(A....D)	Mic	Si-N	LF Drv, 25/20V, 1/1,5A, 0,625W, 120MHz	{CL055	7e	TO-92	BC 337	7a	BC 337...338, BC 635, BC 637, 2SD1616,++
CL 066...P		Si-N	=CL 066...: 0,75W		30e	TO-237	(2SC4135)[5]	30j	2SD1078, 2SD1295, (BD 505, BD 507), ++[6]
CL 116 P		Si-P	=BC 307		7a	TO-92	BC 556	7a	›BC 307
CL 151-3(A...C)	Mic	Si-N	Min, Uni, -/10V, 0,1A, 0,1W	{CL152	≈36b				BC 122...123, BC 146
CL 151-4(A...C)		Si-N	=CL 151-3:		7c	SOT-42			BC 122...123, BC 146
CL 152-3(A...C)	Mic	Si-P	Min, Uni, -/10V, 0,1A, 0,1W	{CL151	≈36b				BC 200, BC 202...203
CL 152-4(A...C)		Si-P	=CL 152-3:		7c	SOT-42			BC 200, BC 202...203
CL 155(A....D)	Mic	Si-P	LF Drv, 30/25V, 1,5/2,2A, 0,625W, 120MHz	{CL166	7e	TO-92	2SB892	7c(9mm)	MPS 650...51, 2SC2236, 2SD1146, 2SD1207
CL 155...P		Si-P	=CL 155.: 0,75W		30e	TO-237	(2SA1593)[5]	30j	2SB968, 2SD1181...82, (BD 506, BD 508),++[6]
CL 166(A....D)	Mic	Si-N	LF Drv, 30/25V, 1,5/2,2A, 0,625W, 120MHz	{CL155	7e	TO-92	2SD1207	7c	MPS 750...51, 2SA966, 2SA1315, 2SA1382
CL 166...P		Si-N	=CL 166...: 0,75W		30e	TO-237	(2SC4135)[5]	30j	2SD1078, 2SD1295, (BD 505, BD 507), ++[6]
CL 168	Mic	Si-N	LF Drv,Out, -/7V, 3A, 0,625W, 120MHz		7c	TO-92	2SD1347	7c(9mm)	2SD879, 2SD1347, 2SD1507, 2SD1617, ++
CL 169	Mic	Si-N	LF Drv,Out, -/9V, 3A, 0,625W, 100MHz		7c	TO-92	2SD1347	7c(9mm)	2SD879, 2SD1347, 2SD1507, 2SD1617, ++
CL 266	Mic	Si-N	LF Drv,Out, -/60V, 2A, 0,625W		7c	TO-92	(2SD1207)[7]	7c	MPS 651, 2SC3328, 2SC3669, 2SC4145
CL 266 P		Si-N	=CL 266: 0,75W		30e	TO-237	(2SC4135)[5]	30j	2SD1079, 2SD1281...82, (BD 519, BD 527)++[6]
CL 855(A....C)	Mic	Si-P	LF Drv, 70/60V, 1/1,5A, 0,625W, 150MHz	{CL866	7e	TO-92	BC 640	7c	BC 640, 2SA1708, 2SB984, 2SB1116A,++
CL 866(A....C)	Mic	Si-N	LF Drv, 70/60V, 1/1,5A, 0,625W, 150MHz	{CL855	7e	TO-92	BC 639	7c	BC 639, 2SC4488, 2SD1768, 2SD1616A,++
CLK 5010	Itt	CMOS-IC	Kfz-Quarzuhr/Car Quartz Clock		16-DIP				-
CLK 5011	Itt	CMOS-IC	Kfz-Quarzuhr/Car Quartz Clock		16-DIP				-
CLY 5	Sie	GaAs-N-FET	UHF, 8/6V, 1,2A, Gp=9,5dB(1,8GHz)		≈39°	SOT-223			-
CLY 10	Sie	GaAs-N-FET	UHF, 8/6V, 2A, Gp=9dB(1,8GHz)		≈39°	SOT-223			-
CM		Si-N	=2SC4504 (SMD-Marking)		39	SOT-89			›2SC4504
CM		Si-N	=2SD999-CM (SMD-Marking)		39	SOT-89			›2SD999
CM(s)		Si-P	=BSS 82C (SMD-Marking)		35	SOT-23			›BSS 82C
CM 4-482 B		Opto							
CMY 90	Sie	GaAs-FET	UHF, Wideband Amp, Ucc=3...6V, F=5,4/Gp=12dB(1845M)						-
CN		Si-N	=2SC4548 (SMD-Marking)		39	SOT-89			›2SC4548
CN 515 T	Fer	OP-IC	=µA 709: -55...+125°						›µA 709
CNX 62	Phi	Opto	Optokoppler, Riso>10GΩ		6-DIP		CNX 62 A	6-DIP	-
CNX 62 A	Phi	Opto	=CNX62: VDE-, SEMKO-, NEMKO-, DEMKO-Spec.		6-DIP		CNX 62 A	6-DIP	-
CNX 82	Phi	Opto	=CNX 83: ohne Basisanschl./no base conn. (Pin 6)		6-DIP		CNX 83 A	6-DIP	-
CNX 82 A	Phi	Opto	=CNX82: VDE-, SEMKO-, NEMKO-, DEMKO-Spec.		6-DIP		CNX 83 A	6-DIP	-
CNX 83	Phi	Opto	Optokoppler, Basis-Anschluß/base connect.(Pin 6)		6-DIP		CNX 83 A	6-DIP	-
CNX 83 A	Phi	Opto	=CNX62: VDE-, SEMKO-, NEMKO-, DEMKO-Spec.		6-DIP		CNX 83 A	6-DIP	-
CNY....		Opto							
CO		Si-N	=2SC2881-O (SMD-Marking)		39	SOT-89			›2SC2881
CO		Si-N	=2SC4209-O (SMD-Marking)		35	SOT-23			›2SC4209
CO		Si-N	=2SC5087-O (SMD-Marking)		44	SOT-143			›2SC5087
CO		Si-N	=KTC4373-O (SMD-Marking)		39	SOT-89			›KTC 4373
CP		Si-P	=2SB767-P (SMD-Marking)		39	SOT-89			›2SB767
CP		Si-N	=2SC2411-CP (SMD-Marking)		≈35	(MMT)			›2SC2411
CP		Si-N	=2SC2411K-P (SMD-Marking)		35	SOT-23			›2SC2411K
CP		Si-N	=2SC4097-P (SMD-Marking)		35(2mm)	SOT-323			›2SC4097
CP		Si-N	=HC 1L2N (SMD-Marking)		39	SOT-89			›HC 1...
CP 8 C...G	Hit	50Hz-Thy	200...600V, 30A(Tc=85°), 47A=, Igt/Ih<50/60mA C=200, D=300, E=400, F=500, G=600V		21b	TO-48			BTW48/..., CS23-..., MCR64-..., TAG35-...
CP 9 C...G	Hit	50Hz-Thy	=CP 8 C...G: TO-48 Flat Base		≈21b				-
CP 1600	Itt	µC-IC	µComp., 8x16 Bit RAM		40-DIC				-
CQ		Si-P	=2SB1219-Q (SMD-Marking)		35(2mm)	SOT-323			›2SB1219
CQ		Si-P	=2SB1582-Q (SMD-Marking)		≈35	(T Mini)			›2SB1582
CQ		Si-P	=2SB710-Q (SMD-Marking)		35	SOT-23			›2SB710
CQ		Si-P	=2SB767-Q (SMD-Marking)		39	SOT-89			›2SB767
CQ		Si-N	=2SC2411-CQ (SMD-Marking)		≈35	(MMT)			›2SC2411
CQ		Si-N	=2SC2411K-Q (SMD-Marking)		35	SOT-23			›2SC2411K

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
CQ		Si-N	=2SC4097-Q (SMD-Marking)		35(2mm)	SOT-323			›2SC4097
CQ		Si-N	=HC 1A3M (SMD-Marking)		39	SOT-89			›HC 1...
CQX....		Opto							
CQY....		Opto							
CR		Si-P	=2SB1219-R (SMD-Marking)		35(2mm)	SOT-323			›2SB1219
CR		Si-P	=2SB1582-R (SMD-Marking)		=35	(T Mini)			›2SB1582
CR		Si-P	=2SB710-R (SMD-Marking)		35	SOT-23			›2SB710
CR		Si-P	=2SB767-R (SMD-Marking)		39	SOT-89			›2SB767
CR		Si-N	=2SC2411-CR (SMD-Marking)		=35	(MMT)			›2SC2411
CR		Si-N	=2SC2411K-R (SMD-Marking)		35	SOT-23			›2SC2411K
CR		Si-N	=2SC4097-R (SMD-Marking)		35(2mm)	SOT-323			›2SC4097
CR		Si-N	=2SC4422 (SMD-Marking)		39	SOT-89			›2SC4422
CR		Si-N	=HC 1F3M (SMD-Marking)		39	SOT-89			›HC 1...
CR		Si-N	=XP 6210 (SMD-Marking)		46(2mm)	SOT-363			›XP 6210
CR 02 AM-....		Thy	=BRX 49		7b	TO-92	BRX 49	7a	›BRX 49
CRT 1544	Itt	Ge-P	LF,S P, 60/40V, 25A, 90W		23a	TO-3			2N1651...1653, 2N2285...2287
CRT 1545	Itt	Ge-P	LF,S P, 80/60V, 25A, 90W		23a	TO-3			2N1652...1653, 2N2286...2287
CRT 1552	Itt	Ge-P	LF,S P, 40/30V, 25A, 90W		23a	TO-3			2N1651...1653, 2N2285...2287
CRT 1553	Itt	Ge-P	LF,S P, 100/75V, 25A, 90W		23a	TO-3			2N1652...1653, 2N2286...2287
CRT 1592	Itt	Ge-P	LF,S P, 80/60V, 35A		23a	TO-3			2N5693...5696
CS									
CS		Si-N	=HC 1F3P (SMD-Marking)		39	SOT-89			›HC 1...
CS		Si-P	=2SA1682 (SMD-Marking)		35	SOT-23			›2SA1682
CS		Si-P	=2SB1219-S (SMD-Marking)		35(2mm)	SOT-323			›2SB1219
CS		Si-P	=2SB1582-S (SMD-Marking)		=35	(T Mini)			›2SB1582
CS		Si-P	=2SB710-S (SMD-Marking)		35	SOT-23			›2SB710
CS		Si-P	=2SB767-S (SMD-Marking)		39	SOT-89			›2SB767
CS		Si-N	=2SD1870 (SMD-Marking)		39	SOT-89			›2SD1870
CS 0,6-02...-12	Bbc	50Hz-Thy	200...1200V, 1,5A(Tc=85°C), 5A=, Igt<10mA		27n				-
CS 0,8-02...-07	Bbc	50Hz-Thy	200...700V, 0,8A(Ta=45°C), 8A=, Igt/Ih<10/20mA		30b	(TO-220MF)	TAG 626-600[4]	17e	BStA30...M, (TAG 632-..., TAG 621-...)[4]
CS 1-02...-12	Bbc	50Hz-Thy	200...1200V, 2A(Tc=85°), 7A=, Igt/Ih<15/40mA		27n		TAG 626-...[4]	17e	BStD36...
CS 1,2-02...-07	Bbc	50Hz-Thy	200...700V, 0,3A(Ta=45°C),10A=, Igt/Ih<15/25mA		30b	(TO-220MF)	TAG 626-600[4]	17e	BStC07..., (TAG 630-..., TAG 620-...)[4]
CS 2,5-04...-06	Bbc	50Hz-Thy	200...600V, 3,2A(Tc=85°C),5A=, Igt/Ih<15/25mA		17e	TO-220	TAG 626-600	17e	TAG 620-..., BStC10..., TIC 116... ++
CS 3-02...-07	Bbc	50Hz-Thy	200...700V, 5A(Tc=85°C), 8A=, Igt/Ih<10/20mA		17e	TO-220	TAG 626-600	17e	T 3,5N..., TAG 661-..., TAG 662-... ++
CS 3,5-02...-07	Bbc	50Hz-Thy	200...700V, 6A(Tc=85°), 10A=, Igt/Ih<15/25mA		17e	TO-220	TAG 626-600	17e	S 2800..., TAG 665-..., TIC 126... ++
CS 3,5-05FZ2	Bbc	50Hz-Thy			13e	TO-202	TAG 626-600[4]	17e	S 2800D, TY 4004, 17122
CS 6-02....08	Bbc	50Hz-Thy	200...800V, 6A(Tc=85°C), Igt/Ih<15/25mA		17e	TO-220			S 2800..., TAG 665-..., TIC 126... ++
CS 10-02....08	Bbc	50Hz-Thy	200...800V, 10A(Tc=85°C), Igt/Ih<25/100mA		17e	TO-220			T 9,5N..., BStD10...M
CS 0014		Si-Di	=BA 100		31a		1N4148	31a	›BA 100
CS 15-02....08	Bbc	50Hz-Thy	200...800V, 15A(Tc=85°C), Igt/Ih<25/100mA		17e	TO-220			-
CS 0080		Si-Di	=BA 100		31a		1N4148	31a	›BA 100
CS 1245(F....T)		Si-N	=BC 337				BC 337	7a	›BC 337
CS 1250(E,F)		Si-N	=BC 639				BC 639	7c	›BC 639
CS 1251(E,F)		Si-P	=BC 640				BC 640	7c	›BC 640
CS 1303		Si-P	=BC 640				BC 640	7c	›BC 640
CS 1312 F,G		Si-P	=BF 450		2a		BF 324	7a	›BF 450
CS 1312 H		Si-P	=BC 309		2a		BC 560	7a	›BC 309
CS 1312 I		Si-P	=BC 307		2a		BC 560	7a	›BC 307
CS 1506 F,G		Si-P	=BC 307		2a		BC 556	7a	›BC 307
CS 1508 E,G		Si-N	=BF 255		2a		BF 255	7d	›BF 255
CS 1509 E,F		Si-N	=BF 254		2a		BF 255	7d	›BF 254
CS 1655		Si-N	=BF 494		7c	TO-92	BF 255	7d	›BF 494
CS 1659		Si-N	=BC 338		7c	TO-92	BC 337	7a	›BC 338
CS 1660		Si-P	=BC 328		7c	TO-92	BC 327	7a	›BC 328
CS 1702		Si-N	=BC 337				BC 337	7a	›BC 337
CS 1774		Si-N	=BC 548		7c	TO-92	BC 546	7a	›BC 548
CS 1909		Si-N	=BC 337		2a		BC 337	7a	›BC 337
CS 1910		Si-P	=BC 327		2a		BC 327	7a	›BC 327
CS 1914(H)		Si-P	=BC 307		2a		BC 556	7a	›BC 307
CS 1978(A)		Si-N	=BC 337		7e	TO-92	BC 337	7a	›BC 337
CS 5609		Si-N	=BC 337				BC 337	7a	›BC 337
CS 5610		Si-P	=BC 327				BC 327	7a	›BC 327
CS 6203 H,I		Si-P	=BC 309		7e	TO-92	BC 560	7a	›BC 309
CS 6208		Si-N	=BC 337		2a		BC 337	7a	›BC 337
CS 6209		Si-P	=BC 327		2a		BC 327	7a	›BC 327
CS 6305(A)		Si-P	=BC 307		2a		BC 556	7a	›BC 307
CS 8204	Chy	LIN-IC	›KA 2410		8-DIP				KA 2410, ML 8204, TA 31001
CS 8205	Chy	LIN-IC	›KA 2411		8-DIP				KA 2411, ML 8205, TA 31002
CS 9003		Si-N	=BC 547		7	TO-92	BC 546	7a	›BC 547
CS 9010		Si-N	=BC 547		7e	TO-92	BC 546	7a	›BC 547
CS 9011(D....I)		Si-N	=SS 9011		7e	TO-92	›SS 9011		›SS 9011
CS 9012(D....I)		Si-P	=SS 9012		7e	TO-92	›SS 9012		›SS 9012
CS 9013(D....I)		Si-N	=SS 9013		7e	TO-92	›SS 9013		›SS 9013
CS 9014(A....C)		Si-N	=SS 9014		7e	TO-92	›SS 9014		›SS 9014
CS 9015(A....C)		Si-P	=SS 9015		7e	TO-92	›SS 9015		›SS 9015
CS 9016(D....H)		Si-N	=SS 9016		7e	TO-92	›SS 9016		›SS 9016
CS 9017		Si-N	AM/FM, -/18V		7e	TO-92	BF 255	7d	BF 225, BF 255, BF 314, BF 495, BF 595++
CS 9018(D....H)		Si-N	=SS 9018		7e	TO-92	›SS 9018		›SS 9018
CS 9020(G,H)		Si-P	=BF 450		7e	TO-92	BF 324	7a	›BF 450
CS 9021		Si-N	=BF 495		7	TO-92	BF 255	7d	›BF 495
CS 9022		Si-N	=BC 547		7	TO-92	BC 546	7a	›BC 547
CS 9102(B)		Si-P	=BC 640				BC 640	7c	›BC 640
CS 9103(B,C)		Si-N	=BC 639				BC 639	7c	›BC 639
CS 9126		Si-N	=BC 548		7e	TO-92	BC 546	7a	›BC 548
CS 9127		Si-P	=BC 558		7e	TO-92	BC 556	7a	›BC 558
CSF....CW									
CSF 0,7-04	Bbc	F-Thy	400V, 3A(Tc=85°C), 4,7A=, Igt/Ih<50/<200mA		17e	TO-220			BT153, TAG650S-400, TAG655S-400
CSF 02 AM 1	Bbc	F-Thy	50V, 0,26A(Ta=45°C), 0,47A=, Igt/Ih<0,25/<2,3mA		7b	TO-92	BRX 49	7a	BRX45...46, BRX 50...51, TAG60F, TAG62F
CSF 02 AM 2		F-Thy	=CSF02AM1: 100V		7b	TO-92	BRX 49	7a	BRX46...47, BRX 50...51, TAG60A, TAG 62A
CSF 02 AM 4		F-Thy	=CSF02AM1: 200V		7b	TO-92	BRX 49	7a	BRX47...48, BRX 52...54, BRY55S/200

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
CSF 02 AM 8		F-Thy	=CSF02AM1: 400V		7b	TO-92	BRX 49	7a	BRX49, BRX 54...56, BRY55S/400
CSF 02 AM 10		F-Thy	=CSF02AM1: 500V		7b	TO-92	(TAG 626-600)[6]	17e	BRX 55...56, BRY55S/500
CSF 7,9-04....08	Bbc	F-Thy	400...800V, 14A(Tc=50°), 58A=, Igt/Ih<100/<100mA		21b	TO-64			-
CSF 11-02....08	Bbc	F-Thy	200...800V, 10A(Tc=85°C), Igt/Ih<35/<80mA		17e	TO-220			-
CSM 2B2	Hit	50Hz-Thy	200V, 2A(Tc=71°), Igt/Ih=1/1,5mA		13b	TO-202	(TIC 106M)[4]	17e	C 107..., TAG 107..., C 106..., TAG 106...
CSM 2B4		50Hz-Thy	=CSM2B2: 400V		13b	TO-202	(TIC 106M)[4]	17e	C 107..., TAG 107..., C 106..., TAG 106...
CSM 3B2	Hit	50Hz-Thy	200V, 3A(Tc=63°), Igt/Ih=1/1,5mA		13b	TO-202	(TIC 106M)[4]	17e	C 107..., TAG 107..., C 106..., TAG 106...
CSM 3B4		50Hz-Thy	=CSM3B2: 400V		13b	TO-202	(TIC 106M)[4]	17e	C 107..., TAG 107..., C 106..., TAG 106...
CSM 5B2	Hit	50Hz-Thy	200V, 5A(Tc=101°), Igt/Ih=30/25mA		17b	TO-220			TAG 651-..., TAG 656-..., (CS 2,5-...,++)[3]
CSM 5B4		50Hz-Thy	=CSM5B2: 400V		17b	TO-220			TAG 651-..., TAG 656-..., (CS 2,5-...,++)[3]
CT		Si-N-Darl+Di	=2SD1472 (SMD-Marking)		39	SOT-89			›2SD1472
CT		Si-N	=2SD1935 (SMD-Marking)		35	SOT-23			›2SD1935
CT		Si-N	=HC 1L2Q (SMD-Marking)		39	SOT-89			›HC 1...
CT 1010	Pls	DIG-IC	TV, Frequ.-Teiler/Prescaler, :64						-
CT 1011	Pls	DIG-IC	TV, Frequ. Synthesizer						-
CT 1117	Pls	DIG-IC	TV, Synthesizer Tuning Interface, Band Switch						-
CT 1133	Pls	DIG-IC	TV, Synthesizer Tuning, Prog. Divider, 100-Ch. ROM						-
CT 1134	Pls	DIG-IC	TV, 100-Channel Control Logic f. CT 1133						-
CT 1650	Pls	DIG-IC	TV, µP-Synthesizer Control, 32 Progr./100 Channels						-
CT 2010	Pls	DIG-IC	TV, Frequ.-T./Prescaler, 1GHz : 380/400, ECL Out		8-DIP				-
CT 2012	Pls	MOS-IC	TV, PLL Frequ. Synthesizer		24-DIP				-
CT 2014	Pls	DIG-IC	TV, Synthesizer Tuning Control, 32 Progr., 400 Ch.		40-DIP				-
CT 2015	Pls	DIG-IC	TV, Synthesizer Tuning Control, 32 Progr., 400 Ch.		24-DIP				-
CT 2017	Pls	DIG-IC	TV, Synthesizer Tuning Interface						-
CT 2030	Pls	ROM-IC	TV, ROM f. 100Kanäle/Channel(Name & Frequ.) (PAL)		16-DIP				-
CT 2031	Pls	ROM-IC	=CT 2030: f. Frankr./French Standard		16-DIP				-
CT 2032	Pls	ROM-IC	=CT 2030: f. USA		16-DIP				-
CT 2033	Pls	ROM-IC	=CT 2030: f. England/British Isles		16-DIP				-
CT 2200	Pls	NMOS-IC	5-Bit › 13-Segment Decoder, Driver		24-DIP				-
CT 7004		IC	Digital-Uhr/Digital Clock						
CTP 1104	Itt	Ge-P	LF P, 40/40/10V, 3A, 40W		23a	TO-3			AD 149, AL 102, AUY 19...20, 2SB449
CTP 1108	Itt	Ge-P	=2N2061		23a	TO-3			›2N2061
CTP 1109	Itt	Ge-P	=2N2062		23a	TO-3			›2N2062
CTP 1111	Itt	Ge-P	LF P, 80/50/40V, 3A, 45W		23a	TO-3			AL 102, AUY 20, 2N1541...43, 2N1546...48
CTP 1500	Itt	Ge-P	LF,S P, 100/60/80V, 15A, 50W(Tc=45°)		23a	TO-3			AUY 37, 2N1552, 2N1556, 2N1560
CTP 1503	Itt	Ge-P	=CTP 1500: 80/50/60V		23a	TO-3			2N1551...52, 2N1555...56, 2N1559...60
CTP 1504	Itt	Ge-P	=CTP 1500: 60/35/40V		23a	TO-3			2N1550...52, 2N1554...56, 2N1558...60
CTP 1508	Itt	Ge-P	LF,S P, 40/20/20V, 15A, 50W(Tc=45°)		23a	TO-3			2N1549...52, 2N1553...56, 2N1557...60
CTP 1544	Itt	Ge-P	LF,S P, 60/30/30V, 25A, 50W(Tc=45°)		23a	TO-3			2N1651...1653, 2N2285...2287
CTP 1545	Itt	Ge-P	=CTP 1544: 80/40/30V		23a	TO-3			2N1652...1653, 2N2286...2287
CTP 1552	It	Ge-P	LF,S P, 40/20/30V, 25A, 50W(Tc=45°)		23a	TO-3			2N1651...1653, 2N2285...2287
CTP 1553	Itt	Ge-P	=CTP 1552: 100/50/30V		23a	TO-3			2N1652...1653, 2N2286...2287
CU		Si-N	=HC 1F2Q (SMD-Marking)		39	SOT-89			›HC 1...
CV		PIN-Di	=1SV234 (SMD-Marking)		35	SOT-23			›1SV234
CV		PIN-Di	=1SV246 (SMD-Marking)		35(2mm)	SOT-323			›1SV246
CV		Si-P	=XN 4404 (SMD-Marking)		46	SOT-163			›XN 4404
CV 12(B....E)		Thy	100...500V, 2A, Igt/Ih<1,5/<1mA		13e	TO-202	TAG 626-600[4]	17e	BT 100A/300R, BT 100/02
CVPU 2210	Itt	NMOS-IC	CTV, NTSC Kammfilter-/Comb Filter Video-Processor		40-DIP				-
CVPU 2233	Itt	NMOS-IC	CTV, NTSC Kammfilter-/Comb Filter Video-Processor		40-DIP				-
CVPU 2235	Itt	NMOS-IC	CTV, NTSC Kammfilter-/Comb Filter Video-Processor		40-DIP				-
CVPU 2270	Itt	NMOS-IC	CTV, NTSC Kammfilter-/Comp Filter Video-Processor		40-DIP				-
CW		Si-N/P+R	=XN 4381 (SMD-Marking)		46	SOT-163			›XN 4381
CW 01 B	Hit	Thy	100V, 0,2A(Tc=57°), 0,3A=, Igt/Ih=1/5mA		9b	(5x6x3mm)	(BRX 49)[4]	7a	MCR 1906-..., 2N1595...1599, TAG 2-...
CW 01 C		Thy	=CW01B: 200V		9b	(5x6x3mm)	(BRX 49)[4]	7a	MCR 1906-..., 2N1595...1599, TAG 2-...
CW 12 B	Hit	50Hz-Thy	100V, 0,2A(Tc=57°), Igt/Ih=1/5mA		7b	TO-92L	BRX 49	7a	MCR 1906-..., 2N1595...1599, TAG 2-...
CW 12 C		50Hz-Thy	=CW12C: 200V		7b	TO-92L	BRX 49	7a	MCR 1906-..., 2N1595...1599, TAG 2-...
CX....CZ									
CX		MOS-N-FET-d	=3SK227 (SMD-Marking)		44	SOT-143			›2SK227
CX		MOS-N-FET-d	=3SK271 (SMD-Marking)		44(2mm)	SOT-343			›3SK271
CX		Si-N	=HC 1A4A (SMD-Marking)		39	SOT-89			›HC 1...
CX 701	Mic	Si-N	TV-VA, 150/120V, 2/4A, 25W		17j	TO-220	2SD1138	17j	BD 239D, 2SD578, 2SD608(A), 2SD1138
CX 701 A		Si-N	=CX 701: 180/150V		17j	TO-220	2SD1138	17j	BD 239E, 2SD578, 2SD608A, 2SD1138
CX 702	Mic	Si-N	TV-HA, 160/80V, 5/8A, 40W		17j	TO-220	BU 406	17j	BU 104P, BU 406...408, 2SD823
CX 702 A		Si-N	=CX 702: 200/100V		17j	TO-220	BU 406	17j	BU 104P, BU 406...408, 2SD823
CX 703	Mic	Si-N	Vid, 160/160V, 0,1A, 0,625W, >50MHz		7e	TO-92	BF 420 A	7c	BF 422A, BF 420A, BFR 87...89, BFT 57...59
CX 703 A		Si-N	=CX 703: 200/200V		7e	TO-92	BF 420 A	7c	BF 240A, BF 422A, BFR 88...89, BFT 58...59
CX 703 B		Si-N	=CX 703: 250/250V		7e	TO-92	BF 420 A	7c	BF 420A, BF 422A, BFR 88, BFT 58
CX 704(A....C)	Mic	Si-N	LF,S P, 60/50V, 4/7A, 30W, >3MHz	(CX754	17j	TO-220	BD 243 C	17j	BD 243A, BD 535, BD 539A, BD 949
CX 705	Mic	Si-N	LF,S P, 55/45V, 7A, 75W, >0,5MHz		23a	TO-3	BD 245 C	18j	BD 245A, BD 311, BDV 91, 2N5873, ++
CX 705 A		Si-N	=CX 705: 70/60V		23a	TO-3	BD 245 C	18j	BD 245A, BD 313, BDV 93, 2N5874, ++
CX 754(A....C)	Mic	Si-P	LF,S P, 60/50V, 4/7A, 30W, >3MHz	(CX704	17j	TO-220	BD 244 C	17j	BD 244A, BD 536, BD 540A, BD 950
CX 901	Mic	Si-N	LF, Z-Diode (Ube=6,7...7,7V)		7e	TO-92			-
CX 904(B....E)	Mic	Si-N	Uni, In, 45/40V, 0,1A, 0,3W, 200MHz	(CX954	7e	TO-92	BC 550	7a	BC 184, BC 413...414, BC 550, 2SC2675,++
CX 906(A....D)	Mic	Si-N	LF Drv, 45/40V, 0,5A, 0,5W, 200MHz	(CX956	7e	TO-92	BC 337	7a	BC 337, BC 635, BC 637, BC 639, 2SC3377+
CX 908(B....D)	Mic	Si-N	LF Drv, 45/40V, 1A, 0,625W, 150MHz	(CX958	7e	TO-92	BC 337	7a	BC 337, BC 635, BC 635, BC 639, 2SD1225+
CX 917	Mic	Si-N	AM Inp, FM IF, 40V, 50mA, 0,25W, 330MHz		7e	TO-92	BF 255	7d	BF 240...241, BF 254, BF 494, BF 594, ++
CX 918	Mic	Si-N	FM/VHF, TV IF, 30V, 50mA, 620MHz, Gp=28dB(45MHz)		7e	TO-92	BF 198	7d	BF 198, BF 225, BF 310, BF 367, BF 596++
CX 954(B....E)	Mic	Si-P	Uni, In, 45/40V, 0,1A, 0,3W, 200MHz	(CX904	7e	TO-92	BC 560	7a	BC 214, BC 415...416, BC 560, 2SA1137,++
CX 956(A....D)	Mic	Si-P	LF Drv, 45/40V, 0,5A, 0,5W, 200MHz	(CX906	7e	TO-92	BC 327	7a	BC 327, BC 636, BC 638, BC 640, 2SA1515+
CX 958(B....D)	Mic	Si-P	LF Drv, 45/40V, 1A, 0,625W, 150MHz	(CX908	7e	TO-92	BC 327	7a	BC 327, BC 636, BC 638, BC 640, 2SB909++
CX 20026	Son	LIN-IC	TV, Stereo MPX-Decoder f. Japan, Ucc=8,5...9,5V		28-DIP				-
CX 20060	Son	LIN-IC	VC, Video Signal Switch, Ucc=9V		6-DIP				-
CX 20061	Son	LIN-IC	=CX 20060: Fig. ›		8-SIP				-
CX 20095 A	Son	LIN-IC	Video Line Driver/Receiver, Ucc=4,8...5,2V		14-MDIP				-
CX 20100	Son	LIN-IC	CTV, RGB Interface		28-DIP				-
CX 20106 A	Son	LIN-IC	IR-FB, Empfängervorverst./Receiver Preamp., Ucc=5V		8-SIP				KA 2184
CX 20125	Son	LIN-IC	Video, Lumin. Proc., Dynamic Picture, Ucc=12V		8-SIP				-
CX 20126	Son	LIN-IC	TV, Stereo MPX-Decoder f. Japan, Ucc=8,5...9,5V		28-DIP				-
CX 20158	Son	LIN-IC	Video 2-Input Signal Switch, Buffer, Ucc=±5V		14-MDIP				-
CX 20159	Son	LIN-IC	TV, Stromversorgung/Power Supply, Ucc=3,8...10V		16-MDIP				-
CX 20183	Son	LIN-IC	SMD, TV, Video IF, Sound IF, Ucc=3...6V		24-MDIP				-
CX 23038	Son	CMOS-IC	Digital Video, progr. Shift Register, Udd=5V		28-DIP				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
CXA 1011 M		LIN-IC	=CXA 1011P: SMD		16-MDIP			-
CXA 1011 P	Son	LIN-IC	dbx-TV, Noise Reduction Decoder, Ucc=5…15V		16-DIP			KA 2270
CXA 1012 AS	Son	LIN-IC	CTV, Y, Chroma, Sync. Signal Processor(NTSC,Japan)		48-SDIP			-
CXA 1013 AS	Son	LIN-IC	CTV, Y, Chroma, Sync. Signal Processor(NTSC, USA)		48-SDIP			-
CXA 1019		LIN-IC	AM Radio, LF Inp/Out, Ucc=6(2…8,5)V		28-SDIP			KA 22426
CXA 1024 S	Son	LIN-IC	CTV, RGB Interface, Automatic White Balance		48-SDIP			-
CXA 1034 P		LIN-IC	Recoder, 2x LF Amp.					AN 7108, KA 22132
CXA 1044 BP	Son	LIN-IC	hi-res Display(820x700), RGB Predriver, Ucc=12V		18-DIP+g			-
CXA 1081(Q)	Son	LIN-IC	=KA 9201					KA 9201
CXA 1082(Q)	Son	MOS-IC	=KA 8309		48-MP			KA 8309
CXA 1101 P	Son	LIN-IC						KA 2271
CXA 1102	Son	LIN-IC						KA 22712
CXA 1110 BS	Son	LIN-IC	SMD, CTV,VC, Video IF, Sound IF, Ucc=8,5…9,5V		30-SDIP			-
CXA 1113 AS	Son	LIN-IC	TV, Stereo MPX-Decoder, AF Ctrl., f. Japan, Ucc=9V		30-SDIP			-
CXA 1114 M		LIN-IC	=CXA 1114P: SMD		28-MDIP			-
CXA 1114 P	Son	LIN-IC	Audio/Video Switch, 4x In, 3x Out, I²C-Bus, Ucc=9V		28-DIP			-
CXA 1124 BQ	Son	LIN-IC	=CXA 1124BS: Fig. ›		48-MP			-
CXA 1124 BS	Son	LIN-IC	dbx-TV, MTS-Decoder, USA Standard, Ucc=4,7…10V		42-SDIP			-
CXA 1125 P	Son	LIN-IC	TV, CATV Tuner, VHF Os, Mx, TV IF, Ucc=5V		14-DIP			-
CXA 1126 S	Son	LIN-IC	TV, Stereo MPX-Decoder f. Japan, Ucc=8,5…9,5V		28-SDIP			-
CXA 1138 AM	Son	LIN-IC	=CXA 1138AS: SMD		28-MDIP			CXA 1438M
CXA 1138 AS	Son	LIN-IC	TV,VC, Stereo MPX-Decoder f. EIAJ, Ucc=4,5…9,5V		22-SDIP			CXA 1438S
CXA 1145 M	Son	LIN-IC	=CXA 1145P: SMD		24-MDIP			-
CXA 1145 P	Son	LIN-IC	Video, RGB-Encoder (NTSC/PAL), Ucc=5V		24-DIP			-
CXA 1158 P	Son	LIN-IC	Display, Deflection/Synchr. Generator, Ucc=±5V		28-DIP			-
CXA 1163	Son	LIN-IC						KA 22711
CXA 1165 AL	Son	LIN-IC	TV, CATV Tuner, VHF Os, Mx, TV IF, Ucc=7…9,5V		16-SQP			-
CXA 1165 M	Son	LIN-IC	=CXA 1165P: SMD		14-MDIP			-
CXA 1165 P	Son	LIN-IC	TV, CATV Tuner, VHF Os, Mx, TV IF, Ucc=6,5…9,5V		14-DIP			-
CXA 1209 P	Son	LIN-IC	hi-res Display(1024x800), RGB Predriver, Ucc=12V		18-DIP+g			-
CXA 1211 M	Son	LIN-IC	2x Wideband VCA, 0,1…20MHz, Ucc=4,5…5,5V		8-MDIP			-
CXA 1213 AS,BS	Son	LIN-IC	CTV, Y, Chroma, Sync. Signal Processor (PAL/NTSC)		48-SDIP			-
CXA 1214 P	Son	LIN-IC	CTV, SECAM-Decoder		24-DIP			-
CXA 1218 S	Son	LIN-IC	TV++, NTSC/PAL-Decoder, Ucc=5V		28-SDIP			-
CXA 1219 M		LIN-IC	=CXA 1219P: SMD		24-MDIP			-
CXA 1219 P	Son	LIN-IC	NTSC/PAL-Encoder, 75Ω-Drv, Audio Buffer, Ucc=5V		24-DIP			-
CXA 1227 Q	Son	LIN-IC	TV++, SECAM-Decoder, Ucc=5V		32-MP			-
CXA 1228 S	Son	LIN-IC	TV++, NTSC/PAL-Decoder, Ucc=5V		28-SDIP			-
CXA 1229 M		LIN-IC	=CXA 1229P: SMD		24-MDIP			-
CXA 1229 P	Son	LIN-IC	NTSC/PAL-Encoder, 75Ω-Drv, Audio Buffer, Ucc=5V		24-DIP			-
CXA 1261 M	Son	LIN-IC	SMD,IR-FB, Empf.-Vorverst./Receiver Preamp.,Ucc=5V		8-MDIP			-
CXA 1264 AS	Son	LIN-IC	dbx-TV, Zenith Audio-Decoder, US Standard, Ucc=9V		42-SDIP			-
CXA 1268 P	Son	LIN-IC	Display, Deflection/Synchr. Generator, Ucc=±5V		28-DIP			-
CXA 1271	Son	LIN-IC	=KA 9201Q		32-MP			KA 9201Q
CXA 1272	Son	MOS-IC	=KA 9221		48-MP			KA 9221
CXA 1279 AS	Son	LIN-IC	TV, Sound Processor (Volume, Balance, Tone)		22-SDIP			-
CXA 1299 P	Son	LIN-IC	hi-res Display(1280x1024), RGB Predriver, Ucc=12V		18-DIP+g			-
CXA 1314 P	Son	LIN-IC	Audio/Video Switch, 3x In, 2x Out, I²C-Bus, Ucc=9V		16-DIP			-
CXA 1315 M		D/A-IC	=CXA 1315P: SMD		16-MDIP			-
CXA 1315 P	Son	D/A-IC	TV, 8 Bit, 5 Channel, 4 I/O Ports, I²C-Bus		16-DIP			-
CXA 1355 L	Son	LIN-IC	TV, VHF/UHF/CATV Tuner, Ucc=8,1…9,9V		16-SQP			-
CXA 1365 S	Son	LIN-IC	Display, HA/VA Sync. Discrimination, Ucc=8,5…9,5V		28-SDIP			-
CXA 1366 S	Son	LIN-IC	Display, HA/VA Deflection Correction, Ucc=±5V		28-SDIP			-
CXA 1385 Q	Son	LIN-IC	LCD CTV, Y, Chroma, Sync. Signal Processor		32-MP			-
CXA 1387 S	Son	LIN-IC	CTV,Monitor, Aperture Compensation		30-SDIP			-
CXA 1401 M	Son	LIN-IC	SMD, DBS-Tuner, SAT PLL FM-Demodulation, 2. IF		24-MDIP			-
CXA 1403 AM	Son	LIN-IC	SMD, DBS-Tuner, SAT 4-Phase PSK Demodulation		20-MDIP			-
CXA 1409 AQ	Son	LIN-IC	VC++, Video Signal Driver, Buffer, Ucc=5V		32-MP			-
CXA 1410 M	Son	LIN-IC	VC, Video 5-Input Signal Selector, Ucc=5…9V		24-MDIP			-
CXA 1413 L	Son	LIN-IC	TV,VC, Vertical Correlator f. Dynamic Comb Filter		8-SIP			-
CXA 1414 P	Son	LIN-IC	Audio/Video Switch, 3x In, 2x Out, I²C-Bus, Ucc=9V		16-DIP			-
CXA 1420 P	Son	LIN-IC	CTV, Aperture Compensation, Dyn. Picture, I²C-Bus		24-DIP			-
CXA 1434 P	Son	LIN-IC	Audio/Video Switch, 4x In, 3x Out, I²C-Bus, Ucc=9V		28-DIP			-
CXA 1438 M	Son	LIN-IC	=CXA 1438S: SMD		28-MDIP			-
CXA 1438 S	Son	LIN-IC	TV,VC, Stereo MPX-Decoder f. EIAJ, Ucc=8,5…9,5V		22-SDIP			-
CXA 1450 M	Son	LIN-IC	VC, Video Signal Switch, Ucc=4…6V		8-MDIP			-
CXA 1451 M	Son	LIN-IC	VC, Video 2-Input Signal Switch, Driver, Ucc=4…6V		16-MDIP			-
CXA 1464 AS	Son	LIN-IC	CTV, Y, Chroma, Sync. Signal Proc.(Japan Standard)		48-SDIP			-
CXA 1465 AS	Son	LIN-IC	=CXA 1464AS: USA Standard		48-SDIP			-
CXA 1470 AM		LIN-IC	=CXA 1470AS: SMD		28-MDIP			-
CXA 1470 AS	Son	LIN-IC	Display, HA/VA Deflection Compensation, Ucc=±5V		28-SDIP			-
CXA 1477 AS	Son	BiMOS-IC	CTV, Y, Chroma, Sync. Signal Processor, I²C-Bus		48-SDIP			-
CXA 1485 Q	Son	LIN-IC	LCD CTV, RGB Driver f. TFT LCD Display, Ucc=14V		32-MP			-
CXA 1490 M	Son	LIN-IC	=CXA 1490S: SMD		28-MDIP			-
CXA 1490 S	Son	LIN-IC	TV,VC, Stereo MPX-Decoder f. EIAJ, Ucc=8,5…9,5V		22-SDIP			-
CXA 1518 Q		LIN-IC	=CXA 1518S: Fig. ›		32-MP			-
CXA 1518 S	Son	LIN-IC	TV, Stereo MPX-Decoder, EIAJ Standard, Ucc=5V		22-SDIP			-
CXA 1519 M		LIN-IC	=CXA 1519S: SMD		28-MDIP			-
CXA 1519 S	Son	LIN-IC	=CXA 1438S: integr. D-FAX Elimination Filter		22-SDIP			-
CXA 1520 M		LIN-IC	=CXA 1520S: SMD		28-MDIP			-
CXA 1520 S	Son	LIN-IC	=CXA 1490S: integr. D-FAX Elimination Filter		22-SDIP			-
CXA 1521 M	Son	LIN-IC	Wideband(20MHz) Video Gain Control Amp., Ucc=4…6V		8-MDIP			-
CXA 1526 P	Son	LIN-IC	CTV, Dynamic Convergence, I²C-Bus, Ucc=12V		16-DIP			-
CXA 1534 Q	Son	LIN-IC	=CXA 1124BS: Fig. ›		48-MP			-
CXA 1534 S	Son	LIN-IC	dbx-TV, MTS-Decoder, USA Standard, Ucc=4,7…10V		42-SDIP			-
CXA 1545 AS	Son	LIN-IC	Audio/Video Switch, 5x In, 3x Out, I²C-Bus, Ucc=9V		48-SDIP			-
CXA 1558 L	Son	LIN-IC	VC, Video 4-Input Signal Switch, Driver, Ucc=±5V		16-SQP			-
CXA 1585 Q	Son	LIN-IC	TV++, RGB-Decoder (NTSC/PAL), Ucc=5V		32-MP			-
CXA 1587 S	Son	LIN-IC	CTV, Y, Chroma, RGB Signal Processor (PAL/NTSC)		48-SDIP			-
CXA 1686 A	Son	LIN-IC	SMD, Digital TV, Clock Signal Generator, Ucc=5V		30-MDIP			-
CXA 1727 Q	Son	LIN-IC	TV,Camera, Wide TV ID Signal Additional/Detecting		32-MP			-
CXB 1010 G	Son	LIN-IC	Digital Video, 16x16 Bit Multiplier/Accumulator		85-PGA			-
CXD 1050 A	Son	CMOS-IC	CRT, Sreen Display, 128 Characters(12x16Dots)		24-DIP			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
CXD 1161	Son	CMOS-D/A-IC	=KDA 0316		20-DIP			KDA 0316
CXD 1167(Q)	Son	MOS-IC	=KS 9210		80-MP			KS 9210
CXD 1229 Q	Son	CMOS-IC	Digital Video, Sync. Separation, AFC		48-MP			-
CXD 2011 Q	Son	CMOS-IC	Digital TV,VC, Digital Comb Filter (NTSC/PAL)		80-MP			-
CXD 2012 Q	Son	CMOS-IC	DBS-Tuner, Audio PCM Demodulator		80-MP			-
CXD 2018 Q	Son	CMOS-IC	CTV, VA Processor, Multi-Standard, HDTV, I²C-Bus		48-MP			-
CXD 2020 Q	Son	CMOS-IC	Signal Processor f. MUSE-NTSC Converter		100-MP			-
CXD 2021 Q	Son	CMOS-IC	Time Conversion Processor f. MUSE-NTSC Converter		100-MP			-
CXD 2023 Q	Son	CMOS-IC	Digital TV/VC, Digital Comb Filter (NTSC)		80-MP			-
CXD 2024 Q	Son	CMOS-IC	Digital TV/VC, Digital Comb Filter (NTSC/PAL)		80-MP			-
CXD 2105 AQ	Son	CMOS-IC	Digital VC, Digital Comb Filter (NTSC/PAL/SECAM)		80-MP			-
CXD 2122 AQ	Son	CMOS-IC	TV,Camera, Video Aspect Ratio ID Signal De/Encoder		32-MP			-
CXD 2305 Q	Son	CMOS-D/A-IC	hi-res Display, 10 Bit, 50 Msps, RGB 3 Channel		100-MP			-
CXK 1202 Q	Son	CMOS-IC	Digital TV/VC, Digital Delay Line (NTSC/PAL/SECAM)		32-MP			-
CXK 1202 S		CMOS-IC	=CXK 1202Q: Fig. ›		28-SDIP			-
CXK 1203 Q,R	Son	CMOS-IC	Digital TV/VC, Digital Line Memory(NTSC/PAL/SECAM) Q=12x12mm, R=7x7mm		48-MP			-
CXK 1206 AM,ATM	Son	CMOS-VRAM-IC	3-Port Dig. Video Signal Field Memory (NTSC/PAL)			38-SMDIP	(20x14mm)	-
CXD 1206 ATM		CMOS-VRAM-IC	=CXK 1206AM:			44-SSDIP	(18x10mm)	-
CXK 1207 M	Son	CMOS-VRAM-IC	3-Port Dig. Video Signal Field Memory (NTSC/PAL)			38-SMDIP		-
CXK 5864 AP/BP		sRAM-IC	MOS, 8k x 8Bit					-
CXK 48324 Q	Son	CMOS-VRAM-IC	3-Port Dig. Video Signal Field Memory (NTSC/PAL)			64-MP	(20x14mm)	-
CXK 48324 R		CMOS-VRAM-IC	=CXK 48324Q: Fig. ›			80-MP	(12x12mm)	-
CXL 5509 M		CMOS-CCD-IC	=CXL 5509P: SMD		16-MDIP			-
CXL 5509 P	Son	CMOS-CCD-IC	Video, CCD Delay Line (NTSC)		16-DIP			-
CY		Si-N	=2SC2881-Y (SMD-Marking)		39	SOT-89		›2SC2881
CY		Si-N	=2SC3396 (SMD-Marking)		35	SOT-23		›2SC3396
CY		Si-N	=2SC4209-Y (SMD-Marking)		35	SOT-23		›2SC4209
CY		Si-N	=2SC4397 (SMD-Marking)		35(2mm)	SOT-323		›2SC4397
CY		Si-N	=2SC5087-Y (SMD-Marking)		44	SOT-143		›2SC5087
CY		MOS-P-FET-e	=2SJ186 (SMD-Marking)		39	SOT-89		›2SJ186
CY		Si-N	=BFS 18R (SMD-Marking)		35	SOT-23		›BFS 18R
CY		Si-N	=KTC4373-Y (SMD-Marking)		39	SOT-89		›KTC 4373
CYQ		Si-N	=2SC4661-Q (SMD-Marking)		35(2mm)	SOT-323		›2SC4661
CYR		Si-N	=2SC4661-R (SMD-Marking)		35(2mm)	SOT-323		›2SC4661
CYS		Si-N	=2SC4661-S (SMD-Marking)		35(2mm)	SOT-323		›2SC4661
CZ		Si-N	=BFS 19R (SMD-Marking)		35	SOT-23		›BFS 19R
D								
D....	JAP	...-N	›2SD...., z.B./e.g. "D731" = 2SD731 ›		Japantypen			
D....	Sam	...-N	›KSD...., z.B./e.g. "D1616"=KSD1616 ›		Samsung			
D....	Nec	IC	›µPD.... (NEC !)					
D		Si-P	=2SA1687 (SMD-Marking)		35(2mm)	SOT-323		›2SA1687
D 1	Hfo	Se-Di	Blitzschutz/Lightning Protection, Ubr=75V(400mA)		12	(17x20x6)		-
D 01		Si-Di	=SD 914 (SMD-Marking)		35	SOT-23		›SD 914
D 1		Si-Di	=BAW 63 (SMD-Marking)		35(2mm)	SOT-323		›BAW 63
D 1(p)		Si-N	=BCW 31 (SMD-Marking)		35	SOT-23		›BCW 31
D 1 G		Si-P	=KSA 812-G (SMD-Marking)		35	SOT-23		›KSA 812
D 1 G		Si-P	=HN 1A01F-GR (SMD-Marking)		46	SOT-163		›HN 1A01F
D 1 G		Si-P	=HN 1A01FU-GR (SMD-Marking)		46(2mm)	SOT-363		›HN 1A01FU
D 1 L		Si-P	=KSA 812-L (SMD-Marking)		35	SOT-23		›KSA 812
D 1O		Si-P	=KSA 812-O (SMD-Marking)		35	SOT-23		›KSA 812
D 1 Y		Si-P	=KSA 812-Y (SMD-Marking)		35	SOT-23		›KSA 812
D 1 Y		Si-P	=HN 1A01F-Y (SMD-Marking)		46	SOT-163		›HN 1A01F
D 1 Y		Si-P	=HN 1A01FU-Y (SMD-Marking)		46(2mm)	SOT-363		›HN 1A01FU
D 2		Si-Di	=BAW 63A (SMD-Marking)		35(2mm)	SOT-323		›BAW 63A
D 2(p)		Si-N	=BCW 32 (SMD-Marking)		35	SOT-23		›BCW 32
D2T 918	Tix	Si-N	Dual, 30/15V, 0,05A, >600MHz, (=2x2N918)		TO-77	(CBE-EBC-)		2N3423...3424
D2T 2218	Tix	Si-N	Dual, 60/30V, 0,8A, >250MHz, hFE>40, (2x2N2218)		TO-77	(CBE-EBC-)		2N3409...3411
D2T 2218A		Si-N	=D2T 2218: 75/40V, >300MHz, (=2x2N2218A)		TO-77	(CBE-EBC-)		(2N3409...3411)[7]
D2T 2219	Tix	Si-N	=D2T 2218: hFE>100, (=2X2N2219)		TO-77	(CBE-EBC-)		2N3409...3411
D2T 2219A		Si-N	=D2T 2218A: hFE>100, (=2x2N2219A)		TO-77	(CBE-EBC-)		(2N3409...3411)[7]
D2T 2904(A)	Tix	Si-P	Dual, 60/40V, 0,6A, >200MHz, hFE>40, (=2x2N2904...)		TO-77	(CBE-EBC-)		2N4015...4016
D2T 2905(A)	Tix	Si-P	=D2T2904: hFE>100, (=2x2N2905...)		TO-77	(CBE-EBC-)		2N4015...4016
D 3		Si-Di	=1SS 187 (SMD-Marking)		35	SOT-23		›2SS 187
D 3		Si-Di	=BAW 63B (SMD-Marking)		35(2mm)	SOT-323		›BAW 63B
D 3(p)		Si-N	=BCW 33 (SMD-Marking)		35	SOT-23		›BCW 33
D 4		Si-P	=2SA1252-4 (SMD-Marking)		35	SOT-23		›2SA1252
D 4		Si-Di	=BAW 63B (SMD-Marking)		35(2mm)	SOT-323		›BAW 64
D 4		Si-N	=BCW 31R (SMD-Marking)		35	SOT-23		›BCW 31R
D 5		Si-P	=2SA1252-5 (SMD-Marking)		35	SOT-23		›2SA1252
D 5		Si-N	=2SC1622-D5 (SMD-Marking)		35	SOT-23		›2SC1622
D 5		Si-Di	=BAW 65 (SMD-Marking)		35(2mm)	SOT-323		›BAW 65
D 5		Si-N	=BCW 32R (SMD-Marking)		35	SOT-23		›BCW 32R
D 5 E29	Gen	UJT-P	Iv>25mA, Ip<25µA, η<0,82, Rbb<9,1kΩ		5a	TO-72		-
D 5 E35	Gen	UJT-P	Iv>10mA, η<0,82, Rbb<9,1kΩ		5a	TO-72		-
D 5 E36	Gen	UJT-P	Iv>10mA, η<0,82, Rbb<9,1kΩ		5a	TO-72		-
D 5 E37	Gen	UJT-P	35V, 50mA, Iv>4mA, Ip<25µA, η=0,47...0,85, Rbb<12kΩ		5a	TO-72		-
D 5 E43	Gen	UJT-P	35V, 50mA, Iv>6mA, Ip<2µA, η=0,68...0,82, Rbb<9,1kΩ		5a	TO-72		-
D 5 E44	Gen	UJT-P	35V, 50mA, Iv>4mA, Ip<5µA, η=0,68...0,82, Rbb<9,1kΩ		5a	TO-72		-
D 5 E45	Gen	UJT-P	35V, 50mA, Iv>8mA, Ip<2µA, η=0,68...0,82, Rbb<9,1kΩ		5a	TO-72		2N2647
D 5 K1	Gen	UJT-N	30V, 150mA, Iv>1mA, Ip<5µA, η=0,58...0,6, Rbb<8,2kΩ		5a	TO-72		2N6114
D 5 K2	Gen	UJT-N	20V, 150mA, Iv>1mA, Ip<15µA, η=0,58...0,6, Rbb<15kΩ		5a	TO-72		2N6115
D 6		Si-P	=2SA1252-6 (SMD-Marking)		35	SOT-23		›2SA1252
D 6		Si-N	=2SC1622-D6 (SMD-Marking)		35	SOT-23		›2SC1622
D 6		Si-Di	=BAW 66 (SMD-Marking)		35(2mm)	SOT-323		›BAW 66
D 6		Si-N	=BCW 33R (SMD-Marking)		35	SOT-23		›BCW 33R
D 7		Si-P	=2SA1252-7 (SMD-Marking)		35	SOT-23		›2SA1252
D 7		Si-N	=2SC1662-D7 (SMD-Marking)		35	SOT-23		›2SC1662
D 7		Si-Di	=BAW 67 (SMD-Marking)		35(2mm)	SOT-323		›BAW 67
D 7(p)		Si-N	=BCF 32 (SMD-Marking)		35	SOT-23		›BCF 32
D 8		Si-N	=2SC1662-D8 (SMD-Marking)		35	SOT-23		›2SC1662
D 8		Si-Di	=BAW 68 (SMD-Marking)		35(2mm)	SOT-323		›BAW 68

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
D 8		Si-N	=BCF 33 (SMD-Marking)		35	SOT-23		›BCF 33
D 12 E026	Gen	Si-N	Dual, 45/30V, 0,03A, >30MHz		TO-77	(CBE-EBC-)		BFW 39…40, 2N2913…2918
D 12 E109	Gen	Si-N	Dual, 60V, 0,05A		TO-71	(CBE-EBC-)		(2N2919…2920)[6]
D 12 E126	Gen	Si-N	=D12E026:		TO-71	(CBE-EBC-)		(BFW 39…40, 2N2913…2918)[6]
D 13 H1	Gen	SAS	Ub=+7…+9/-14…-18V, Itsm=+1A/-0,5A, Is<80µA Igt/Ih<0,07/<0,25mA		7n	TO-92		-
D 13 H2		SAS	=D 13 H1: Is<100µA		7n	TO-92		-
D 13 K1	Gen	PUT	=2N6116		2a	TO-18		›2N6116
D 13 K2	Gen	PUT	=2N6117		2a	TO-18		›2N6117
D 13 K3	Gen	PUT	=2N6118		2a	TO-18		›2N6118
D 13 T1	Gen	PUT	=2N6027:		7a	TO-92		›2N6027
D 13 T2	Gen	PUT	=2N6028:		7a	TO-92		›2N6028
D 13 V	Gen	Z-IC	+10…40V, 40mA		2	TO-5		-
D 15		Si-N	=2SC1622A-D15 (SMD-Marking)		35	SOT-23		›2SC1622A
D 15		Si-N	=2SC4180-D15 (SMD-Marking)		35(2mm)	SOT-323		›2SC4180
D 16		Si-N	=2SC1662A-D16 (SMD-Marking)		35	SOT-23		›2SC1662A
D 16		Si-N	=2SC4180-D16 (SMD-Marking)		35(2mm)	SOT-323		›2SC4180
D 16 E7	Gen	Si-N	25V, 0,2W, 135MHz		7	TO-98		-
D 16 E9	Gen	Si-N	30V, 0,2W, 135MHz		7	TO-98		-
D 16 G6	Gen	Si-N	UHF Os, 30V, 25mA, 0,2W, >500MHz		7c	TO-98		BF 377…78, BF 763, 2N2857, 2SC3776…77+
D 16 K1….K4	Gen	Si-N	VHF, 30V, 25mA, 0,2W, 580…650MHz		7c	TO-98		BF 225, BF 314, BF 496, BF 502…503, ++
D 16 P1….P4	Gen	Si-N-Darl	LF, 18…20V, 0,2/0,5A, 0,32W, >60MHz, hFE>2000		7c	TO-98		BC 517, BC 875, MPS-A25, 2SC4017,++
D 17		Si-N	=2SC1662A-D17 (SMD-Marking)		35	SOT-23		›2SC1662A
D 17		Si-N	=2SC4180-D17 (SMD-Marking)		35(2mm)	SOT-323		›2SC4180
D 18		Si-N	=2SC1662A-D18 (SMD-Marking)		35	SOT-23		›2SC1662A
D 18		Si-N	=2SC4180-D18 (SMD-Marking)		35(2mm)	SOT-323		›2SC4180
D 21		N-FET	=2SK931-21 (SMD-Marking)		35	SOT-23		›2SK931
D 22		N-FET	=2SK931-22 (SMD-Marking)		35	SOT-23		›2SK931
D 23		N-FET	=2SK931-23 (SMD-Marking)		35	SOT-23		›2SK931
D 24		N-FET	=2SK931-24 (SMD-Marking)		35	SOT-23		›2SK931
D 24 A3391(A)	Gen	Si-N	Min, 25/25V, 0,1A, 120MHz		=24c			BC 122…123
D 24 A3392	Gen	Si-N	Min, 25/25V, 0,1A, 140MHz		=24c			BC 122…123
D 24 A3393	Gen	Si-N	Min, 25/25V, 0,1A, 140MHz		=24c			BC 122…123
D 24 A3394	Gen	Si-N	Min, 25/25V, 0,1A, 140MHz		=24c			BC 122…123
D 24 A3900(A)	Gen	Si-N	Min, 18/18V, 0,1A, 160MHz		=24c			BC 122…123
D 25		Si-N	=2SC3115-D25 (SMD-Marking)		35	SOT-23		›2SC3115
D 25		N-FET	=2SK931-25 (SMD-Marking)		35	SOT-23		›2SK931
D 26		Si-N	=2SC3115-D26 (SMD-Marking)		35	SOT-23		›2SC3115
D 26 B1….B2	Gen	Si-N	Min, S, 40V, <12/18ns		36b	(2mmØ)		-
D 26 C1….C5	Gen	Si-N	Min, Uni, 25V, 0,09W		36b	(2mmØ)		BC 122…123
D 26 E1….E7	Gen	Si-N	Min, LF, 18…45V, 0,09W		36b	(2mmØ)		BC 123
D 26 G1	Gen	Si-N	Min, VHF/UHF, 30/15V, >600MHz, Gp>15dB(200MHz)		36b	(2mmØ)		-
D 26 P1….P3	Gen	Si-N-Darl	Min, 18…25V, 0,09W, hFE>6000		36b	(2mmØ)		-
D 27		Si-N	=2SC3115-D27(SMD-Marking)		35	SOT-23		›2SC3115
D 27 C1	Gen	Si-N	›D42C5					
D 27 C2	Gen	Si-N	›D42C4					
D 27 C3	Gen	Si-N	›D42C2					
D 27 C4	Gen	Si-N	›D42C1					
D 27 D1	Gen	Si-P	›D43C5					
D 27 D2	Gen	Si-P	›D43C4					
D 27 D3	Gen	Si-P	›D43C2					
D 27 D4	Gen	Si-P	›D43C1					
D 28		Si-N	=2SC3115-D28 (SMD-Marking)		35	SOT-23		›2SC3115
D 28 A5….A13	Gen	Si-N	LF Drv,Out, 35…50V, 0,5A		13	TO-202		BD 385, BD 415, BD 827, BD 841
D 28 B	Gen	Si-N	S,Vid, 150V, 0,1A		13	TO-202		BF 615, BF 617, BF 857…859
D 28 C1….C8	Gen	Si-N	›D40C1….C8					
D 28 D1….D10	Gen	Si-N	›D40D1….D10					
D 28 E	Gen	Si-N	›D40N3					
D 29 A4….A12	Gen	Si-P	Uni, 35…60V, 0,5A, 0,33W		7c	TO-98		BC 327, BC 638, BC 640
D 29 E1….E10(J1)	Gen	Si-P	LF Drv 35…70V, 0,75A, 0,5W		7c	TO-98		BC 327, BC 638, BC 640
D 29 F1….F7	Gen	Si-P	Uni, 40…60V, 0,1A, 0,36W, >90MHz		7c	TO-18		BC 212, BC 257, BC 307, BC 556, ++
D 30 A1….A5	Gen	Si-P	Min, Uni, 25V, 0,09W		36b	(2mmØ)		BC 202…203
D 31 B	Gen	Si-P	›D40D					
D 32	Tag	Diac	Ub=28…36V, Ib<0,3mA, Itsm=1A		31l	DO-7		A 9903
D 32 H1….H9	Gen	Si-N	Uni, 60…100V, 0,5A, 0,5W		7a	SOT-30		BC 639, 2N3700…3701, 2SD667
D 32 K1….K2	Gen	Si-N	LF,S Drv, 30…50V, 0,75A, 0,5W		7a	SOT-30		BC 337, BC 637, BC 639, 2N3700…3701, ++
D 32 L1….L6	Gen	Si-N-Darl	25…40V, 0,5A, >80MHz, hFE>2000		7a	SOT-30		BC 517, BC 875, BC 877, BC 879, MPS-A25
D 32 P1….P4	Gen	Si-N	AM/FM IF, 40V, 50mA, >120…>490MHz		7a	SOT-30		BF 240…241, BF 254, BF 494, BF 594, ++
D 32 S1….S10	Gen	Si-N	LF, 30…60V, 0,1A, 0,4W		7a	SOT-30		BC 174, BC 182, BC 190, BC 546, ++
D 32 W7….W14	Gen	Si-N	Uni, 100…120V, 0,1A, 0,4W, >75MHz		7a	SOT-30		2SC2240, 2SC2459, 2SC3245
D 33 D1….D6	Gen	Si-N	Uni, 40…50V, 0,5A, 0,4W		7c	TO-98		BC 337, BC 637, BC 639, 2N3700…01, ++
D 33 D21….D30(J1)	Gen	Si-N	LF Drv, 35…70V, 0,75A, 0,5W		7c	TO-98		BC 337, BC 637, BC 639, 2N3700…01, ++
D 33 K1….K3	Gen	Si-N	Uni, 50…80V, 1A, 0,33W		7c	TO-98		BC 637, BC 639, 2N3700…01, 2SD667, ++
D 34 C1….C6	Gen	Si-P-Darl	25…40V, 0,5A, >80MHz, hFE>2000		7a	SOT-30		BC 516, BC 876, BC 878, BC 880, MPS-A75
D 34 J1….J9	Gen	Si-P	Uni, 60…100V, 0,5A, 0,5W, >60MHz		7a	SOT-30		BC 640, 2SA965, 2SB647
D 38 H1….H9	Gen	Si-N	LF Drv, 60…100V, 0,5A, 0,5A, >80MHz		7e	TO-92		BC 637, BC 639, 2N3700…01, 2SD667, ++
D 38 L1….L6	Gen	Si-N-Darl	25…40V, 0,5A, >80MHz		7e	TO-92		BC 517, BC 875, BC 877, BC 879, MPS-A25
D 38 S1….S10	Gen	Si-N	Uni, 30…60V, 0,1A, 0,4W, 100MHz		7e	TO-92		BC 174, BC 182, BC 190, BC 546, ++
D 38 V1….V3	Gen	Si-N	S, Vid, 200…300V, 0,1A, 0,5W, >50MHz		7e	TO-92		BF 298…299, BFR 88…89, BFT 58…59, ++
D 38 W7….W14	Gen	Si-N	LF,S, 100…120V, 0,1A, 0,4W, >75MHz		7e	TO-92		2SC2240, 2SC2459, 2SC3245
D 39 C1….C6	Gen	Si-P-Darl	25…40V, 0,5A, >80MHz, hFE>2000		7e	TO-92		BC 516, BC 876, BC 878, BC 880, MPS-A75
D 39 J1….J9	Gen	Si-P	LF Drv, 60…100V, 0,5A, 0,5W, >60MHz		7e	TO-92		BC 638, BC 640, 2SA965, 2SB647
D 40 C1….C8(U)	Gen	Si-N-Darl	LF,S P, 30…50V, 0,5A, 6,25W, 75MHz		13m	TO-202		MPS-U45
D 40 D1….D14(U)	Gen	Si-N	LF,S P, 45…90V, 1A, 6,25W, 200MHz		13m	TO-202	(2SC4135)[4]	30j BD 419, BD 519, BD 529
D 40 E1….E7	Gen	Si-N	LF,S P, 45…90V, 2A, 8W, 230MHz		13m	TO-202	(2SC4135)[4]	30j BD 525, BD 527, BD 529
D 40 K1….K4	Gen	Si-N-Darl	LF,S P, 30…50V, 2A, 10W, 75MHz, hFE>10k		13m	TO-202	(BD 679)[4]	14h MPS-U45
D 40 N1….N5(U)	Gen	Si-N	S/Vid, 250…300V, 0,1A, 6,25W, 80MHz		13m	TO-202	MPS-U10	13m BF 382, BF 461…462, MPS-U10, 2SC1758,++
D 40 P1….P5(U)	Gen	Si-N	Vid, 200…300V, 0,5A, 6,25W, >50MHz		13m	TO-202	MPS-U10	13m BF 382, BF 461…462, MPS-U10
D 40 V1….V6	Gen	Si-N	S/Vid, 300…400V, 0,1A, >50MHz		13m	TO-202	(MPS-U10)	13m BF 462, (BF 881)[5]
D 41 D1….D14(U)	Gen	Si-P	LF,S P, 45…90V, 1A, 6,25W, 150MHz		13m	TO-202	(2SA1593)[4]	30j BD 420, BD 520, BD 530
D 41 E1….E7	Gen	Si-P	LF,S P, 40…90V, 2A, 8W, 175MHz		13m	TO-202	(2SA1593)[4]	30j BD 526, BD 528, BD 530
D 41 K1….K4	Gen	Si-P-Darl	LF,S P, 30…50V, 2A, 10W, 100MHz, hFE>10k		13m	TO-202	(BD 680)[4]	14h MPS-U95
D 42 C1….C12(J,U)	Gen	Si-N	LF,S P, 40…90V, 3A, 12,5W, 50MHz		13j	TO-202	(BD 243 C)[4]	17j (BDV 10…12)[6]

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
D 42 D1....D6	Gen	Si-N-Darl	LF,S P, 50...90V, 4A, 12W, 50MHz		13m	TO-202	(BD 679)[5]	14h	(BD 679, BD 681, BD 779, 2N6039)[5]
D 42 R1....R2	Gen	Si-N	Vid P, 250...300V, 1A, 55MHz		13j	TO-202	(MJE 340)[5]	14h	(BF 468, BF 668)[5]
D 42 T1....T8	Gen	Si-N	S/Vid P, 300...400V, 2A, 15W, 45MHz		13m, 13j	TO-202	(MJE 340)[5]	14h	(BUV 93...95)[5]
D 43 C1....C12(J,U)	Gen	Si-P	LF,S P, 40...90V, 3A, 12,5W, 40MHz		13j	TO-202	(BD 244 C)[4]	17j	(BD 242(A...F), 2SA1293)[4]
D 43 D1....D6	Gen	Si-P-Darl	LF,S P, 50...90V, 4A, 12W, 50MHz, hFE=10k		13m	TO-202	(BD 680)[5]	14h	(BD 680, BD 682, BD 780, 2N6036)[5]
D 44 C1....C12	Gen	Si-N	LF,S P, 40...90V, 4A, 30W, 50MHz		17j	TO-220	BD 243 C	17j	BD 243(A...C), BD 539(A...C), BD 953, ++
D 44 D1....D6	Gen	Si-N-Darl+Di	LF,S P, 50...90V, 6A, 30W, 50MHz, hFE>2k		17j	TO-220	BD 901[8]	17j	BDT 63(A...C), BDX 33(A...D)
D 44 E1....E3	Gen	Si-N-Darl	LF,S P, 40...80V, 10A, 50W, hFE>1000		17j	TO-220	BDW 93 C	17j	BDT 65(A...C), BDW 93(A...C)
D 44 H1....H11	Gen	Si-N	LF,S P, 30...80V, 10A, 50W, 50MHz		17j	TO-220	BD 809	17j	BD 711, BD 809, 2SC2527
D 44 Q1....Q5	Gen	Si-N	S P, 200...300V, 4A, 31W, 50MHz		17j	TO-220	BU 406	17j	BU 406...409, MJE 51T...53T, TIP 75, ++
D 44 R1....R8	Gen	Si-N	LF,S P, 400...500V, 1A, 31W, 40MHz		17j	TO-220	BUX 85	17j	BUW 40A...B, BUX 84...85, TIP 50
D 44 T1....T8	Gen	Si-N	S P, 300...400V, 2A, 45MHz		17j	TO-220	BUX 85	17j	BUW 40(A...B), BUX 84...85, TIP 49...59, ++
D 44 TD3...TD5	Gen	Si-N	S P, lo-sat, 400...600V, 2A, 50W		17j	TO-220			2SC3148
D 44 TE3....TE5	Gen	Si-N	LF,S P, lo-sat, 400...600V, 4A, 75W		17j	TO-220			2SC3148
D 44 TQ1...TQ2	Gen	Si-N	S P, SMPS, 650...750V, 12A, 100W		17j	TO-220			BUV 66(A)
D 44 VH1....VH10	Gen	Si-N	S P, lo-sat, 50...100V, 15A, 83W, 50MHz		17j	TO-220			-
D 44 VM1...VM10	Gen	Si-N	S P, lo-sat, 50...100V, 8A, 50W, 50MHz		17j	TO-220			-
D 45		Si-Di	=BA 170		31a		1N4148	31a	›BA 170
D 45 C1....C12	Gen	Si-P	LF,S P, 40...90V, 4A, 30W, 40MHz		17j	TO-220	BD 244 C	17j	BD 244(A...C), BD 540(A...C), BD 954, ++
D 45 D1....D6	Gen	Si-P-Darl+Di	LF,S P, 50...90V, 6A, 30W, 50MHz, hFE>2k		17j	TO-220	BD 902[8]	17j	BDT 62(A...C), BDX 34(A...D)
D 45 E1....E3	Gen	Si-P-Darl	LF,S P, 40...80V, 10A, 50W, hFE>1000		17j	TO-220	BDW 94 C	17j	BDT 64(A...C), BDW 94(A...C)
D 45 H1....H12	Gen	Si-P	LF,S P, 30...80V, 10A, 50W, 40MHz		17j	TO-220	BD 810	17j	BD 712, BD 810, 2SA1077,++
D 45 VH1....VH10	Gen	Si-P	S P, lo-sat, 40...100V, 15A, 83W, 50MHz		17j	TO-220			-
D 45 VM1...VM10	Gen	Si-P	S P, lo-sat, 50...100V, 8A, 50W, 50MHz		17j	TO-220			-
D 46 TQ1...TQ2	Gen	Si-N	S P, 650...750V, 12A, 110W		18j	TO-3P	BUW 13 A	18j	BUV 48(A...C), BUW 13(A), BUW 133(A), ++
D 47		Z-Di	=BZX 84/C3V9 (SMD-Marking)		35	SOT-23			›BZX 84
D 48		Z-Di	=BZX 84/C4V3 (SMD-Marking)		35	SOT-23			›BZX 84
D 49		Si-Di	=BAY 84 (SMD-Marking)		35	SOT-23			›BAY 84
D 51		Si-N	=2SD780A-D51 (SMD-Marking)		35	SOT-23			›2SD780A
D 52		Si-Di	=BY 133		31a		1N4007	31a	›BY 133
D 52		Si-N	=2SD780A-D52(SMD-Marking)		35	SOT-23			›2SD780A
D 52		Thy	=SoBRY55/30 (SMD-Marking)		35	SOT-23			›SoBRY55/30
D 53		Si-N	=2SD780A-D53 (SMD-Marking)		35	SOT-23			›2SD780A
D 53		Si-Di	=BAY 85 (SMD-Marking)		35	SOT-23			›BAY 85
D 54		Z-Di	=BZX 84/C3V3 (SMD-Marking)		35	SOT-23			›BZX 84
D 54		Si-N	=2SD780A-D54 (SMD-Marking)		35	SOT-23			›2SD780A
D 54 A7D	Gen	Si-N-Darl+Di	Hammer Drv, 100/100V, 7A, 30W, hFE=2....15k		17c	SOT-186			BD 647F, 2SD1415, 2SD1791, 2SD1830, ++
D 54 D6D	Gen	Si-N-Darl+Di	S P, 600/400V, 6A, 25W, hFE>600		17c	SOT-186			2SD1409
D 54 FY7D	Gen	Si-N-Darl+Di	Hammer Drv, 80/80V, 7A, 30W, hFE>2k...15k		17c	SOT-186			BD 645F, 2SD1415, 2SD1791, 2SD1830, ++
D 54 H6D	Gen	Si-N-Darl	S P, 300/250V, 6A, 25W, hFE>2000		17c	SOT-186			2SD1410, 2SD2017
D 55		Si-N	=2SD780A-D55 (SMD-Marking)		35	SOT-23			›2SD780A
D 55 A7D	Gen	Si-N-Darl+Di	Hammer Drv, 100/100V, 7A, 30W, hFE>2k...15k		17c	SOT-186			BD 647F, 2SD1415, 2SD1791, 2SD1830, ++
D 55 FY7D	Gen	Si-N-Darl+Di	Hammer Drv, 80/80V, 7A, 30W, hFE>2k...15k		17c	SOT-186			BD 645F, 2SD1415, 2SD1791, 2SD1830, ++
D 56 W1....W2	Gen	Si-N	S P, 1400V, 5A, 78W		23a	TO-3	BU 208 A	23a	BU 208(A), BU 508(A), 2SC2928, 2SD820,++
D 62		Si-Di	=BAT 53 (SMD-Marking)		35	SOT-23			›BAT 53
D 64		Z-Di	=BZX 84/C3V6 (SMD-Marking)		35	SOT-23			›BZX 84
D 64 DS5...DS7	Gen	Si-N-Darl+Di	S P, 500...700V, 20A, 125W, hFE>100		23a	TO-3			BUT 15, MJ 10009, MJ 10024...25
D 64 DV5...DV7	Gen	Si-N-Darl+Di	S P, 500...700V, 50A, 185W, hFE>100		23a	TO-3			BUT 34, MJ 10016
D 64 ES5...ES7	Gen	Si-N-Darl+Di	=D64DS: integr. Speedup Diode		23a	TO-3			-
D 64 EV5...EV7	Gen	Si-N-Darl+Di	=D64DV: integr. Speedup Diode		23a	TO-3			-
D 64 TS3...TS5	Gen	Si-N	S P, 195W		23a	TO-3			-
D 64 VS3...VS5	Gen	Si-N	S P, 450...550V, 15A, 195W		23a	TO-3			BUS 13(A), BUS 23(A...B), BUW 45...46
D 65		Thy	=SoBRY55/30R (SMD-Marking)		35	SOT-23			›SoBRY55/30R
D 66 DS5...DS7	Gen	Si-N-Darl+Di	=D64DS5...7: Iso, 62,5W		66b	TO-238			-
D 66 DV5...DV7	Gen	Si-N-Darl+Di	=D64DV5...7: Iso, 125W		66b	TO-238			-
D 66 DW1...DW3	Gen	Si-N-Darl+Di	S P, 800...900V, 50A, 167W		66b	TO-238			-
D 66 ES5...ES7	Gen	Si-N-Darl+Di	=D64ES5...7: Iso, 62,5W		66b	TO-238			-
D 66 EV5...EV7	Gen	Si-N-Darl+Di	=D64EV5...7: Iso, 125W		66b	TO-238			-
D 66 EW1...EW3	Gen	Si-N-Darl+Di	=D66DW1...3: integr. Speedup Diode		66b	TO-238			-
D 66 GV5...GV7	Gen	Si-N-Darl+Di	S P, 600...700V, 50A, 125W, Speedup Diode		66b	TO-238			-
D 66		Thy	=SoBRY55/60 (SMD-Marking)		35	SOT-23			›SoBRY55/60
D 67		Thy	=SoBRY55/60R (SMD-Marking)		35	SOT-23			›SoBRY55/60R
D 67 DE5...DE7	Gen	Si-N-Darl+Di	S P, 500...700V, 100A, 312W						-
D 67 FP5...FP7	Gen	Si-N-Darl+Di	S P, 500...700V, 100A, 312W						-
D 70 F2T1	Gen	Si-N	SMD, 50/50V, 2A, 100/1100ns, sat<0,5A(1A)	{D71F2T1	39b	SOT-89			2SD1623...24, 2SC4409, 2SC4541
D 70 G.05T1	Gen	Si-N	SMD, S, 200/150V, 0,05A	{D71G.05T1	39b	SOT-89			BF 622, 2SC2880, 2SC4372, 2SC4080
D 70 Y.8T1	Gen	Si-N	SMD, LF, 35/30V, 0,8A	{D71Y.8T1	39b	SOT-89			BCX 54...56, 2SC3444, 2SC4539, 2SD1623,++
D 70 Y1.5T1	Gen	Si-N	SMD, LF, 30/30V, 1,5A	{D71Y1.5T1	39b	SOT-89			2SC3439, 2SC4377, 2SD1621, 2SD1766,++
D 71		Si-N	=BCW 60A (SMD-Marking)		35	SOT-23			›BCW 60A
D 71 F2T1	Gen	Si-P	SMD, 50/50V, 2A, 100/1100ns, sat<0,5V(1A)	{D70F2T1	39b	SOT-89			2SA1681, 2SA1736, 2SB1123...24, 2SB1520
D 71 G.05T1	Gen	Si-P	SMD, S, 150/150V, 0,05A	{D70G.05T1	39b	SOT-89			BF 623, 2SA1200, 2SA1660, 2SB1046...47
D 71 Y.8T1	Gen	Si-P	SMD, LF, 35/30V, 0,8A	{D70Y.8T1	39b	SOT-89			BCX 51...53, 2SA1364, 2SB1122, 2SB1260,++
D 71 Y1.5T1	Gen	Si-P	SMD, LF, 30/30V, 1,5A	{D70Y1.5T1	39b	SOT-89			2SA1213, 2SA1681, 2SB1313, 2SB1123,++
D 72		Si-N	=BCW 60B (SMD-Marking)		35	SOT-23			›BCW 60B
D 72 F5T1...2	Gen	Si-N	60/50V, 5A, 20W, sat<0,4V(3A), 100/1100ns	{D73F5T...	30j	TO-251/252			2SC3074, 2SD1803, 2SD1805
D 72 FY4D1...2	Gen	Si-N-Darl+Di	100/80V, 4A, 15W, hFE>2000, 200/2100ns	{D73FY4D...	30j	TO-251/252			2SC4345, 2SD1223, 2SD1520
D 72 K3D1...2	Gen	Si-N-Darl+Di	60/40V, 3A, 15W, hFE>2000, 100/1200ns	{D73K3D...	30j	TO-251/252			2SD1222...23, 2SD1520, 2SD1817
D 72 Y1.5D1...2	Gen	Si-N-Darl	Uni, 30V, 1,5A, 10W, hFE>4000, 180/900ns		30j	TO-251/252			2SD1759, 2SD1800, 2SD1980, 2SD2410
D 73		PIN-Di	=BA 579A (SMD-Marking)		35	SOT-23			›BA 579A
D 73		Si-N	=BCW 60C (SMD-Marking)		35	SOT-23			›BCW 60C
D 73 F5T1...2	Gen	Si-P	60/50V, 5A, 20W, 100/1100ns, sat<0,4V(3A)	{D72F5T...	30j	TO-251/252			2SA1244, 2SA1795, 2SB1203...04
D 73 FY4D1...2	Gen	Si-P-Darl+Di	100/80V, 4A, 15W, 150/1200ns, hFE>2000	{D72FY4D...	30j	TO-251/252			2SB908, 2SB1072
D 73 K3D1...2	Gen	Si-P-Darl+Di	60/40V, 3A, 15W, hFE>2000, 300/850ns	{D72K3D...	30j	TO-251/252			2SB907, 2SB1214, 2SB1303
D 74		PIN-Di	=BA 579C (SMD-Marking)		35	SOT-23			›BA 579C
D 74		Si-N	=BCW 60D (SMD-Marking)		35	SOT-23			›BCW 60D
D 74... ....D 78...	Gen	Si-N/P	General Electric: Transistor-Arrays						-
D 75		PIN-Di	=BA 579S (SMD-Marking)		35	SOT-23			›BA 579S
D 76		Si-Di	=BAR 18 (SMD-Marking)		35	SOT-23			›BAR 18
D 77		Si-N	=BCF 32R (SMD-Marking)		35	SOT-23			›BCF 32R
D 78		Si-Di	=1N4148		31a		1N4148	31a	›1N4148
D 81		Si-Di	=BAR 43A (SMD-Marking)		35	SOT-23			›BAR 43A
D 81		Si-N	=BCF 33R (SMD-Marking)		35	SOT-23			›BCF 33R
D 82		Si-Di	=BAR 43C (SMD-Marking)		35	SOT-23			›BAR 43C

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
D 83		Si-Di	=BB 503DK (SMD-Marking)		35	SOT-23			›BB 503DK
D 84		Si-Di	=BAT 18DK (SMD-Marking)		35	SOT-23			›BAT 18DK
D 85		Si-Di	=BAT 17DS (SMD-Marking)		35	SOT-23			›BAT 17DS
D 91		Si-N	=BCV 61 (SMD-Marking)		44	SOT-143			›BCV 61
D 92		Si-N	=BCV 61A (SMD-Marking)		44	SOT-143			›BCV 61
D 93		Si-N	=BCV 61B (SMD-Marking)		44	SOT-143			›BCV 61
D 94		Si-Di	=BAR 42 (SMD-Marking)		35	SOT-23			›BAR 42
D 94		Si-N	=BCV 61C (SMD-Marking)		44	SOT-143			›BCV 61
D 95		Si-Di	=BAR 43 (SMD-Marking)		35	SOT-23			›BAR 43
D 95		Si-N	=BCV 63 (SMD-Marking)		44	SOT-143			›BCV 63
D 96		Si-N	=BCV 63B (SMD-Marking)		44	SOT-143			›BCV 63
D 96		Si-Di	=BAS 70-04 (SMD-Marking)		35	SOT-23			›BAS 70-04
D 97		Si-Di	=BAS 70-05 (SMD-Marking)		35	SOT-23			›BAS 70-05
D 98		Si-Di	=BAS 70-06 (SMD-Marking)		35	SOT-23			›BAS 70-06
D 100 C,D	Hfo	TTL-Logic	=... 7400 (TTL)		14-DIC,DIP				... 7400... (TTL)
D 103 C,D	Hfo	TTL-Logic	=... 7403 (TTL)		14-DIC,DIP				... 7403... (TTL)
D 104 C,D	Hfo	TTL-Logic	=... 7404 (TTL)		14-DIC,DIP				... 7404... (TTL)
D 108 C,D	Hfo	TTL-Logic	=... 7408 (TTL)		14-DIC,DIP				... 7408... (TTL)
D 110 C,D	Hfo	TTL-Logic	=... 7410 (TTL)		14-DIC,DIP				... 7410... (TTL)
D 118		Si-Di	≈1N4148		31a		1N4148	31a	›1N4148
D 120 C,D	Hfo	TTL-Logic	=... 7420 (TTL)		14-DIC,DIP				... 7420... (TTL)
D 121 C,D	Hfo	TTL-Logic	=... 74121 (TTL)		14-DIC,DIP				... 74121... (TTL)
D 122 D	Hfo	LIN-IC	2-Kanal Leseverstärker/2-Channel Read Amp.		16-DIP				SN 7522N
D 123 D	Hfo	LIN-IC	2-Kanal Leseverstärker/2-Channel Read Amp.		16-DIP				SN 7523N
D 126 C,D	Hfo	TTL-Logic	=... 7426 (TTL)		14-DIC,DIP				... 7426... (TTL)
D 129		Si-Di	≈BA 127		31a		1N4148	31a	›BA 127
D 130 C,D	Hfo	TTL-Logic	=... 7430 (TTL)		14-DIC,DIP				... 7430... (TTL)
D 140 C,D	Hfo	TTL-Logic	=... 7440 (TTL)		14-DIC,DIP				... 7440... (TTL)
D 146 C,D	Hfo	TTL-Logic	=... 7446 (TTL)		16-DIC,DIP				... 7446... (TTL)
D 147		C-Di	≈BA 136		31a				›BA 136
D 147 C,D	Hfo	TTL-Logic	=... 7447 (TTL)		16-DIC,DIP				... 7447... (TTL)
D 150 C,D	Hfo	TTL-Logic	=... 7450 (TTL)		14-DIC,DIP				... 7450... (TTL)
D 151 C,D	Hfo	TTL-Logic	=... 7451 (TTL)		14-DIC,DIP				... 7451... (TTL)
D 153 C,D	Hfo	TTL-Logic	=... 7453 (TTL)		14-DIC,DIP				... 7453... (TTL)
D 154 C,D	Hfo	TTL-Logic	=... 7454 (TTL)		14-DIC,DIP				... 7454... (TTL)
D 160 C,D	Hfo	TTL-Logic	=... 7460 (TTL)		14-DIC,DIP				... 7460... (TTL)
D 172 C,D	Hfo	TTL-Logic	=... 7472 (TTL)		14-DIC,DIP				... 7472... (TTL)
D 174 C,D	Hfo	TTL-Logic	=... 7474 (TTL)		14-DIC,DIP				... 7474... (TTL)
D 175 C,D	Hfo	TTL-Logic	=... 7475 (TTL)		16-DIC,DIP				... 7475... (TTL)
D 181 C,D	Hfo	TTL-Logic	=... 7481 (TTL)		14-DIC,DIP				... 7481... (TTL)
D 191 C,D	Hfo	TTL-Logic	=... 7491 (TTL)		14-DIC,DIP				... 7491... (TTL)
D 192 C,D	Hfo	TTL-Logic	=... 74192 (TTL)		16-DIC,DIP				... 74192... (TTL)
D 193 C,D	Hfo	TTL-Logic	=... 74193 (TTL)		16-DIC,DIP				... 74193... (TTL)
D 195 C,D	Hfo	TTL-Logic	=... 7495 (TTL)		14-DIC,DIP				... 7495... (TTL)
D 200 C,D	Hfo	TTL-Logic	=... 74H00 (TTL)		14-DIC,DIP				... 74H00... (TTL)
D 201 C,D	Hfo	TTL-Logic	=... 74H01 (TTL)		14-DIC,DIP				... 74H01... (TTL)
D 204 C,D	Hfo	TTL-Logic	=... 74H04 (TTL)		14-DIC,DIP				... 74H04... (TTL)
D 210 C,D	Hfo	TTL-Logic	=... 74H10 (TTL)		14-DIC,DIP				... 74H10... (TTL)
D 220 C,D	Hfo	TTL-Logic	=... 74H20 (TTL)		14-DIC,DIP				... 74H20... (TTL)
D 228		Si-Di	≈BA 159		31a		BA 159	31a	›BA 159
D 230 C,D	Hfo	TTL-Logic	=... 74H30 (TTL)		14-DIC,DIP				... 74H30... (TTL)
D 232		Si-Di	≈BA 159		31a		BA 159	31a	›BA 159
D 240 C,D	Hfo	TTL-Logic	=... 74H40 (TTL)		14-DIC,DIP				... 74H40... (TTL)
D 251 C,D	Hfo	TTL-Logic	=... 74H51 (TTL)		14-DIC,DIP				... 74H51... (TTL)
D 254 C,D	Hfo	TTL-Logic	=... 74H54 (TTL)		14-DIC,DIP				... 74H54... (TTL)
D 274 C,D	Hfo	TTL-Logic	=... 74H74 (TTL)		14-DIC,DIP				... 74H74... (TTL)
D 335		Ge-Di	≈AA 119		31a		AA 119	31a	›AA 119
D 336		Si-Di	≈1N4148		31a		1N4148	31a	›1N4148
D 345 D	Hfo	TTL-Logic	BCD ›7-Segment Decoder, 0...+70°		16-DIP				-
D 346 D	Hfo	TTL-Logic	BCD ›7-Segment Decoder, 0...+70°		16-DIP				-
D 347 D	Hfo	TTL-Logic	BCD ›7-Segment Decoder, 0...+70°		16-DIP				74LS247 (TTL)
D 348 D	Hfo	TTL-Logic	BCD ›7-Segment Decoder, 0...+70°		16-DIP				74LS247 (TTL)
D 351 D	Hfo	TTL-Logic	Teiler/Divider, 0...+75°		14-DIP				-
D 352		Si-Di	≈BA 282		31a				›BA 282
D 355 D	Hfo	TTL-Logic	Timer, I²L		18-DIP				-
D 356 D	Hfo	TTL-Logic	Timer, I²L		18-DIP				-
D 377		Si-Di	≈FDH 600		31a		1N4148	31a	›FDH 600
D 380		Se-Di	Dual-Rr				(2x AA 133)	31a	M40C4
D 394 D	Hfo	LIN-IC	Schrittmotorsteuerung/Stepper Motor Control		18-DIP				-
D 395 D	Hfo	TTL-Logic	Schrittmotorsteuerung/Stepper Motor Control		18-DIP				-
D 410 D	Hfo	TTL-Logic	3x Treiber/Driver (AND-Gates)		16-DIP				SAA 1029
D 461 D	Hfo	TTL-Logic	Dual-Treiber/Driver f. MOS-Memory		14-DIP				SN 75361
D 473		Si-Di	≈BA 127		31a		1N4148	31a	›BA 127
D 474		Si-Di	≈1N4148		31a		1N4148	31a	›1N4148
D 475		Si-Di	≈1N4148		31a		1N4148	31a	›1N4148
D 491 D	Hfo	TTL-Logic	4-Segment-Treiber/Driver		14-DIP				-
D 492 D	Hfo	TTL-Logic	6x Digit-Treiber/Driver		14-DIP				SN 75492
D 716 X	Hfo	LIN-IC	Thermo Printer Control						-
D 718 D	Hfo	LIN-IC	16-Bit Ser./Par. Converter						(UAA 2022)
D 764 A		Si-Di	≈BAV 45		31a		(1N4148)	31a	›BAV 45
D 797		Si-Di	≈1N4148		31a		1N4148	31a	›1N4148
D 837(A)		Si-Di	≈1N4148		31a		1N4148	31a	›1N4148
D 838		Si-Di	≈BA 159		31a		BA 159	31a	›BA 159
D 1201 A	Rca	Si-Di	≈1N4002		31a	DO-15	1N4007	31a	›1N4002
D 1201 B	Rca	Si-Di	≈1N4003		31a	DO-15	1N4007	31a	›1N4003
D 1201 D	Rca	Si-Di	≈1N4004		31a	DO-15	1N4007	31a	›1N4004
D 1201 F	Rca	Si-Di	≈1N4001		31a	DO-15	1N4007	31a	›1N4001
D 1201 M	Rca	Si-Di	≈1N4005		31a	DO-15	1N4007	31a	›1N4005
D 1201 N	Rca	Si-Di	≈1N4006		31a	DO-15	1N4007	31a	›1N4006
D 1201 P	Rca	Si-Di	≈1N4007		31a	DO-15	1N4007	31a	›1N4007
D 1300 A....D	Rca	Si-Di	Uni, 150...525V, 0,25A, Uf<1(0,25A), 30µs A=100/150V, B=200/300V, D=400/525V		2c	TO-1	BA 159	31a	BA 157...159, BA 199/..., BY 204/..., ++
D 2101(S)	Rca	Si-Di	TV Clamp Diode, 600V, 1A≈, Uf<1,5V(4A), <700ns		34b	DO-1	BYD 33 M	31a	BYX 55/600, MR 816...818, RGP 10J...M, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
D 2103 S,SF	Rca	Si-Di	TV Damper Diode, 750V, 3A≈, Uf<1,4V(4A), <500ns S: Rücklauf/Retrace, SF: Hinlauf/Trace	34b	DO-1	BYW 96 E BY 329/1200[4]	31a 17k	BY 399, RGP 30K...M, (BY 229/800...1000)[5]
D 2201 A....N	Rca	Si-Di	FRr, 50...800V, 1A, Uf<1,9V(4A), <500ns A=100, B=200, D=400, F=50, M=600, N=800V	31a	DO-15	BYD 33 M	31a	BY 218/..., BY 258/..., RGP 15A...M, ++
D-2240 A		Hybrid-IC	LF Out, ±25V, >20W(±22V/8Ω)					-
D 2406 A....M	Rca	Si-Di	P FRr, 100...600V, 6A(Tc=100°), Uf<1,4V(6A), <350ns A=100, B=200, C=300, D=400, F=50, M=600	32a	DO-4			BYX 50/...
D 2406 A-R....M-R		Si-Di	=D 2406A...M:	32b	DO-4			BYX 50/...R
D 2412 A....M	Rca	Si-Di	P FRr, 100...600V, 12ATc=100°), Uf<1,4(12A), <350ns	32a	DO-4			BYT 61/..., BYX 62/..., BYV 24/..., ++
D 2412 A-R...M-R		Si-Di	=D 2412A...M:	32b	DO-4			BYT 61/...R, BYX 62/...R, BYV 24/...R, ++
D 2520 A....M	Rca	Si-Di	P FRr,100...600V, 20A(Tc=100°), Uf<1,4V(20A),<350ns	32a	DO-5			BYT 65/..., BYX 63/..., BYX 64/..., ++
D 2520 A-R....M-R		Si-Di	=D 2520A...M:	32b	DO-5			BYT 65/...R, BYX 63/...R, BYX 64/...R, ++
D 2540 A....M	Rca	Si-Di	P FRr,100...600, 40A(Tc=100°), Uf<1,8V(100A),<350ns	32a	DO-5			BYW 25/..., MR 861...866, MR 871...876
D 2540 A-R....M-R		Si-Di	=D 2540A...M:	32b	DO-5			BYW 25/...R, MR 861R...866R, MR 871R...876R
D 2600 EF,M	Rca	Si-Di	TV Clamp Di, 550...600V, 0,5A, Uf<2V(4A), <700ns EF=550V, M=600V	31a		BYD 33 M	31a	BY 407, BY 208/600, BY 201/6, RGP 10J,++
D 2601 A....N	Rca	Si-Di	TV Damper Di, 100...800V, 1/6A, Uf<1,9V(4A), <500ns A=100, B=200, D=400, DF=450, E=500, EF=550V, M=600, N=800V	31a	DO-26	BYD 33 M	31a	BY 258/..., BYV 12...16, RGP 15B...M, ++
D-2950 A		Hybrid-IC	LF Out, 50V, >20W(44V/8Ω)					-
D 3202 U	Rca	Diac	Ub=25...40V, 0,19A, Itsm=2A, Ib<25µA	31I	DO-15			1N5760, N 413L
D 3202 Y		Diac	=D 3202 U: Ub=29...35V	31I				1N5761, N 413M, BR 100, DO 201YR
D 3702	Pls	LIN-IC	Telecom, 5x Relay Driver, 65V Output, Ucc=5V, 50mA	-DIC				-
D 4042	Pls	NMOS-IC	Telecom, Dual 1008-Bit Shift Register, 5V, 28mA	14-DIC				-
D 4803 DC	Hfo	LIN-IC	8-Bit Treiber/Driver	16-DIP				-
D-4902		Hybrid-Z-IC	Z-IC, +5V, 1,5A					-
D-4903		Hybrid-Z-IC	Z-IC, +12V, 1,8A					-
D-4904		Hybrid-Z-IC	Z-IC, +24V, 1,5A					-
D 6221 VC	Hfo	LIN-IC	4x Darl.-Schalter/Switch, 50V, 1,8A	15-SQL				L 6221N
DA....DM								
DA		Si-N	=2SD1418-DA (SMD-Marking)	39	SOT-89			›2SD1418
DA		Si-N	=2SD1618 (SMD-Marking)	39	SOT-89			›2SD1618
DA		Si-N	=2SD1664 (SMD-Marking)	39	SOT-89			›2SD1664
DA(s)		Si-P	=BCW 67A (SMD-Marking)	35	SOT-23			›BCW 67A
DA		Si-N	=BF 622 (SMD-Marking)	39	SOT-89			›BF 622
DA		Si-N	=BF 722 (SMD-Marking)	≈39°	SOT-223			›BF 722
DA		MOS-N-FET-e	=µPA502T (SMD-Marking)	45	SOT-153			›µPA502T
DA 2		Si-Di	=SD BAX 12 (SMD-Marking)	35	SOT-23			›SD BAX 12
DA 3	Tho	Diac	Ub=28...36V, Ib<0,3mA, Itsm=1A	31I	DO-7			A 9903, D 32
DA 4	Tho	Diac	Ub=35...45V, Ib<0,15mA, Itsm=2A	31I	DO-7			1N5762, N 413N, D 3202U
DA 5		Si-Di	=BAR 43S (SMD-Marking)	35	SOT-23			›BAR 43S
DA 6		Z-Di	=BZV 53A (SMD-Marking)	35	SOT-23			›BZV 53A
DA 7		Z-Di	=BZV 53B (SMD-Marking)	35	SOT-23			›BZV 53B
DA 8		Z-Di	=BZV 54A (SMD-Marking)	35	SOT-23			›BZV 54A
DA 9		Z-Di	=BZV 54B (SMD-Marking)	35	SOT-23			›BZV 54B
DA 0601	Hit	LIN-IC	6x Si-Dioden Array, gemeinsame/common Cathode	7-SIP				-
DA 0602	Hit	LIN-IC	6x Si-Dioden Array, gemeinsame/common Anode	7-SIP				-
DAC-08....F,N,DC,PC	Fch,Mot,Phi	D/A-IC	8 Bit, multiplying, hi-speed	16-DIC,DIP				NE 5007...5008, SE 5008, DAC 0800...0802
DAC 0800 ...	Nsc	CMOS-A/D-IC	8 Bit, Settling 100ns, ±18V	16-DIC,DIP				-
DAC 0801 ...	Nsc	CMOS-A/D-IC	8 Bit, Settling 100ns, ±18V	16-DIC,DIP				-
DAC 0802 ...	Nsc	CMOS-A/D-IC	8 Bit, Settling 100ns, ±18V	16-DIC,DIP				-
DAC 0806 D	Tho	D/A-IC	=DAC 0806LCN: SMD	16-MDIP				-
DAC 0806 LCJ	Nsc,Tho	D/A-IC	=DAC 0806LCN: Fig. ›	16-DIC				MC 1408L6
DAC 0806 LCN	Nsc,Tho	D/A-IC	8 Bit, multiplying, hi-speed(150ns Settl.),0...+75°	16-DIP				MC 1408P6
DAC 0807 D	Tho	D/A-IC	=DAC 0807LCN: SMD	16-MDIP				-
DAC 0807 LCJ	Nsc,Tho	D/A-IC	=DAC 0807LCN: Fig. ›	16-DIC				MC 1408L7
DAC 0807 LCN	Nsc,Tho	D/A-IC	8 Bit, multiplying, hi-speed(150ns Settl.),0...+75°	16-DIP				MC 1408P7
DAC 0808 D	Tho	D/A-IC	=DAC 0808LCN: SMD	16-MDIP				-
DAC 0808 LCJ	Nsc,Tho	D/A-IC	=DAC 0808LCN: Fig. ›	16-DIC				MC 1408L8
DAC 0808 LCN	Nsc,Tho	D/A-IC	8 Bit, multiplying, hi-speed(150ns Settl.),0...+75°	16-DIP				MC 1408P8
DAC 0808 LJ,LD	Nsc,Tho	D/A-IC	=DAC 0808LCN: -55...+125°	16-DIC				MC 1508L8
DAC 0830 LCD	Nsc	CMOS-D/A-IC	8 Bit, 0,05% Linearity, 1µs Settling, -40...+85°	20-DIC				-
DAC 0831 LCD	Nsc	CMOS-D/A-IC	8 Bit, 0,1% Linearity, 1µs Settling, -40...+85°	20-DIC				-
DAC 0832 LCD	Nsc	CMOS-D/A-IC	8 Bit, 0,2% Linearity, 1µs Settling, -40...+85°	20-DIC				-
DAC 0830...832 LCN	Nsc	CMOS-D/A-IC	=DAC 0830LCD...0832LCD: 0...+70°	20-DIP				-
DAC 0830...832 LD	Nsc	CMOS-D/A-IC	=DAC 0830LCD...0832LCD: -55...+125°	20-DIC				-
DAC 1000 LCD	Nsc	CMOS-D/A-IC	10 Bit, 0,05% Linearity, 500ns Settling, -40...+85°	24-DIC				-
DAC 1001 LCD	Nsc	CMOS-D/A-IC	10 Bit, 0,1% Linearity, 500ns Settling, -40...+85°	24-DIC				-
DAC 1002 LCD	Nsc	CMOS-D/A-IC	10 Bit, 0,2% Linearity, 500ns Settling, -40...+85°	24-DIC				-
DAC 1000...1002 LCN	Nsc	CMOS-D/A-IC	=DAC 1000LCD...1002LCD: 0...+70°	24-DIP				-
DAC 1000...1002 LD	Nsc	CMOS-D/A-IC	=DAC 1000LCD...1002LCD: -55...+125°	24-DIC				-
DAC 1006 LCD	Nsc	CMOS-D/A-IC	10 Bit, 0,05% Linearity, 500ns Settling, -40...+85°	20-DIC				-
DAC 1007 LCD	Nsc	CMOS-D/A-IC	10 Bit, 0,1% Linearity, 500ns Settling, -40...+85°	20-DIC				-
DAC 1008 LCD	Nsc	CMOS-D/A-IC	10 Bit, 0,2% Linearity, 500ns Settling, -40...+85°	20-DIC				-
DAC 1006...1008 LCN	Nsc	CMOS-D/A-IC	=DAC 1006LCD...1008LCD: 0...+70°	20-DIP				-
DAC 1006...1008 LD	Nsc	CMOS-D/A-IC	=DAC 1006LCD...1008LCD: -55...+125°	20-DIC				-
DAC 1020 LCD	Nsc	D/A-IC	10 Bit, 0,05% Linearity, 500ns Settling, -40...+85°	16-DIC				-
DAC 1021 LCD	Nsc	D/A-IC	10 Bit, 0,1% Linearity, 500ns Settling, -40...+85°	16-DIC				-
DAC 1022 LCD	Nsc	D/A-IC	10 Bit, 0,2% Linearity, 500ns Settling, -40...+85°	16-DIC				-
DAC 1020...1022 LCN	Nsc	D/A-IC	=DAC 1020LCD...1022LCD: 0...+70°	16-DIP				-
DAC 1020...1022 LD	Nsc	D/A-IC	=DAC 1020LCD...1022LCD: -55...+125°	16-DIC				-
DAC 1200 HCD	Nsc	D/A-IC	12 Bit, 0,012% Linearity, 15V/µs, -40...+85	24-DIC				-
DAC 1201 HCD	Nsc	D/A-IC	12 Bit, 0,049% Linearity, 15V/µs, -40...+85	24-DIC				-
DAC 1200...1201 HD	Nsc	D/A-IC	=DAC 1200HCD...1201HCD: -55...+125°	24-DIC				-
DAC 1208 LCD	Nsc	D/A-IC	12 Bit, 0,012% Linearity, 1µs Settling, -40...+85°	24-DIC				-
DAC 1209 LCD	Nsc	D/A-IC	12 Bit, 0,024% Linearity, 1µs Settling, -40...+85°	24-DIC				-
DAC 1210 LCD	Nsc	D/A-IC	12 Bit, 0,05% Linearity, 1µs Settling, -40...+85°	24-DIC				-
DAC 1218 LCD	Nsc	D/A-IC	12 Bit, 0,012% Linearity, 1µs Settling, -40...+85°	18-DIC				-
DAC 1219 LCD	Nsc	D/A-IC	12 Bit, 0,024% Linearity, 1µs Settling, -40...+85°	18-DIC				-
DAC 1218...1219 LD	Nsc	D/A-IC	=DAC 1218LCD...1219LCD: -55...+125°	18-DIC				-
DAC 1220 LCD	Nsc	D/A-IC	12 Bit, 0,05% Linearity, 500ns Settling, -40...+85°	18-DIC				-
DAC 1221 LCD	Nsc	D/A-IC	12 Bit, 0,1% Linearity, 500ns Settling, -40...+85°	18-DIC				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DAC 1222 LCD	Nsc	D/A-IC	12 Bit, 0,2% Linearity, 500ns Settling, -40…+85°		18-DIC				-
DAC 1220…1222 LCN	Nsc	D/A-IC	=DAC 1220LCD…1222LCD: 0…+70°		18-DIP				-
DAC 1220…1222 LD	Nsc	D/A-IC	=DAC 1220LCD…1222LCD: -55…+125°		18-DIC				-
DAC 1230 LCD	Nsc	D/A-IC	12 Bit, 0,012% Linearity, 1µs Settling, -40…+85°		20-DIC				-
DAC 1231 LCD	Nsc	D/A-IC	12 Bit, 0,024% Linearity, 1µs Settling, -40…+85°		20-DIC				-
DAC 1232 LCD	Nsc	D/A-IC	12 Bit, 0,05% Linearity, 1µs Settling, -40…+85°		20-DIC				-
DAC 1280 ACD	Nsc	D/A-IC	12 Bit, 0,012% Linearity, 0…+70°		24-DIC				-
DAC 1280 CD	Nsc	D/A-IC	12 Bit, 0,024% Linearity, 0…+70°		24-DIC				-
DAC 1280….I	Nsc	D/A-IC	=DAC 1280(A): -25…+85°		24-DIC				-
DAC 1285 ACD,HCD	Nsc	D/A-IC	12 Bit, 0,012% Linearity, -25…+85°		24-DIC				-
DAC 1285 AD	Nsc	D/A-IC	=DAC 1285ADC,HDC: -55…+125°		24-DIC				-
DAC1408(A…C)DC,PC	Fch	D/A-IC	8 Bit, multiplying, hi-speed(85ns Settl.), 0…+70° A<±0,19%, B<±0,39%, C<±0,78% Accuracy		16-DIC,DIP				AM 1408…, MC 1408…
DAC 1508 DM	Fch	D/A-IC	=DAC 1408…: <±0,19% Accuracy, -55…+125°		16-DIC				AM 1508…, MC 1508…
DAN 801	Rhm	Si-Di	=DAN 401: 8 Di, Common Cathode		9-SIP				-
DAN 803	Rhm	Si-Di	=DAN 401: 8 Di, Common Cathode		9-SIP				-
DAP 801	Rhm	Si-Di	=DAN 401: 8 Di, Common Anode		9-SIP				-
DAP 803	Rhm	Si-Di	=DAN 401: 8 Di, Common Anode		9-SIP				-
DB		Si-N	=2SD1418-DB (SMD-Marking)		39	SOT-89			›2SD1418
DB		Si-N	=2SD1619 (SMD-Marking)		39	SOT-89			›2SD1619
DB		Si-N	=2SD1766 (SMD-Marking)		39	SOT-89			›2SD1766
DB(s)		Si-P	=BCW 67B (SMD-Marking)		35	SOT-23			›BCW 67B
DB		Si-P	=BF 623 (SMD-Marking)		39	SOT-89			›BF 623
DB		Si-P	=BF 723 (SMD-Marking)		≈39°	SOT-223			›BF 723
DB		MOS-N-FET-e	=µPA572T (SMD-Marking)		45(2mm)	SOT-353			›µPA572T
DB 1		Si-Di	=BAR 43A (SMD-Marking)		35	SOT-23			›BAR 43A
DB 1 A…P	Gen,Rca	Si-Br	Br Rr, 50…1000V, 1A, Uf<1,1V(1A) A=50, B=200, D=400, F=50, M=600, N=800, P=1000V		4-DIP	(+-≂)			A 0503…0580, DF 01…10
DB 2		Si-Di	=BAR 43B (SMD-Marking)		35	SOT-23			›BAR 43B
DB 3	Tho	Diac	Ub=28…36V, Ib<0,3mA		31I	DO-7,DO-41			-
DB 3-I-35		Diac	Ub=28…36V, Ib<0,05mA		31I	DO-7			-
DB 4	Tho	Diac	=DB 3: Ub=35…45V		31I	DO-7			-
DB 6	Tho	Diac	=DB 3: Ub=56…70V		31I	DO-7			-
DB 6		Si-Di	=BAY 85S (SMD-Marking)		35	SOT-23			›BAY 85S
DBC 146-4(A….C)		Si-N	=BC 146:		36b				›BC 146
DBC 201		Si-P	=BC 201:		36b				›BC 201
DBC 202		Si-P	=BC 202:		36b				›BC 202
DBC 203		Si-P	=BC 203:		36b				›BC 203
DBP		Si-N	=2SD1766-P (SMD-Marking)		39	SOT-89			›2SD1766
DBQ		Si-N	=2SD1766-Q (SMD-Marking)		39	SOT-89			›2SD1766
DBR		Si-N	=2SD1766-R (SMD-Marking)		39	SOT-89			›2SD1766
DC		Ge-P	≈AF 137				AF 239 S	5g	›AF 137
DC		Si-N	=2SC3444-C (SMD-Marking)		39	SOT-89			›2SC3444
DC		Si-N	=2SD1418-DC (SMD-Marking)		39	SOT-89			›2SD1418
DC		Si-N	=2SD1620 (SMD-Marking)		39	SOT-89			›2SD1620
DC		Si-N	=2SD1767 (SMD-Marking)		39	SOT-89			›2SD1767
DC(s)		Si-P	=BCW 67C (SMD-Marking)		35	SOT-23			›BCW 67C
DC		Si-N	=BF 620 (SMD-Marking)		39	SOT-89			›BF 620
DC		Si-N	=BF 720 (SMD-Marking)		≈39°	SOT-223			›BF 720
DC		Si-N	=BFN 20 (SMD-Marking)		39	SOT-89			›BFN 20
DC 018	Digital E.	I/O-IC	Ser.-Par./Par.-Ser. Converter		40-DIP				DS 8609DC
DC 021	Digital E.	DIG-IC	8-Bit Bustreiber/Bus Driver, bidirectional		20-DIP				DS 8638DC
DC 34	Tho	Diac	Ub=30…38V, Ib<50µA		31I	DO-35			-
DC 38	Tho	Diac	Ub=34…42V, Ib<50µA		31I	DO-35			-
DC 42	Tho	Diac	Ub=39…45V, Ib<50µA		31I	DO-35			-
DCP		Si-N	=2SD1767-P (SMD-Marking)		39	SOT-89			›2SD1767
DCQ		Si-N	=2SD1767-Q (SMD-Marking)		39	SOT-89			›2SD1767
DCR		Si-N	=2SD1767-R (SMD-Marking)		39	SOT-89			›2SD1767
DD		Si-N	=2SC2463-D (SMD-Marking)		35	SOT-23			›2SC2463
DD		Si-N	=2SC3441-D (SMD-Marking)		35	SOT-23			›2SC3441
DD		Si-N	=2SC3444-D (SMD-Marking)		39	SOT-89			›2SC3444
DD		Si-N	=2SD1419-DD (SMD-Marking)		39	SOT-89			›2SD1419
DD		Si-N	=2SD1621 (SMD-Marking)		39	SOT-89			›2SD1621
DD		Si-N	=BFN 16 (SMD-Marking)		39	SOT-89			›BFN 16
DD		Z-Di	=SM 6T 6V8 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T….
DD 7661		LIN-IC	TV Tuning Processor		40-DIP				-
DD 7662		LIN-IC	TV-Tuning Processor		16-DIP				-
DE		Si-P	=2SA1037KLN-E (Typ-Code/Stempel/mark.)		35	SOT-23			›2SA1037KLN
DE		Si-N	=2SC2463-E (SMD-Marking)		35	SOT-23			›2SC2463
DE		Si-N	=2SC3441-E (SMD-Marking)		35	SOT-23			›2SC3441
DE		Si-N	=2SC3444-E (SMD-Marking)		39	SOT-89			›2SC3444
DE		Si-N	=2SD1419-DE (SMD-Marking)		39	SOT-89			›2SD1419
DE		Si-N	=2SD1622 (SMD-Marking)		39	SOT-89			›2SD1622
DE		Si-N-Darl	=2SD1834 (SMD-Marking)		39	SOT-89			›2SD1834
DE		Si-N	=BFN 18 (SMD-Marking)		39	SOT-89			›BFN 18
DE		Z-Di	=SM 6T 6V8A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T….
DF		Si-N	=2SC2463-F (SMD-Marking)		35	SOT-23			›2SC2463
DF		Si-N	=2SC3441-F (SMD-Marking)		35	SOT-23			›2SC3441
DF		Si-N	=2SD1623 (SMD-Marking)		39	SOT-89			›2SD1623
DF(s)		Si-P	=BCW 68F (SMD-Marking)		35	SOT-23			›BCW 68F
DF		Si-P	=BF 621 (SMD-Marking)		39	SOT-89			›BF 621
DF		Si-P	=BF 721 (SMD-Marking)		≈39°	SOT-223			›BF 721
DF		Si-P	=BFN 21 (SMD-Marking)		39	SOT-89			›BFN 21
DF		Z-Di	=SM 6T 7V5 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T….
DF 01		C-Di	AFC		31a				
DF 01(M,S)	Gie	Si-Br	Br Rr, 100V, 1A, Uf<1,1V(1A)		4-DIP				A 0526, DB 1B
DF 02(M,S)	Gie	Si-Br	=DF 01(M), 200V		4-DIP				A 0553, DB 1B
DF 04(M,S)	Gie	Si-Br	=DF 01(M): 400V		4-DIP				A 0580, DB 1D
DF 005(M,S)	Gie	Si-Br	=DF 01(M): 50V		4-DIP				A 0506, DB 1A
DF 06(M,S)	Gie	Si-Br	=DF 01(M): 600V		4-DIP				DB 1M
DF 08(M,S)	Gie	Si-Br	=DF 01(M): 800V		4-DIP				DB 1N
DF 10(M,S)	Gie	Si-Br	=DF 01(M): 1000V		4-DIP				DB 1P

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DF 320(DJ,DP)	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		18-DIC/DIP				MV 4320
DF 321	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		28-DIC				-
DF 322(DJ,DP)	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		18-DIC/DIP				-
DF 323(DJ,DP)	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		18-DIC/DIP				-
DF 820(DJ,DK)	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		18-DIP/DIC				-
DF 821(DJ,DK)	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		18-DIP/DIC				-
DF 822(DJ,DK)	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		18-DIP/DIC				-
DF 823(DJ,DK)	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		18-DIP/DIC				-
DF 824(DJ,DK)	Itt	CMOS-IC	Telecom, Tastwahl/Digital Dialing		18-DIP/DIC				-
DFA 007		Ge-Di	=AA 143		31a		AA 138	31a	›AA 143
DG		Si-N	=2SC2713-GR (SMD-Marking)		35	SOT-23			›2SC2713
DG		Si-N	=2SC4117-GR (SMD-Marking)		35(2mm)	SOT-323			›2SC4117
DG		Si-N	=2SD1624 (SMD-Marking)		39	SOT-89			›2SD1624
DG(s)		Si-P	=BCW 68G (SMD-Marking)		35	SOT-23			›BCW 68G
DG		Si-P	=BFN 17 (SMD-Marking)		39	SOT-89			›BFN 17
DG		Z-Di	=SM 6T 7V5A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
DG 1	Gie	Si-Di	=CG 1		31a	SOD-57	BY 228	31a	›CG 1
DG 2	Gie	Si-Di	=CG 2		31a	SOD-57	BY 228	31a	›CG 2
DG 3	Gie	Si-Di	=CG 3		31a	SOD-57	BY 228	31a	›CG 3
DG 13	Say	Ge-Di	TV Damper-Di, 120V, 3/10A, Uf<1V(10A)		23p	TO-3			AY 102, AY 106
DG 14	Say	Ge-Di	=DG 13: 250V		23p	TO-3			AY 102
DG 130	Say	Ge-Di	TV Damper-Di, 120V, 3/10A, Uf<1V(10A)		23(AAK)	TO-3			AY 102, AY 106
DG 140	Say	Ge-Di	=DG 130: 250V		23(AAK)	TO-3			AY 102
DG 182...	Six	Bi-MOS-IC	=TL 182...		14-DIC,DIP				›TL 182...
DG 185...	Six	Bi-MOS-IC	=TL 185...		16-DIC,DIP				›TL 185...
DG 188...	Six	Bi-MOS-IC	=TL 188...		14-DIC,DIP				›TL 188...
DG 191...	Six	Bi-MOS-IC	=TL 191...		16-DIC,DIP				›TL 191...
DGQ		Si-N	=2SD1963-Q (SMD-Marking)		39	SOT-89			›2SD1963
DGR		Si-N	=2SD1963-R (SMD-Marking)		39	SOT-89			›2SD1963
DGS		Si-N	=2SD1963-S (SMD-Marking)		39	SOT-89			›2SD1963
DH		Si-P	=2SB1025-DH (SMD-Marking)		39	SOT-89			›2SB1025
DH		Si-N	=2SD1625 (SMD-Marking)		39	SOT-89			›2SD1625
DH(s)		Si-P	=BCW 68H (SMD-Marking)		35	SOT-23			›BCW 68H
DH		Si-P	=BFN 19 (SMD-Marking)		39	SOT-89			›BFN 19
DI		Si-N	=2SC3867 (SMD-Marking)		35	SOT-23			›2SC3867
DI		Si-N	=2SD1626 (SMD-Marking)		39	SOT-89			›2SD1626
DJ		Si-P	=2SB1025-DJ (SMD-Marking)		39	SOT-89			›2SB1025
DJ		Si-N	=2SD1627 (SMD-Marking)		39	SOT-89			›2SD1627
DJ 4		N-FET	=3SK180-4 (SMD-Marking)		44	SOT-143			›3SK180
DJ 5		N-FET	=3SK180-5 (SMD-Marking)		44	SOT-143			›3SK180
DJ 6		N-FET	=3SK180-6 (SMD-Marking)		44	SOT-143			›3SK180
DJQ		Si-N	=2SD2098-Q (SMD-Marking)		39	SOT-89			›2SD2098
DJR		Si-N	=2SD2098-R (SMD-Marking)		39	SOT-89			›2SD2098
DJS		Si-N	=2SD2098-S (SMD-Marking)		39	SOT-89			›2SD2098
DK		Si-P	=2SB1025-DK (SMD-Marking)		39	SOT-89			›2SB1025
DK		Si-P	=2SB798-DK (SMD-Marking)		39	SOT-89			›2SB798
DK		Si-N	=2SD1628 (SMD-Marking)		39	SOT-89			›2SD1628
DK(s)		Si-P	=BCX 42 (SMD-Marking)		35	SOT-23			›BCX 42
DKP		Si-N	=2SC4672-P (SMD-Marking)		39	SOT-89			›2SC4672
DKQ		Si-N	=2SC4672-Q (SMD-Marking)		39	SOT-89			›2SC4672
DKS 21	Sam	Si-N-Darl	LF, 30/25V, 0,5A, 0,6W, 200MHz, hFE=2k...15k	{DKS23	7e	TO-92	BC 879	7c	BC 517, BC 617, BC 875, MPS-A25...29, ++
DKS 22	Sam	Si-N-Darl	=DKS 21: hFE=10k...40k	{DKS24	7e	TO-92	(BC 879)[13]	7c	BC 517, BC 617, MPS-A25...29, ++
DKS 23	Sam	Si-P-Darl	LF, 30/25V, 0,5A, 0,6W, 175MHz, hFE=2k...15k	{DKS21	7e	TO-92	BC 880	7c	BC 516, BC 876, MPS-A63...64, MPS-A75...77
DKS 24	Sam	Si-P-Darl	=DKS 23: hFE=10k...40k	{DKS22	7e	TO-92	(BC 880)[13]	7c	BC 516, MPS-A63...64, MPS-A75...77
DL		Si-P	=2SA1343 (SMD-Marking)		35	SOT-23			›2SA1343
DL		Si-P	=2SB1026-DL (SMD-Marking)		39	SOT-89			›2SB1025
DL		Si-P	=2SB798-DL (SMD-Marking)		39	SOT-89			›2SB798
DL		Si-N	=2SC2713-BL (SMD-Marking)		35	SOT-23			›2SC2713
DL		Si-N	=2SC4117-BL (SMD-Marking)		35(2mm)	SOT-323			›2SC4117
DL		Si-N	=2SD2099 (SMD-Marking)		39	SOT-89			›2SD2099
DL 000 D,DG	Hfo	TTL-Logic	=... 74LS00		14-DIP				... 74LS00... (TTL)
DL 000 SC	Hfo	TTL-Logic	=DL 000D,DG: SMD		14-MDIP				
DL 002 D,DG	Hfo	TTL-Logic	=... 74LS02		14-DIP				... 74LS02... (TTL)
DL 002 SC	Hfo	TTL-Logic	=DL 002D,DG: SMD		14-MDIP				
DL 003 D,DG	Hfo	TTL-Logic	=... 74LS03		14-DIP				... 74LS03... (TTL)
DL 003 S,SC	Hfo	TTL-Logic	=DL 003D: SMD		14-MDIP				
DL 004 D,DG	Hfo	TTL-Logic	=... 74LS04		14-DIP				... 74LS04... (TTL)
DL 005 DC	Hfo	TTL-Logic	=... 74LS05		14-DIP				... 74LS05... (TTL)
DL 008 D,DG	Hfo	TTL-Logic	=... 74LS08		14-DIP				... 74LS08... (TTL)
DL 008 SC	Hfo	TTL-Logic	=DL 008D,DG: SMD		14-MDIP				
DL 010 D,DG	Hfo	TTL-Logic	=... 74LS10		14-DIP				... 74LS10... (TTL)
DL 010 SC	Hfo	TTL-Logic	=DL 010D,DG: SMD		14-MDIP				
DL 011 D	Hfo	TTL-Logic	=... 74LS11		14-DIP				... 74LS11... (TTL)
DL 011 SC	Hfo	TTL-Logic	=DL 011D,DG: SMD		14-MDIP				
DL 014 D	Hfo	TTL-Logic	=... 74LS14		14-DIP				... 74LS14... (TTL)
DL 016 DC	Hfo	TTL-Logic	=... 74LS16		14-DIP				... 74LS16... (TTL)
DL 020 D,DG	Hfo	TTL-Logic	=... 74LS20		14-DIP				... 74LS20... (TTL)
DL 020 SC	Hfo	TTL-Logic	=DL 020D,DG: SMD		14-MDIP				
DL 021 D	Hfo	TTL-Logic	=... 74LS21		14-DIP				... 74LS21... (TTL)
DL 021 SC	Hfo	TTL-Logic	=DL 021D,DG: SMD		14-MDIP				
DL 026 DC	Hfo	TTL-Logic	=... 74LS26		14-DIP				... 74LS26... (TTL)
DL 030 D,DG	Hfo	TTL-Logic	=... 74LS30		14-DIP				... 74LS30... (TTL)
DL 030 SC	Hfo	TTL-Logic	=DL 030D,DG: SMD		14-MDIP				
DL 032 D	Hfo	TTL-Logic	=... 74LS32		14-DIP				... 74LS32... (TTL)
DL 032 SC	Hfo	TTL-Logic	=DL 032D,DG: SMD		14-MDIP				
DL 037 D	Hfo	TTL-Logic	=... 74LS37		14-DIP				... 74LS37... (TTL)
DL 038 D	Hfo	TTL-Logic	=... 74LS38		14-DIP				... 74LS38... (TTL)
DL 040 D	Hfo	TTL-Logic	=... 74LS40		14-DIP				... 74LS40... (TTL)
DL 051 D	Hfo	TTL-Logic	=... 74LS51		14-DIP				... 74LS51... (TTL)
DL 074 D	Hfo	TTL-Logic	=... 74LS74		14-DIP				... 74LS74... (TTL)
DL 083 D	Hfo	TTL-Logic	=... 74LS83		16-DIP				... 74LS83... (TTL)
DL 086 D	Hfo	TTL-Logic	=... 74LS86		14-DIP				... 74LS86... (TTL)
DL 090 D	Hfo	TTL-Logic	=... 74LS90		14-DIP				... 74LS90... (TTL)

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DL 093 D	Hfo	TTL-Logic	=... 74LS93		14-DIP				... 74LS93... (TTL)
DL 112 D	Hfo	TTL-Logic	=... 74LS112		16-DIP				... 74LS112... (TTL)
DL 123 D	Hfo	TTL-Logic	=... 74LS123		16-DIP				... 74LS123... (TTL)
DL 132 D	Hfo	TTL-Logic	=... 74LS132		14-DIP				... 74LS132... (TTL)
DL 155 D	Hfo	TTL-Logic	=... 74LS155		16-DIP				... 74LS155... (TTL)
DL 164 D	Hfo	TTL-Logic	=... 74LS164		14-DIP				... 74LS164... (TTL)
DL 175 D	Hfo	TTL-Logic	=... 74LS175		16-DIP				... 74LS175... (TTL)
DL 192 D	Hfo	TTL-Logic	=... 74LS192		16-DIP				... 74LS192... (TTL)
DL 193 D	Hfo	TTL-Logic	=... 74LS193		16-DIP				... 74LS193... (TTL)
DL 194 D	Hfo	TTL-Logic	=... 74LS194		16-DIP				... 74LS194... (TTL)
DL 251 D	Hfo	TTL-Logic	=... 74LS251		16-DIP				... 74LS251... (TTL)
DL 253 D	Hfo	TTL-Logic	=... 74LS253		16-DIP				... 74LS253... (TTL)
DL 257 D	Hfo	TTL-Logic	=... 74LS257		16-DIP				... 74LS257... (TTL)
DL 259 D	Hfo	TTL-Logic	=... 74LS259		16-DIP				... 74LS259... (TTL)
DL 295 D	Hfo	TTL-Logic	=... 74LS295		14-DIP				... 74LS295... (TTL)
DL 299 D	Hfo	TTL-Logic	=... 74LS299		20-DIP				... 74LS299... (TTL)
DL 374 D	Hfo	TTL-Logic	=... 74LS374		20-DIP				... 74LS374... (TTL)
DL 540 D	Hfo	TTL-Logic	=... 74LS540		20-DIP				... 74LS540... (TTL)
DL 541 D	Hfo	TTL-Logic	=... 74LS541		20-DIP				... 74LS541... (TTL)
DL 2631 D	Hfo	I/O-IC	Leitungstreiber/Line Driver, CCITT V.11.		16-DIP				AM 26LS31
DL 2632 D	Hfo	LIN-IC	Leitungsempfänger/Line Receiver f. DL 2631D		16-DIP				AM 26LS32
DL 8121 D	Hfo	LIN-IC	8-Bit Komparator		20-DIP				AmZ 8121
DL 8127 D	Hfo	TTL-IC	System Clock f. 16-Bit µComp.		24-DIP				AmZ 8127
DL 8640 DC	Hfo	TTL-IC	Bus-Empfänger/Bus Receiver		14-DIP				DS 8640N
DL 8641 DC	Hfo	TTL-IC	Bus-Empfänger/Treiber, Bus Receiver/Driver		16-DIP				DS 8641N
DL 60278	Sgs	LIN-IC	=TDA 7270 S		16-DIP				›TDA 7270S
DL 75113 DC	Hfo	TTL-IC	Leitungssender/Line Driver		16-DIP				SN 75113N
DLN		Si-N	=2SD2167-N (SMD-Marking)		39	SOT-89			›2SD2167
DLP		Si-N	=2SD2167-P (SMD-Marking)		39	SOT-89			›2SD2167
DLQ		Si-N	=2SD2167-Q (SMD-Marking)		39	SOT-89			›2SD2167
DM		Si-P	=2SB1026-DM (SMD-Marking)		39	SOT-89			›2SB1025
DM		Si-P	=2SB798-DM (SMD-Marking)		39	SOT-89			›2SB798
DM		Si-N	=2SD1998 (SMD-Marking)		39	SOT-89			›2SD1998
DM		Si-N-Darl	=2SD2170 (SMD-Marking)		39	SOT-89			›2SD2170
DM 133		Si-Di	≈2x 1N4007				2x 1N4007	31a	›1N4007
DM 513	Tho	Si-Di	kV-Rr, 1600V, 1/10A, Uf<1,3V(2A)		31a	DO-15	BY 228	31a	BY 228, EM 516, GP 10Y, RGP 15-16...-20
DM 516	Tho	Si-Di	=DM 513: 1800V		31a	SOD-15			RGP 15-18...-20
DM 2502(C)J,N	Nsc	TTL-IC	8-Bit Successive Approximation TTL Register f. A/D		16-DIC,DIP				-
DM 2503(C)J,N	Nsc	TTL-IC	8-Bit Successive Approximation TTL Register f. A/D		16-DIC,DIP				-
DM 2504(C)J,N	Nsc	TTL-IC	12-Bit Successive Approximation TTL Register f.A/D		16-DIC,DIP				-
DMA 2270	Itt	MOS-IC	CTV, D2-MAC Decoder		68-PLCC				-
DMA 2275	Itt	CMOS-IC	CTV, MAC Descrambling Processor		68-PLCC				-
DN....DR									
DN		Si-N	=2SD1999 (SMD-Marking)		39	SOT-89			›2SD1999
DN		Z-Di	=SM 6T 10 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
DN 74 LSxx...	Mat	TTL-Logic	Standard TTL-Logic 74LS-Serie						... 74LSxx... (TTL)
DN 811	Mat	LIN-IC	12/16-Zähler/Counter		14-DIC				-
DN 819	Mat	LIN-IC	i2L Frequenzteiler/Divider		4-SIP				-
DN 834	Mat	LIN-IC	Hall-Element, Schalter/Switch		4-SIP				-
DN 835	Mat	LIN-IC	Hall-Element, linear		4-SIP				-
DN 837	Mat	LIN-IC	Hall-Element, Schalter/Switch		4-SIP				-
DN 838	Mat	LIN-IC	Hall-Element, Schalter/Switch		4-SIP				-
DN 839	Mat	LIN-IC	Hall-Element, Schalter/Switch		4-SIP				-
DN 850	Mat	LIN-IC	Multivibrator, monostab.		14-DIC				-
DN 851	Mat	LIN-IC	4-Bit Zähler/Counter, reversibel		14-DIC				-
DN 852	Mat	LIN-IC	Binary ›Octal Decoder		16-DIC				-
DN 6835	Mat	LIN-IC	Hall-Element, linear		3-SIP				-
DN 6836	Mat	LIN-IC	Hall-Element, linear		3-SIP				-
DN 6837	Mat	LIN-IC	Hall-Element, Schalter/Switch		3-SIP				-
DN 6838	Mat	LIN-IC	Hall-Element, Schalter/Switch		3-SIP				-
DN 6839	Mat	LIN-IC	Hall-Element, Schalter/Switch		3-SIP				-
DN 6844 S	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=3,6...16V		≈4-MDIP				-
DN 6845 S	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=3,6...16V		≈4-MDIP				-
DN 6846 S	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=3,6...16V		≈4-MDIP				-
DN 6847(S,SE,TE)	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=4,5...16V		Diverse				-
DN 6848(S,SE,TE)	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=4,5...16V		Diverse				-
DN 6849(S,SE,TE)	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=4,5...16V		Diverse				-
DN 6851	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=3,6...16V		3-SIP				-
DN 6852	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=3,6...16V		3-SIP				-
DN 6853	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=3,6...16V		3-SIP				-
DN 8640 S	Mat	MOS-IC	3-Bit Shift Register Latch Driver		36-MDIP				-
DN 8643 S	Mat	MOS-IC	24-Bit Shift Register Latch Driver		36-MDIP				-
DN 8646 FBP	Mat	MOS-IC	4x8-Bit Shift Register Latch Driver		44-MP				-
DN 8648 FBP	Mat	MOS-IC	32-Bit Shift Register Latch Driver		44-MP				-
DN 8650	Mat	MOS-IC	Darlington Driver Array, 5V, 0,5A		16-DIP				-
DN 8661	Mat	MOS-IC	Darlington Driver Array, 50V, 0,5A		16-DIP				-
DN 8680	Mat	MOS-IC	Darlington Driver Array, 50V, 1,5A		16-DIP				-
DN 8690	Mat	MOS-IC	Darlington Driver Array, 60V, 1,5A		16-DIP				-
DN 8695	Mat	MOS-IC	Darlington Driver Array, 50V, 1,5A		23-SQL				-
DN 8897(S,SE,TE)	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=4,5...16V		Diverse				-
DN 8898 SE,TE	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=4,5...16V		3-SIP				-
DN 8899(S,SE,TE)	Mat	LIN-IC	Hall-Verstärker/Amplifier, Ucc=4,5...16V		Diverse				-
DNE		Si-N	=2SD2153-E (SMD-Marking)		39	SOT-89			›2SD2153
DNU		Si-N	=2SD2153-U (SMD-Marking)		39	SOT-89			›2SD2153
DNV		Si-N	=2SD2153-V (SMD-Marking)		39	SOT-89			›2SD2153
DNW		Si-N	=2SD2153-W (SMD-Marking)		39	SOT-89			›2SD2153
DO		Si-P	=2SA1201-O (SMD-Marking)		39	SOT-89			›2SA1201
DO		Si-P	=2SA1620-O (SMD-Marking)		35	SOT-23			›2SA1620
DO		Si-N	=2SC5092-O (SMD-Marking)		44	SOT-143			›2SC5092
DO		Si-N	=2SD1997 (SMD-Marking)		39	SOT-89			›2SD1997
DO		Si-P	=KTA1661-O (SMD-Marking)		39	SOT-89			›KTA 1661

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DO 201 YR	Tag	Diac	Ub=26…32V, Ib<50µA, Itsm=2A		31l	DO-35			1N5761, N 413M, BR 100, D 3202Y
DP		Si-P	=2SB789-P (SMD-Marking)		39	SOT-89			›2SB789
DP		Si-N	=2SD2100 (SMD-Marking)		39	SOT-89			›2SD2100
DP		Si-N-Darl	=2SD2195 (SMD-Marking)		39	SOT-89			›2SD2195
DP		Si-P	=HQ 1L2N (SMD-Marking)		39	SOT-89			›HQ 1…
DP		Z-Di	=SM 6T 10A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T….
DPU 2500	Itt	NMOS-IC	CTV, Ablenk-/Deflection Processor		40-DIP				-
DPU 2540	Itt	NMOS-IC	CTV, Ablenk-/Deflection Processor		40-DIP				-
DPU 2543	Itt	NMOS-IC	CTV, Ablenk-/Deflection Processor		40-DIP				-
DPU 2544	Itt	NMOS-IC	CTV, Ablenk-/Deflection Processor		40-DIP				-
DPU 2545	Itt	NMOS-IC	CTV, Ablenk-/Deflection Processor		40-DIP				-
DPU 2553	Itt	NMOS-IC	CTV, Ablenk-/Deflection Processor, normal-scan		40-DIP		DPU 2553	40-DIP	-
DPU 2554	Itt	NMOS-IC	CTV, Ablenk-/Deflection Processor, double-scan		40-DIP				-
DPU 2555	Itt	NMOS-IC	CTV, Ablenk-/Deflection Processor, normal-scan		40-DIP				-
DQ		Si-P	=2SB1219A-Q (SMD-Marking)		35(2mm)	SOT-323			›2SB1219A
DQ		Si-P	=2SB710A-Q (SMD-Marking)		35	SOT-23			›2SB710A
DQ		Si-P	=2SB789-Q (SMD-Marking)		39	SOT-89			›2SB789
DQ		Si-N-Darl+Di	=2SD2176 (SMD-Marking)		39	SOT-89			›2SD2176
DQ		Si-P	=HQ 1A3M (SMD-Marking)		39	SOT-89			›HQ 1…
DQN		Si-N	=2SD2211-N (SMD-Marking)		39	SOT-89			›2SD2211
DQP		Si-N	=2SD2211-P (SMD-Marking)		39	SOT-89			›2SD2211
DQQ		Si-N	=2SD2211-Q (SMD-Marking)		39	SOT-89			›2SD2211
DR		Si-P	=2SA1037KLN-R (SMD-Marking)		35	SOT-23			›2SA1037KLN
DR		Si-P	=2SB1219A-R (SMD-Marking)		35(2mm)	SOT-323			›2SB1219A
DR		Si-P	=2SB710A-R (SMD-Marking)		35	SOT-23			›2SB710A
DR		Si-P	=2SB789-R (SMD-Marking)		39	SOT-89			›2SB789
DR		Si-N	=2SC4643 (SMD-Marking)		39	SOT-89			›2SC4643
DR		Si-N	=2SC5092-R (SMD-Marking)		44	SOT-143			›2SC5092
DR		Si-N-Darl	=2SD2212 (SMD-Marking)		39	SOT-89			›2SD2212
DR		Si-P	=HQ 1F3M (SMD-Marking)		39	SOT-89			›HQ 1…
DRA 01 B…E	Say	50Hz-Thy	100…400V, 0,1A(Ta=55°), 0,15A~, Igt/Ih<0,2/=3mA B=100V, C=200V, E=400V		7b	TO-92	BRX 49	7a	BRX51…56, BRY55/…, MCR100-…, TAG06-…
DRA 2 TB…TG	Say	50Hz-Thy	100…600V, 2A(Tc=45°), Igt/Ih<0,2/=3mA TB=100V, TC=200V, TE=400V, TG=600V		13e	TO-202	(TIC 106 M)[4]	17e	C 106-…, TAG 106-…
DRA 03 TB…TG	Say	50Hz-Thy	100…600V, 0,3A(Ta=30°), 0,45A~, Igt/Ih<0,2/=4mA TB=100V, TC=200V, TE=400V, TG=600V		7b	TO-92	BRX 49	7a	BRX51…56, BRY55/…, MCR100-…, TAG06-…
DRA 5 B…G	Say	50Hz-Thy	100…600V, 5A(Tc=91°), 7,8A~, Igt/Ih<40/<60mA B=100V, C=200V, E=400V, G=600V		17e	TO-220	TAG 626-600	17e	MCR 218-…, TAG 625-…, TIC 116-…, ++
DRA 8 B…G	Say	50Hz-Thy	100…600V, 8A(Tc=83°), 12,6A~, Igt/Ih<40/<60mA B=100V, C=200V, E=400V, G=600V		17e	TO-220			TAG 680-…, TIC 122-…, TIC 126-…, ++
DRB 2 B…E	Say	F-Thy	100…400V, 2A(Tc=35°), Igt/Ih<1,5/=12mA, tq<15µs B=100V, C=200V, E=400V		13e	TO-202			S 3060…
DRC 2 E	Say	50Hz-Thy	400V, 2A(Tc=30°), 3A~, Igt/Ih<50/<120mA		30e	(10x8x5)			-
DRC 3 E	Say	50Hz-Thy	400V, 3A(Tc=65°), 4,7A~, Igt/Ih<50/<120mA		17e	TO-220	TAG 626-600	17e	BStC10…, TAG 620-…
DRD 3 B…G	Say	50Hz-Thy	100…600V, 3A, 4,5A~, Igt/Ih<15/=60mA B=100V, C=200V, E=400V, G=600V		17e	TO-220	TAG 626-600	17e	TAG 620-…
DRE 3 B…G	Say	50Hz-Thy	100…600V, 3A(Tc=90°), 4,7A~, Igt/Ih<0,2/=4mA B=100V, C=200V, E=400V, G=600V		13e	TO-202	(TIC 106 M)[4]	17e	C 108-…, TAG 108-…
DRR 114		Si-Di	=BA 159				BA 159	31a	›BA 159
DS….DV									
DS		Si-P	=2SA1037KLN-S (SMD-Marking)		35	SOT-23			›2SA1037KLN
DS		Si-P	=2SA1728 (SMD-Marking)		35	SOT-23			›2SA1728
DS		Si-P	=2SB1219A-S (SMD-Marking)		35(2mm)	SOT-323			›2SB1219A
DS		Si-P	=2SB710A-S (SMD-Marking)		35	SOT-23			›2SB710A
DS		Si-P	=2SB789-S (SMD-Marking)		39	SOT-89			›2SB789
DS		Si-N	=2SD1946 (SMD-Marking)		39	SOT-89			›2SD1946
DS		Si-P	=BCX 42R (SMD-Marking)		35	SOT-23			›BCX 42R
DS		Si-P	=HQ 1F3P (SMD-Marking)		39	SOT-89			›HQ 1…
DS 0,8-04B…16B	Bbc	Si-Di	Rr, 400…1600V, 1A, 4,5A~, Uf<1,2V(3A)				BY 255	31a	BY 133…134, BY 126…127, GP 10G…Y, ++
DS 0,9-04A…16A	Bbc	Si-Di	Rr, 400…1600V, 1,2A, 5A~, Uf<1,2V(3A)		12c	(10x9x4)	BY 255,BYD 33M	31a	BY 226…228, BY 252…255, BY 350/…, ++
DS 1-04B…16B	Bbc	Si-Di	Rr, 400…1600V, 1,2A, 5A~, Uf<1,2V(6A)				BY 255,BYD 33M	31a	BY 226…228, BY 252…255, BY 350/…, ++
DS 1 H….P	Fjd	Si-Di	Rr, 300…1800V~, 1,1A, Uf<1,1V(2A) H=1800, K=1500, M=1000, N=500, P=300V		34a	(13x9mmØ)	BY 228,BYD 33M	31a	BY 226…228, BY 251…255, GP 15B…M, ++
DS 1,2-04A…16A	Bbc	Si-Di	Rr, 400…1600V, 1,7A, 7A~, Uf<1,3V(6A)		31a	(16x6mmØ)	BY 255	31a	BY 228, BY 252…255, BY 448, GP 20G…M++
DS 1,8-04A…16A	Bbc	Si-Di	Rr, 400…1600V, 1,7A, 7A~, Uf<1,3V(6A)		12c	(12x14x5)	BY 255	31a	BY 228, BY 252…255, BY 448, GP 20G…M++
DS 2-04A…16A	Bbc	Si-Di	Rr, 400…1600V, 1,8A, 7A~, Uf<1,25V(7A)		34b	DO-13	BY 228	31a	BY 228, BY 252…255, BY 448, GP 30G…M++
DS 2 H….P	Fjd	Si-Di	=DS 1H…P: 1,65A, Uf<1,1V(4A)		34a	(13x9mmØ)	BY 228	31a	BY 228, BY 251…255, BYW 52…56, ++
DS 2 S		Si-Di	~BA 100		31a		1N4148	31a	›BA 100
DS 5 S(R)		Si-Di	Dual, Rr				2x 1N4007	31a	2xBY126…127, 2xBY133…135, 2x1N4002…07
DS 6-04A…16A	Bbc	Si-Di	P Rr, 400…1600V, 10A(Tc=131°), 16A~, Uf<1,6V(30A)		32b				BYX 42/…R, BYX 98/…R, SSi D04…, ++
DS 8-04A…16A	Bbc	Si-Di	P Rr, 400…1600V, 11A(Tc=150°), 18A~, Uf<1,4V(36A)		32b				BYW 88/…R, BYX 99/…R, SSi E20…, ++
DS 10-01B…05B	Bbc	Si-Di	P Rr, 100…500V, 12A(Tc=150°), 19A~, Uf<1,2V(30A)		32b	DO-4			BYW 88/…R, BYX 99/…R, SSi E20…, ++
DS 13 A,B	Say	Si-Di	Rr, A=350/500, B=210/300V, 1,5A, Uf<1,1V(2A)		31a	(6x13mmØ)	BY 255	31a	BY 226…227, BY 252…255, GP 20G…M, ++
DS 13 C…J	Hit	Si-Di	P Rr, 200…800V, 20A, Uf<1,2V(20A) C=200V, E=400V, G=600V, J=800V		32a	DO-5			1N3765…3768, 1N4525…4530
DS 14 C…J	Hit	Si-Di	=DS 13 C…J:		32b	DO-5			D 24/…C, 1N3765…3768R
DS 14 C88	Nsc	CMOS-IC	›KS 5788		14-DIP				KS 5788
DS 14 C89(A)	Nsc	CMOS-IC	›KS 5789		14-DIP				KS 5789
DS 15 A,B	Say	Si-Di	Rr, A=600, B=800V, 0,3A, Uf<1,2V(0,5A), <1,5µs		31a	DO-27	BA 159	31a	BA 158…159, BY 126…127, BY 204/…, ++
DS 15 C,E,G	Say	Si-Di	Rr, C=300, E=500, G=800V, 0,2/0,6A, Uf<1,2V(0,2A)		12		BA 159	31a	BA 157…159, BY 126…127, BY 204/…, ++
DS 16(N)A….(N)E	Say	Si-Di	Rr, 50…800V, 0,5A, Uf<1V(0,5A) A=800V, B=600V, C=300V, D=100V, E=50V		31a	DO-27	BY 133	31a	BY 126…127, BY 133…135, 1N4001…07, ++
DS 17	Say	Si-Di	Dual, 70/100V, 2x0,5A, Uf<1,1V(0,5A)		12e	(10x7x4)	2x 1N4007	31a	2xBY126…127, 2xBY133…135, 2x1N4002…07
DS 18	Say	Si-Di	=DS 17:		12h	(10x7x4)	2x 1N4007	31a	2xBY126…127, 2xBY133…135, 2x1N4002…07
DS 19	Say	Si-Di	=DS 17:		12r	(10x7x4)	2x 1N4007	31a	2xBY126…127, 2xBY133…135, 2x1N4002…07
DS 20		Si-Di	~BA 127				1N4148	31a	›BA 127
DS 23		Si-St	~BZX 75/C2V1				Z-Diode, 2,1V	31a	›BZX 75/C2V1
DS 26 LS 31…32…	Nsc	I/O-IC	›AM 26LS31…32…						›AM 26LS31…32…
DS 38	Say	Si-Di	Uni, 50/70V, 0,15/5A, Uf<1V(0,15A)		31a	(4,5x4Ø)	1N4148	31a	BA 188…190, BAY 19…21, 1N4148, ++
DS 113 A….C	Say	Si-Di	TV Damper-Di, 1,5/5A, Uf<1,2V(1,5A), <1µs A=1000V, B=1300V, C=1500V		34b	DO-1	BY 228	31a	BY 228, BY 328, BY 448

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DS 118 A....E	Say	Si-Di	Rr, 200...1000V, 1,5A, Uf<0,93V(1,5A) A=200V, B=400V, C=600V, D=800V, E=1000V		34	DO-1	BY 255,BYD 33M	31a	BY 226...227, BY 251...255, GP 20B...M, ++
DS 130 A....E	Say	Si-Di	Rr, 100...800V, 1A, Uf<1V(1A) A=800V, B=600V, C=400V, D=200V, E=100V		31a	DO-27	1N4007	31a	BY 126...127, BY 133...135, 1N4002...07, ++
DS 130 NA....NE		Si-Di	=DS 130A...E		31a	DO-27	1N4007	31a	›DS 130A...E
DS 130 TA....TE		Si-Di	=DS 130A...E:		31a	DO-15	1N4007	31a	›DS 130A...E
DS 130 YA...YE		Si-Di	=DS 130A...E:		31a	=DO-21	1N4007	31a	›DS 130A...E
DS 131 A,B	Say	Si-Di	Dual, A=100, B=200V, 2x0,9A, Uf<1V(0,9A)		12e	(12x9x5)	2x BY 255	31a	2xBY251...255, 2xBY259/..., 2xGP20B...M, ++
DS 132 A,B	Say	Si-Di	=DS 131A,B:		12h	(12x9x5)	2x BY 255	31a	›DS 131A,B
DS 133 A,B	Say	Si-Di	=DS 131A,B:		12r	(12x9x5)	2x BY 255	31a	›DS 131A,B
DS 135 C....F	Say	Si-Di	Rr, 50...400V, 1/15A, Uf<1V(1A) C=400V, D=200V, E=100V, F=50V		31a	SOD-22	1N4007	31a	BY 126...127, BY 133...135, 1N4001...07, ++
DS 140	Say	Si-Di	TV Damper, 700/750V, -/13A, Uf<1,2V(1,5A), <360ns		34b	DO-1	BY 228	31a	BY 399, BYW 14...16/..., BYW 96/...
DS 140 DC	Hfo	TTL-Logic	Schottky Interface, Power Driver		14-DIP				SN 74S140
DS 150 A....C	Say	Si-Di	Rr, 200...600V, 1,5A, Uf<0,93V(1,5A) A=200, B=400, C=600V		31a	(7x6mmØ)	BYD 33 M	31a	BY 226...227, BY 251...255, GP 20D...M, ++
DS 157 DC	Hfo	TTL-Logic	Schottky Interface, Multiplexer		16-DIP				SN 74S157
DS 160 A,B	Say	Si-Di	kV-Rr, A=9kV, B=12kV, 0,55A						-
DS 185 D....F	Say	Si-Br	Br Rr, 50...200V, 1,3A, Uf<0,9V(0,65A) D=200V, E=100V, F=50V		33(-≈+≈)	(20x22x6)	B250C1500		B30C1500...B150C1500, etc.
DS 230 A....D	Say	Si-Di	FRr, 300...1000V, 0,3A, Uf<1,5V(0,5A), <300ns A=300V, B=600V, C=800V, D=1000V		31a	DO-27	BA 159	31a	BA 157...159, BY 204/..., BY 208/..., ++
DS 330 A....D	Say	Si-Di	FRr, 400...1000V, 0,13A, Uf<2,5V(0,1A), <300ns A=400V, B=600V, C=800V, D=1000V		31a	DO-27	BA 159	31a	BA 157...159, BY 204/..., BY 208/..., ++
DS 410		Si-Di	=BA 127		31a		1N4148	31a	›BA 127
DS 430	Say	Si-St	20mA, 0,55...0,8V(1,5mA)		31a	SOD-17	(1N4148)	31a	BA 216, BA 314...315
DS 441	Say	Si-Di	Uni, 30/35V, 0,1/0,3A, Uf<1,3V(0,1A)		31a	DO-35	1N4148	31a	BA 127, BA 147/50, BA 187...190, 1N4148++
DS 442	Say	Si-Di	SS, 30/35V, 0,12/0,36V, Uf<0,65V(1,5mA), <4ns		31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
DS 442 X	Say	Si-Di	=DS 442: 50/55V, 0,13/0,4A, <2ns		31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
DS 446	Say	Si-Di	SS, 100/105V, 0,2/0,5A, Uf<0,65V(1,5mA), 2<4ns		31a	DO-35	(1N4148)	31a	BAV 14
DS 448	Say	Si-Di	SS, 30/35V, 0,12/0,36A, Uf<1V(50mA), <4ns		31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
DS 452	Say	Si-Di	Uni, 200/220V, 0,1/0,3A, Uf<1V(0,1A)		31a	DO-35	BA 159	31a	BAY 20, BAY 46, BAY 88, BA 157...159
DS 454	Say	Si-Di	=DS 452: 300/320V		31a	DO-35	BA 159	31a	BA 157...159, BAY 46, BAY 88...89, ++
DS 462	Say	Si-Di	Uni, S, 200/250V, 0,2/0,6A, Uf<1,2V(0,1A), <60ns		31a	DO-35	BA 159	31a	BAY 21, BAY 46, BAY 88, BA 157...159
DS 464	Say	Si-Di	=DS 462: 250/300V		31a	DO-35	BA 159	31a	BAY 21, BAY 46, BAY 88, BA 157...159
DS 1488	Nsc	I/O-IC	4x Leitungstreiber/Line Driver f. RS232		14-DIP				MC 1488, SN 75188, XR 1488, µA 1488
DS 1489(A)	Nsc	I/O-IC	4x Leitungsempfänger/Line Receiver f. RS232		14-DIP				MC1489(A),SN75189(A),XR1489(A),µA1489(A)
DS 2510 DC	Hfo	TTL-IC	Schottky Interface, 4-Bit Shifter		16-DIP				Am 25S10N
DS 2610 DC	Hfo	TTL-IC	Schottky Interface, 4x Bus-I/O		16-DIP				Am 26S10N
DS 3486	Mot	I/O-IC	=MC 3486L,P		16-DIC/DIP				›MC 3486
DS 3487	Mot	I/O-IC	=MC 3487L,P		16-DIC/DIP				›MC 3487
DS 8205 D	Hfo	TTL-IC	Schottky, 1/8-Binärdecoder/Binary Decoder		16-DIP				i 8205
DS 8212 D	Hfo	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		24-DIP				i 8212
DS 8216 D	Hfo	TTL-IC	Schottky, 4-Bit Bustreiber/Bus Driver		16-DIP				i 8216
DS 8282 D	Hfo	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		20-DIP				i 8282
DS 8283 D	Hfo	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		20-DIP				i 8283
DS 8286 D	Hfo	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		20-DIP				i 8286
DS 8287 D	Hfo	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		20-DIP				i 8287
DS 8601 DC	Hfo	I/O-IC	DMA-Logic		20-DIP				-
DS 8609 DC	Hfo	I/O-IC	Ser.-Par./Par.-Ser. Converter		40-DIP				DC 018
DS 8638 DC	Hfo	DIG-IC	8-Bit Bustreiber/Bus Driver, bidirectional		20-DIP				DC 021
DS 8640 N	Nsc	TTL-IC	Bus-Empfänger, Bus Receiver		14-DIP				DL 8640DC
DS 8641 N	Nsc	TTL-IC	Bus-Empfänger/Treiber, Bus Receiver/Driver		16-DIP				DL 8641DC
DS 75107...	Nsc	I/O-IC	›µA 75107...						›µA 75107...
DS 75108...	Nsc	I/O-IC	›µA 75108...						›µA 75108...
DS 75150...	Nsc	I/O-IC	›µA 75150...						›µA 75150...
DS 75154...	Nsc	I/O-IC	›µA 75154...						›µA 75154...
DS 75450...	Nsc	I/O-IC	›µA 75450...						›µA 75450...
DS 75491...	Nsc	I/O-IC	›µA 75491...						›µA 75491...
DS 80612 DC	Hfo	DIG-IC	Taktgenerator/Clock Generator		18-DIP				-
DT									
DT		Si-N	=2SC4112 (SMD-Marking)		35	SOT-23			›2SC4112
DT		Si-N-Darl	=2SD1471-DT (SMD-Marking)		39	SOT-89			›2SD1471
DT		Si-P	=BCW 67RA (SMD-Marking)		35	SOT-23			›BCW 67RA
DT		Si-P	=HQ 1L2Q (SMD-Marking)		39	SOT-89			›HQ 1...
DT		Si-N	=XN 6A554 (SMD-Marking)		46	SOT-163			›XN 6A554
DT 1-02....12	Tho	50Hz-Thy	200...1200V, 1,3A(Tc=135°C), Igt/Ih=15/<40mA		27n	(10x9x5)			BStA30...M, BStC07...
DT 5 A114E	Nec	Si-P+R	5xPNP, common Emitter, Rb=Rbe=10kΩ, 50V, 50mA		12-SQP				-
DT 5 A124E	Nec	Si-P+R	5xPNP, common Emitter, Rb=Rbe=22kΩ, 50V, 30mA		12-SQP				-
DT 5 A143E	Nec	Si-P+R	5xPNP, common Emitter, Rb=Rbe=4,7kΩ, 50V, 100mA		12-SQP				-
DT 5 A143X	Nec	Si-P+R	5xPNP,common Emit., Rb=4,7kΩ, Rbe=10kΩ, 50V, 100mA		12-SQP				-
DT 5 A144E	Nec	Si-P+R	5xPNP, common Emitter, Rb=Rbe=47kΩ, 50V, 30mA		12-SQP				-
DT 5 C114E	Nec	Si-N+R	5xNPN, common Emitter, Rb=Rbe=10kΩ, 50V, 50mA		12-SQP				-
DT 5 C124E	Nec	Si-N+R	5xNPN, common Emitter, Rb=Rbe=22kΩ, 50V, 30mA		12-SQP				-
DT 5 C143E	Nec	Si-N+R	5xNPN, common Emitter, Rb=Rbe=4,7kΩ, 50V, 100mA		12-SQP				-
DT 5 C144E	Nec	Si-N+R	5xNPN, common Emitter, Rb=Rbe=47kΩ, 50V, 30mA		12-SQP				-
DT 06-02....10	Tho	50Hz-Thy	200...1000V, 0,8A(Tc=125°C), Igt/Ih=10/<20mA		2a	TO-5			TAG 612-..., S 2600..., TAG 613-..., ++
DTA									
DTA 1 C...E	Say	Triac	200...400V, 1A≈(Tc=74°), Igt/Ih=10/<10mA C=200V, E=400V		7p	TO-92			Z 0101..., Z 0104..., Z 0106
DTA1D3R(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=2,7k, Rbe=1kΩ, 50V, 70/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c				-
DTA 1 D3RE		Si-P+R	=DTA 1D3R...: SMD		35a(1,6mm)	SS Mini			-
DTA 1 D3RK(A)		Si-P+R	=DTA 1D3R...: SMD		35a(2,9mm)	SOT-23			-
DTA 1 D3RU(A)		Si-P+R	=DTA 1D3R...: SMD		35a(2mm)	SOT-323			-
DTA 2 B...E	Say	Triac	100...400V, 2A≈(Tc=70°), Igt/Ih<15/<25mA B=100V, C=200V, E=400V		13j	TO-202			TAG 137-..., TAG 138-...
DTA 3 E...G	Say	Triac	400...600V, 3A≈(Tc=77°), Igt/Ih<45/≈25mA E=400V, F=500V, G=600V		13j	TO-202	(TAG 232-600)[4]	17j	Z 0409..., Z 0410...

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DTA 05 B...E	Say	Triac	100...400V, 0,5A=(Ta=20°), Igt/Ih<15/<25mA B=100V, C=200V, E=400V		7l	TO-92			MAC 94(A)-..., MAC 95(A)-...
DTA 6 C...G(-N)	Say	Triac	200...600V, 6A=(Tc=104°), Igt/Ih<50/<50mA C=200V, E=400V, G=600V		17j	TO-220			MAC 216A-..., T 2500..., TAG 220-...
DTA 08 E	Say	Triac	400V, 0,8A=(Tc=60°), Igt/Ih<10/<10mA		7p	TO-92			MAC 94(A)-..., MAC 95(A)-..., MAC 96(A)-...
DTA 10 E...G	Say	Triac	400...600V, 10A=(Tc=91°), Igt/Ih<80/=30mA E=400V, F=500V, G=600V		17j	TO-220			BTA 22-..., TAG 250-..., TAG 251-...
DTA 25 C...G	Say	Triac	200...600V, 25A=(Tc=73°), Igt/Ih<50/<70mA C=200V, E=400V, G=600V		65l				MAC 525(A)-...
DTA113Z(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=1k, Rbe=10kΩ, 50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c				AN 1A3Q, UN 4119
DTA 113 ZE		Si-P+R	=DTA 113Z...: SMD		35a(1,6mm)	SS Mini			-
DTA 113 ZK(A)		Si-P+R	=DTA 113Z...: SMD		35a(2,9mm)	SOT-23			FN 1A3Q, UN 2119
DTA 113 ZU(A)		Si-P+R	=DTA 113Z...: SMD		35a(2mm)	SOT-323			-
DTA114E(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=Rbe=10kΩ, 50V, 50/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c		(BC 556)[18]	7a	AN 1A4M, RN 2002, UN 4111, 2SA1348,++
DTA 114 EE		Si-P+R	=DTA 114E...: SMD		35a(1,6mm)	SS Mini			-
DTA 114 EK(A)		Si-P+R	=DTA 114E...: SMD		35a(2,9mm)	SOT-23			FN 1A4M, RN 2402, UN2111, 2SA1344,++
DTA 114 EU(A)		Si-P+R	=DTA 114E...: SMD		35a(2mm)	SOT-323			2SA1678
DTA114G(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=-, Rbe=10kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	-
DTA 114 GE		Si-P+R	=DTA 114G...: SMD		35a(1,6mm)	SS Mini			-
DTA 114 GK(A)		Si-P+R	=DTA 114G...: SMD		35a(2,9mm)	SOT-23			-
DTA 114 GU(A)		Si-P+R	=DTA 114G...: SMD		35a(2mm)	SOT-323			-
DTA114T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=10kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	AN 1A4Z, RN 2011, UN 4115, 2SA1497,++
DTA 114 TE		Si-P+R	=DTA 114T...: SMD		35a(1,6mm)	SS Mini			-
DTA 114 TK(A)		Si-P+R	=DTA 114T...: SMD		35a(2,9mm)	SOT-23			FN 1A4Z, RN 2411, UN 2115, 2SA1496,++
DTA 114 TU(A)		Si-P+R	=DTA 114T...: SMD		35a(2mm)	SOT-323			-
DTA114W(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=10k, Rbe=4,7kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	UN 411K
DTA 114 WE		Si-P+R	=DTA 114W...: SMD		35a(1,6mm)	SS Mini			-
DTA 114 WK(A)		Si-P+R	=DTA 114W...: SMD		35a(2,9mm)	SOT-23			-
DTA 114 WU(A)		Si-P+R	=DTA 114W...: SMD		35a(2mm)	SOT-323			-
DTA114Y(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=10k, Rbe=47kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	AN 1A4P, RN 2007, UN 4114, 2SA1564,++
DTA 114 YE		Si-P+R	=DTA 114Y...: SMD		35a(1,6mm)	SS Mini			-
DTA 114 YK(A)		Si-P+R	=DTA 114Y...: SMD		35a(2,9mm)	SOT-23			FN 1A4P, RN 2407, UN 2114, 2SA1563,++
DTA 114 YU(A)		Si-P+R	=DTA 114Y...: SMD		35a(2mm)	SOT-323			-
DTA115E(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=Rbe=100kΩ, 50V, 20/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c				-
DTA 115 EE		Si-P+R	=DTA 115E...: SMD		35a(1,6mm)	SS Mini			-
DTA 115 EK(A)		Si-P+R	=DTA 115E...: SMD		35a(2,9mm)	SOT-23			-
DTA 115 EU(A)		Si-P+R	=DTA 115E...: SMD		35a(2mm)	SOT-323			-
DTA115G(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=-, Rbe=100kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c				-
DTA 115 GE		Si-P+R	=DTA 115G...: SMD		35a(1,6mm)	SS Mini			-
DTA 115 GK(A)		Si-P+R	=DTA 115G...: SMD		35a(2,9mm)	SOT-23			-
DTA 115 GU(A)		Si-P+R	=DTA 115G...: SMD		35a(2mm)	SOT-323			-
DTA115T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=100kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c				-
DTA 115 TE		Si-P+R	=DTA 115T...: SMD		35a(1,6mm)	SS Mini			-
DTA 115 TK(A)		Si-P+R	=DTA 115T...: SMD		35a(2,9mm)	SOT-23			-
DTA 115 TU(A)		Si-P+R	=DTA 115T...: SMD		35a(2mm)	SOT-323			-
DTA123E(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=Rbe=2,2kΩ, 50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c				-
DTA 123 EE		Si-P+R	=DTA 123E...: SMD		35a(1,6mm)	SS Mini			-
DTA 123 EK(A)		Si-P+R	=DTA 123E...: SMD		35a(2,9mm)	SOT-23			-
DTA 123 EU(A)		Si-P+R	=DTA 123E...: SMD		35a(2mm)	SOT-323			-
DTA123J(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=2,2k, Rbe=47kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c				RN 2005
DTA 123 JE		Si-P+R	=DTA 123J...: SMD		35a(1,6mm)	SS Mini			-
DTA 123 JK(A)		Si-P+R	=DTA 123J...: SMD		35a(2,9mm)	SOT-23			RN 2405
DTA 123 JU(A)		Si-P+R	=DTA 123J...: SMD		35a(2mm)	SOT-323			-
DTA123Y(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=2,2k, Rbe=10kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c				UN 411H, 2SA1503
DTA 123 YE		Si-P+R	=DTA 123Y...: SMD		35a(1,6mm)	SS Mini			-
DTA 123 YK(A)		Si-P+R	=DTA 123Y...: SMD		35a(2,9mm)	SOT-23			UN 211H, 2SA1502
DTA 123 YU(A)		Si-P+R	=DTA 123Y...: SMD		35a(2mm)	SOT-323			2SA1722
DTA124E(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=22k, Rbe=22kΩ, 50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c		(BC 556)[18]	7a	AN 1F4M, RN 2003, UN 4112, 2SA1346,++
DTA 124 EE		Si-P+R	=DTA 124E...: SMD		35a(1,6mm)	SS Mini			-
DTA 124 EK(A)		Si-P+R	=DTA 124E...: SMD		35a(2,9mm)	SOT-23			FN 1F4M, RN 2403, UN 2112, 2SA1342,++
DTA 124 EU(A)		Si-P+R	=DTA 124E...: SMD		35a(2mm)	SOT-323			2SA1677
DTA124G(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=-, Rbe=22kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	2SA1574
DTA 124 GE		Si-P+R	=DTA 124G...: SMD		35a(1,6mm)	SS Mini			-
DTA 124 GK(A)		Si-P+R	=DTA 124G...: SMD		35a(2,9mm)	SOT-23			2SA1573
DTA 124 GU(A)		Si-P+R	=DTA 124G...: SMD		35a(2mm)	SOT-323			-
DTA124T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=22kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	AN 1F4Z, KSR 2011, UN 4117, 2SA1590
DTA 124 TE		Si-P+R	=DTA 124T...: SMD		35a(1,6mm)	SS Mini			-
DTA 124 TK(A)		Si-P+R	=DTA 124T...: SMD		35a(2,9mm)	SOT-23			FN 1F4Z, KSR 2111, UN 2117, 2SA1598
DTA 124 TU(A)		Si-P+R	=DTA 124T...: SMD		35a(2mm)	SOT-323			-
DTA124X(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=22k, Rbe=47kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	AN 1F4N, KSR 2007, RN 2008
DTA 124 XE		Si-P+R	=DTA 124X...: SMD		35a(1,6mm)	SS Mini			-
DTA 124 XK(A)		Si-P+R	=DTA 124X...: SMD		35a(2,9mm)	SOT-23			FN 1F4N, KSR 2107, RN 2408
DTA 124 XU(A)		Si-P+R	=DTA 124X...: SMD		35a(2mm)	SOT-323			-
DTA125T(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=200kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c				-
DTA 125 TK		Si-P+R	=DTA 125T...: SMD		35a(2,9mm)	SOT-23			-
DTA 125 TU		Si-P+R	=DTA 125T...: SMD		35a(2mm)	SOT-323			-
DTA143E(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=Rbe=4,7kΩ, 50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c				AN 1L3M, RN 2001, UN 411L, 2SA1656,++
DTA 143 EE		Si-P+R	=DTA 143E...: SMD		35a(1,6mm)	SS Mini			-
DTA 143 EK(A)		Si-P+R	=DTA 143E...: SMD		35a(2,9mm)	SOT-23			FN 1L3M, RN 2401, UN 211L, 2SA1655,++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DTA 143 EU(A)		Si-P+R	=DTA 143E...: SMD		35a(2mm)	SOT-323			-
DTA143T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=4,7kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c				AN 1L3Z, RN 2010, UN 4116, 2SA1511,++
DTA 143 TE		Si-P+R	=DTA 143T...: SMD		35a(1,6mm)	SS Mini			-
DTA 143 TK(A)		Si-P+R	=DTA 143T...: SMD		35a(2,9mm)	SOT-23			FN 1L3Z, RN 2410, UN 2116, 2SA1510,++
DTA 143 TU(A)		Si-P+R	=DTA 143T...: SMD		35a(2mm)	SOT-323			-
DTA143X(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=4,7k, Rbe=10kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c				AN 1L3N, KSR 2005, UN 411F, 2SA1654
DTA 143 XE		Si-P+R	=DTA 143X...: SMD		35a(1,6mm)	SS Mini			-
DTA 143 XK(A)		Si-P+R	=DTA 143X...: SMD		35a(2,9mm)	SOT-23			FN 1L3N, KSR 2105, UN 211F, 2SA1653
DTA 143 XU(A)		Si-P+R	=DTA 143X...: SMD		35a(2mm)	SOT-323			-
DTA143Z(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=4,7k, Rbe=47kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c				RN 2006, 2SA1591, 2SA1616
DTA 143 ZE		Si-P+R	=DTA 143Z...: SMD		35a(1,6mm)	SS Mini			-
DTA 143 ZK(A)		Si-P+R	=DTA 143Z...: SMD		35a(2,9mm)	SOT-23			RN 2406, 2SA1597
DTA 143 ZU(A)		Si-P+R	=DTA 143Z...: SMD		35a(2mm)	SOT-323			-
DTA144E(A,F,L,S,V)(A)	Rhm	Si-P+R	S, Rb=Rbe=47kΩ, 50V, 30/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTA...(...)A: 100mA Version Serie/Series		9c, 41c		(BC 556)[18]	7a	AN 1L4M, RN 2004, UN 4113, 2SA1345,++
DTA 144 EE		Si-P+R	=DTA 144E...: SMD		35a(1,6mm)	SS Mini			-
DTA 144 EK(A)		Si-P+R	=DTA 144E...: SMD		35a(2,9mm)	SOT-23			FN 1L4M, RN 2404, UN 2113, 2SA1341,++
DTA 144 EU(A)		Si-P+R	=DTA 144E...: SMD		35a(2mm)	SOT-323			2SA1676
DTA144G(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=-, Rbe=47kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	2SA1572
DTA 144 GE		Si-P+R	=DTA 144G...: SMD		35a(1,6mm)	SS Mini			-
DTA 144 GK(A)		Si-P+R	=DTA 144G...: SMD		35a(2,9mm)	SOT-23			2SA1571
DTA 144 GU(A)		Si-P+R	=DTA 144G...: SMD		35a(2mm)	SOT-323			-
DTA144T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=47kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	AN 1L4Z, KSR 2012, UN 4110, 2SA1509
DTA 144 TE		Si-P+R	=DTA 144T...: SMD		35a(1,6mm)	SS Mini			-
DTA 144 TK(A)		Si-P+R	=DTA 144T...: SMD		35a(2,9mm)	SOT-23			FN 1L4Z, KSR 2112, UN 2210, 2SA1508
DTA 144 TU(A)		Si-P+R	=DTA 144T...: SMD		35a(2mm)	SOT-323			-
DTA124V(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=47k, Rbe=10kΩ, 50V, 30/100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	UN 411D
DTA 144 VE		Si-P+R	=DTA 144V...: SMD		35a(1,6mm)	SS Mini			-
DTA 144 VK(A)		Si-P+R	=DTA 144V...: SMD		35a(2,9mm)	SOT-23			UN 211D
DTA 144 VU(A)		Si-P+R	=DTA 144V...: SMD		35a(2mm)	SOT-323			-
DTA144W(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=47k, Rbe=22kΩ, 50V, 30/100mA, 0,3W, 250MHz		9c, 41c		(BC 556)[18]	7a	AN 1L4L, RN 2009, UN 411E, 2SA1347,++
DTA 144 WE		Si-P+R	=DTA 144W...: SMD		35a(1,6mm)	SS Mini			-
DTA 144 WK(A)		Si-P+R	=DTA 144W...: SMD		35a(2,9mm)	SOT-23			FN 1L4L, RN 2409, UN 211E, 2SA1343,++
DTA 144 WU(A)		Si-P+R	=DTA 144W...: SMD		35a(2mm)	SOT-323			-
DTB									
DTB 3 B...G	Say	Triac	100...600V, 3A=(Tc=71°), Igt/Ih<30/<25mA B=100V, C=200V, E=400V, G=600V		13j	TO-202			TAG 136-..., TAG 137-...
DTB113E(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=Rbe=1kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				RN 2221
DTB 113 EK		Si-P+R	=DTB 113E...: SMD		35a(2,9mm)	SOT-23			-
DTB113Z(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=1kΩ, Rbe=10kΩ, 50V, 500mA, 0,6W, 200MHz		9c, 41c				RN 2226
DTB 113 ZK		Si-P+R	=DTB 113Z...: SMD		35a(2,9mm)	SOT-23			-
DTB114E(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=Rbe=10kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				RN 2224, UN 4123, 2SA1522, 2SA1526
DTB 114 EK		Si-P+R	=DTB 114E...: SMD		35a(2,9mm)	SOT-23			UN 2123, 2SA1518
DTB114G(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=-, Rbe=10kΩ, 50/50V, 500mA, 0,6W, 200MHz		9c, 41c				-
DTB 114 GK		Si-P+R	=DTB 114G...: SMD		35a(2,9mm)	SOT-23			-
DTB114T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=10kΩ, Rbe=-, 50/40V, 500mA, 0,6W, 200MHz		9c, 41c				-
DTB 114 TK		Si-P+R	=DTB 114T...: SMD		35a(2,9mm)	SOT-23			-
DTB122J(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=220Ω, Rbe=4,7kΩ, 50V, 500mA, 0,6W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				-
DTB 122 JK		Si-P+R	=DTB 122J...: SMD		35a(2,9mm)	SOT-23			-
DTB123E(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=Rbe=2,2kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				RN 2222, UN 4121, 2SA1525, 2SA1529
DTB 123 EK		Si-P+R	=DTB 123E...: SMD		35a(2,9mm)	SOT-23			UN 2121, 2SA1521
DTB123T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=2,2kΩ, Rbe=-, 50/40V, 500mA, 0,6W, 200MHz		9c, 41c				-
DTB 123 TK		Si-P+R	=DTB 123T...: SMD		35a(2,9mm)	SOT-23			-
DTB123Y(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=2,2k, Rbe=10kΩ, 50V, 500mA, 0,6W, 200MHz		9c, 41c				RN 2227, UN 4124, 2SA1524, 2SA1528
DTB 123 YK		Si-P+R	=DTB 123Y...: SMD		35a(2,9mm)	SOT-23			UN 2124, 2SA1520
DTB133H(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=3,3k, Rbe=10kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				-
DTB 133 HK		Si-P+R	=DTB 133Y...: SMD		35a(2,9mm)	SOT-23			-
DTB143E(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=Rbe=4,7kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				RN 1223, UN 4122, 2SA1523, 2SA1527
DTB 143 EK		Si-P+R	=DTB 143E...: SMD		35a(2,9mm)	SOT-23			UN 2122, 2SA1519
DTB143T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=4,7kΩ, Rbe=-, 50/40V, 500mA, 0,6W, 200MHz		9c, 41c				-
DTB 143 TK		Si-P+R	=DTB 143T...: SMD		35a(2,9mm)	SOT-23			-
DTB163T(A,F,L,S,V)	Rhm	Si-P+R	S, Rb=6,8kΩ, Rbe=-, 50/40V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				-
DTB 163 TK		Si-P+R	=DTB 163T...: SMD		35a(2,9mm)	SOT-23			-
DTC									
DTC1D3R(A,F,L,S,V)(A)	Rhm	Si-N+R	S, Rb=2,7k, Rbe=1kΩ, 50V, 70/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTC...(...)A: 100mA Version Serie/Series		9c, 41c				-
DTC 1 D3RE		Si-N+R	=DTC 1D3R...: SMD		35a(1,6mm)	SS Mini			-
DTC 1 D3RK(A)		Si-N+R	=DTC 1D3R...: SMD		35a(2,9mm)	SOT-23			-
DTC 1 D3RU(A)		Si-N+R	=DTC 1D3R...: SMD		35a(2mm)	SOT-323			-
DTC 8 C...G(-N)	Say	Triac	200...600V, 8A=(Tc=105°), Igt/Ih<50/<50mA C=200V, E=400V, G=600V		17j	TO-220			T 2800..., T 2850..., TAG 224-...
DTC 10 C-N...G-N	Say	Triac	200...600V, 10A=(Tc=98°), Igt/Ih<50/<50mA C-N=200V, E-N=400V, G-N=600V		17j	TO-220			BTA 22-..., TAG 250-..., TAG 251-...
DTC 12 C...G(-N)	Say	Triac	200...600V, 12A=(Tc=98°), Igt/Ih<50/<50mA C=200V, E=400V, G=600V		17j	TO-220			BTA23-..., BT138-..., TAG255-..., TAG256-...
DTC113Z(A,F,L,S,V)(A)	Rhm	Si-N+R	S, Rb=1k, Rbe=10kΩ, 50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTC...(...)A: 100mA Version Serie/Series		9c, 41c				AA 1A3Q, UN 4219
DTC 113 ZE		Si-N+R	=DTC 113Z...: SMD		35a(1,6mm)	SS Mini			-
DTC 113 ZK(A)		Si-N+R	=DTC 113Z...: SMD		35a(2,9mm)	SOT-23			FA 1A3Q, UN 2219
DTC 113 ZU(A)		Si-N+R	=DTC 113Z...: SMD		35a(2mm)	SOT-323			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
DTC114E(A,F,L,S,V) (A)	Rhm	Si-N+R	S, Rb=Rbe=10kΩ, 50V, 50/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTC...(...)A: 100mA Version Serie/Series		9c, 41c	(BC 546)[18]	7a	AA 1A4M, RN 1002, UN 4211, 2SC3402,++
DTC 114 EE		Si-N+R	=DTC 114E...: SMD		35a(1,6mm) SS Mini			-
DTC 114 EK(A)		Si-N+R	=DTC 114E...: SMD		35a(2,9mm) SOT-23			FA 1A4M, RN 1402, UN 2211, 2SC3398,++
DTC 114 EU(A)		Si-N+R	=DTC 114E...: SMD		35a(2mm) SOT-323			2SC4398
DTC114G(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=-, Rbe=10kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c	(BC 546)[18]	7a	-
DTC 114 GE		Si-N+R	=DTC 114G...: SMD		35a(1,6mm) SS Mini			-
DTC 114 GK(A)		Si-N+R	=DTC 114G...: SMD		35a(2,9mm) SOT-23			-
DTC 114 GU(A)		Si-N+R	=DTC 114G...: SMD		35a(2mm) SOT-323			-
DTC114T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=10kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c	(BC 546)[18]	7a	AA 1A4Z, RN 1011, UN 4215, 2SC3860,++
DTC 114 TE		Si-N+R	=DTC 114T...: SMD		35a(1,6mm) SS Mini			-
DTC 114 TK(A)		Si-N+R	=DTC 114T...: SMD		35a(2,9mm) SOT-23			FA 1A4Z, RN 1411, UN 2215, 2SC3859,++
DTC 114 TU(A)		Si-N+R	=DTC 114T...: SMD		35a(2mm) SOT-323			-
DTC114W(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=10k, Rbe=4,7kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c	(BC 546)[18]	7a	UN 421K
DTC 114 WE		Si-N+R	=DTC 114W...: SMD		35a(1,6mm) SS Mini			-
DTC 114 WK(A)		Si-N+R	=DTC 114W...: SMD		35a(2,9mm) SOT-23			-
DTC 114 WU(A)		Si-N+R	=DTC 114W...: SMD		35a(2mm) SOT-323			-
DTC114Y(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=10k, Rbe=47kΩ, 50V, 70/100mA, 0,3W, 250MHz		9c, 41c	(BC 546)[18]	7a	AA 1A4P, RN 1007, UN 4214, 2SC4048,++
DTC 114 YE		Si-N+R	=DTC 114Y...: SMD		35a(1,6mm) SS Mini			-
DTC 114 YK(A)		Si-N+R	=DTC 114Y...: SMD		35a(2,9mm) SOT-23			FA 1A4P, RN 1407, UN 2214, 2SC4047,++
DTC 114 YU(A)		Si-N+R	=DTC 114Y...: SMD		35a(2mm) SOT-323			-
DTC115E(A,F,L,S,V) (A)	Rhm	Si-N+R	S, Rb=Rbe=100kΩ, 50V, 20/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTC...(...)A: 100mA Version Serie/Series		9c, 41c			-
DTC 115 EE		Si-N+R	=DTC 115E...: SMD		35a(1,6mm) SS Mini			-
DTC 115 EK(A)		Si-N+R	=DTC 115E...: SMD		35a(2,9mm) SOT-23			-
DTC 115 EU(A)		Si-N+R	=DTC 115E...: SMD		35a(2mm) SOT-323			-
DTC115G(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=-, Rbe=100kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c			-
DTC 115 GE		Si-N+R	=DTC 115G...: SMD		35a(1,6mm) SS Mini			-
DTC 115 GK(A)		Si-N+R	=DTC 115G...: SMD		35a(2,9mm) SOT-23			-
DTC 115 GU(A)		Si-N+R	=DTC 115G...: SMD		35a(2mm) SOT-323			-
DTC115T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=100kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c			-
DTC 115 TE		Si-N+R	=DTC 115T...: SMD		35a(1,6mm) SS Mini			-
DTC 115 TK(A)		Si-N+R	=DTC 115T...: SMD		35a(2,9mm) SOT-23			-
DTC 115 TU(A)		Si-N+R	=DTC 115T...: SMD		35a(2mm) SOT-323			-
DTC115U(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=100k, Rbe=10kΩ, 50V, 20/100mA, 0,3W, 250MHz		9c, 41c			-
DTC 115 UK		Si-N+R	=DTC 115U...: SMD		35a(2,9mm) SOT-23			-
DTC 115 UU		Si-N+R	=DTC 115U...: SMD		35a(2mm) SOT-323			-
DTC123E(A,F,L,S,V) (A)	Rhm	Si-N+R	S, Rb=Rbe=2,2kΩ, 50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTC...(...)A: 100mA Version Serie/Series		9c, 41c			-
DTC 123 EE		Si-N+R	=DTC 123E...: SMD		35a(1,6mm) SS Mini			-
DTC 123 EK(A)		Si-N+R	=DTC 123E...: SMD		35a(2,9mm) SOT-23			-
DTC 123 EU(A)		Si-N+R	=DTC 123E...: SMD		35a(2mm) SOT-323			-
DTC123J(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=2,2k, Rbe=47kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c			RN 1005
DTC 123 JE		Si-N+R	=DTC 123J...: SMD		35a(1,6mm) SS Mini			-
DTC 123 JK(A)		Si-N+R	=DTC 123J...: SMD		35a(2,9mm) SOT-23			BCR 108, RN 1405
DTC 123 JU(A)		Si-N+R	=DTC 123J...: SMD		35a(2mm) SOT-323			-
DTC123Y(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=2,2k, Rbe=10kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c			UN 421H, 2SC3864
DTC 123 YE		Si-N+R	=DTC 123Y...: SMD		35a(1,6mm) SS Mini			-
DTC 123 YK(A)		Si-N+R	=DTC 123Y...: SMD		35a(2,9mm) SOT-23			UN 221H, 2SC3863
DTC 123 YU(A)		Si-N+R	=DTC 123Y...: SMD		35a(2mm) SOT-323			2SC4498
DTC124E(A,F,L,S,V) (A)	Rhm	Si-N+R	S, Rb=Rbe=22kΩ, 50V, 30/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTC...(...)A: 100mA Version Serie/Series		9c, 41c	(BC 546)[18]	7a	AA 1F4M, RN 1003, UN 4212, 2SC3400,++
DTC 124 EE		Si-N+R	=DTC 124E...: SMD		35a(1,6mm) SS Mini			-
DTC 124 EK(A)		Si-N+R	=DTC 124E...: SMD		35a(2,9mm) SOT-23			FA 1F4M, RN 1403, UN2212, 2SC3396,++
DTC 124 EU(A)		Si-N+R	=DTC 124E...: SMD		35a(2mm) SOT-323			2SC4397
DTC124G(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=-, Rbe=22kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c	(BC 546)[18]	7a	2SC4070
DTC 124 GE		Si-N+R	=DTC 124G...: SMD		35a(1,6mm) SS Mini			-
DTC 124 GK(A)		Si-N+R	=DTC 124G...: SMD		35a(2,9mm) SOT-23			2SC4069
DTC 124 GU(A)		Si-N+R	=DTC 124G...: SMD		35a(2mm) SOT-323			-
DTC124T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=22kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c	(BC 546)[18]	7a	AA 1F4Z, KSR 1011, UN 4217, 2SC4121,++
DTC 124 TE		Si-N+R	=DTC 124T...: SMD		35a(1,6mm) SS Mini			-
DTC 124 TK(A)		Si-N+R	=DTC 124T...: SMD		35a(2,9mm) SOT-23			FA 1F4Z, KSR 1111, UN 2217, 2SC4120
DTC 124 TU(A)		Si-N+R	=DTC 124T...: SMD		35a(2mm) SOT-323			-
DTC124X(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=22k, Rbe=47kΩ, 50V, 100mA, 0,3W, 250MHz		9c, 41c	(BC 546)[18]	7a	AA 1F4N, KSR 1007, RN 1008
DTC 124 XE		Si-N+R	=DTC 124X...: SMD		35a(1,6mm) SS Mini			-
DTC 124 XK(A)		Si-N+R	=DTC 124X...: SMD		35a(2,9mm) SOT-23			FA 1F4N, KSR 1107, RN 1408
DTC 124 XU(A)		Si-N+R	=DTC 124X...: SMD		35a(2mm) SOT-323			-
DTC125T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=200kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c			-
DTC 125 TK		Si-N+R	=DTC 125T...: SMD		35a(2,9mm) SOT-23			-
DTC 125 TU		Si-N+R	=DTC 125T...: SMD		35a(2mm) SOT-323			-
DTC143E(A,F,L,S,V) (A)	Rhm	Si-N+R	S, Rb=4,7k, Rbe=4,7kΩ, 50V, 100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTC...(...)A: 100mA Version Serie/Series		9c, 41c			AA 1L3M, RN 1001, UN 421L, 2SC4363,++
DTC 143 EE		Si-N+R	=DTC 143E...: SMD		35a(1,6mm) SS Mini			-
DTC 143 EK(A)		Si-N+R	=DTC 143E...: SMD		35a(2,9mm) SOT-23			FA 1L3M, RN 1401, UN 221L, 2SC5362,++
DTC 143 EU(A)		Si-N+R	=DTC 143E...: SMD		35a(2mm) SOT-323			-
DTC143T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=4,7kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c			AA 1L3Z, RN 1010, UN 4216, 2SC3901,++
DTC 143 TE		Si-N+R	=DTC 143T...: SMD		35a(1,6mm) SS Mini			-
DTC 143 TK(A)		Si-N+R	=DTC 143T...: SMD		35a(2,9mm) SOT-23			FA 1L3Z, RN 1410, UN 2216, 2SC3900,++
DTC 143 TU(A)		Si-N+R	=DTC 143T...: SMD		35a(2mm) SOT-323			-
DTC143X(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=4,7k, Rbe=10kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c			AA 1L3N, KSR 1005, UN 421F, 2SC4361
DTC 143 XE		Si-N+R	=DTC 143X...: SMD		35a(1,6mm) SS Mini			-
DTC 143 XK(A)		Si-N+R	=DTC 143X...: SMD		35a(2,9mm) SOT-23			FA 1L3N, UN 221F, 2SC4360
DTC 143 XU(A)		Si-N+R	=DTC 143X...: SMD		35a(2mm) SOT-323			-
DTC143Z(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=4,7k, Rbe=47kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c			RN 1006, 2SC4133, 2SC4195
DTC 143 ZE		Si-N+R	=DTC 143Z...: SMD		35a(1,6mm) SS Mini			-
DTC 143 ZK(A)		Si-N+R	=DTC 143Z...: SMD		35a(2,9mm) SOT-23			RN 1406, 2SC4146
DTC 143 ZU(A)		Si-N+R	=DTC 143Z...: SMD		35a(2mm) SOT-323			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DTC144E(A,F,L,S,V) (A)	Rhm	Si-N+R	S, Rb=Rbe=47kΩ, 50V, 30/100mA, 0,3W, 250MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c DTC...(...)A: 100mA Version Serie/Series		9c, 41c				AA 1L4M, RN 1004, UN 4213, 2SC3399,++
DTC 144 EE		Si-N+R	=DTC 144E...: SMD		35a(1,6mm)	SS Mini			-
DTC 144 EK(A)		Si-N+R	=DTC 144E...: SMD		35a(2,9mm)	SOT-23			FA 1L4M, RN 1404, UN 2213, 2SC3395,++
DTC 144 EU(A)		Si-N+R	=DTC 144E...: SMD		35a(2mm)	SOT-323			2SC4396
DTC144G(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=-, Rbe=47kΩ, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c				2SC4067
DTC 144 GE		Si-N+R	=DTC 144G...: SMD		35a(1,6mm)	SS Mini			-
DTC 144 GK(A)		Si-N+R	=DTC 144G...: SMD		35a(2,9mm)	SOT-23			2SC4066
DTC 144 GU(A)		Si-N+R	=DTC 144G...: SMD		35a(2mm)	SOT-323			-
DTC144T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=47kΩ, Rbe=-, 50/50V, 100mA, 0,3W, 250MHz		9c, 41c				AA 1L4Z, KSR 1012, UN 4210, 2SC3899
DTC 144 TE		Si-N+R	=DTC 144T...: SMD		35a(1,6mm)	SS Mini			-
DTC 144 TK(A)		Si-N+R	=DTC 144T...: SMD		35a(2,9mm)	SOT-23			FA 1L4Z, KSR 1112, UN 2210, 2SC3898
DTC 144 TU(A)		Si-N+R	=DTC 144T...: SMD		35a(2mm)	SOT-323			FA 1L4Z, KSR 1112, UN 2210, 2SC3898
DTC144V(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=47k, Rbe=10kΩ, 50V, 30/100mA, 0,3W, 250MHz		9c, 41c				UN 421D
DTC 144 VE		Si-N+R	=DTC 144V...: SMD		35a(1,6mm)	SS Mini			-
DTC 144 VK(A)		Si-N+R	=DTC 144V...: SMD		35a(2,9mm)	SOT-23			UN 221D
DTC 144 VU(A)		Si-N+R	=DTC 144V...: SMD		35a(2mm)	SOT-323			-
DTC144W(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=47k, Rbe=22kΩ, 50V, 30/100mA, 0,3W, 250MHz		9c, 41c				AA 1L4L, RN 1009, UN 421E, 2SC3401,++
DTC 144 WE		Si-N+R	=DTC 144W...: SMD		35a(1,6mm)	SS Mini			-
DTC 144 WK(A)		Si-N+R	=DTC 144W...: SMD		35a(2,9mm)	SOT-23			FA 1L4L, RN 1409, UN 221E, 2SC3397,++
DTC 144 WU(A)		Si-N+R	=DTC 144W...: SMD		35a(2mm)	SOT-323			-
DTC314T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=10kΩ, Rbe=-, 30/15V, 600mA, 0,3W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				DTD 114T...
DTC 314 TK		Si-N+R	=DTC 314T...: SMD		35a(2,9mm)	SOT-23			DTD 114TK
DTC323T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=2,2kΩ, Rbe=-, 30/15V, 600mA, 0,3W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				DTD 123T...
DTC 323 TK		Si-N+R	=DTC 323T...: SMD		35a(2,9mm)	SOT-23			DTD 123TK
DTC343T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=4,7kΩ, Rbe=-, 30/15V, 600mA, 0,3W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				DTD 143T...
DTC 343 TK		Si-N+R	=DTC 343T...: SMD		35a(2,9mm)	SOT-23			DTD 143TK
DTC363E(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=Rbe=6,8kΩ, 20V, 600mA, 0,3W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				2SD1676
DTC 363 EK		Si-N+R	=DTC 363E...: SMD		35a(2,9mm)	SOT-23			-
DTC363T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=6,8kΩ, Rbe=-, 30/15V, 600mA, 0,3W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				DTD 163T...
DTC 363 TK		Si-N+R	=DTC 363T...: SMD		35a(2,9mm)	SOT-23			DTD 163TK
DTD									
DTD113E(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=Rbe=1kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				RN 1221
DTD 113 EK		Si-N+R	=DTD 113E...: SMD		35a(2,9mm)	SOT-23			-
DTD113Z(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=1kΩ, Rbe=10kΩ, 50V, 500mA, 0,6W, 200MHz		9c, 41c				RN 1226
DTD 113 ZK		Si-N+R	=DTD 113Z...: SMD		35a(2,9mm)	SOT-23			-
DTD114E(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=Rbe=10kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				RN 1224, UN 4223, 2SC3916, 2SC 3920
DTD 114 EK		Si-N+R	=DTD 114E...: SMD		35a(2,9mm)	SOT-23			UN 2223, 2SC3912
DTD114G(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=-, Rbe=10kΩ, 50/50V, 500mA, 0,6W, 200MHz		9c, 41c				-
DTD 114 GK		Si-N+R	=DTD 114G...: SMD		35a(2,9mm)	SOT-23			-
DTD114T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=10kΩ, Rbe=-, 50/40V, 500mA, 0,6W, 200MHz		9c, 41c				DTC 314T...
DTD 114 TK		Si-N+R	=DTD 114T...: SMD		35a(2,9mm)	SOT-23			DTC 314TK
DTD122J(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=220Ω, Rbe=4,7kΩ, 50V, 500mA, 0,6W, 250MHz		9c, 41c				-
DTD 122 JK		Si-N+R	=DTD 122J...: SMD		35a(2,9mm)	SOT-23			-
DTD123E(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=Rbe=2,2kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				RN 1222, UN 4221, 2SC3919, 2SC 3923
DTD 123 EK		Si-N+R	=DTD 123E...: SMD		35a(2,9mm)	SOT-23			UN 2221, 2SC3915
DTD123T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=2,2kΩ, Rbe=-, 50/40V, 500mA, 0,6W, 200MHz		9c, 41c				DTC 323T...
DTD 123 TK		Si-N+R	=DTD 123T...: SMD		35a(2,9mm)	SOT-23			DTC 323TK
DTD123Y(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=2,2k, Rbe=10kΩ, 50V, 500mA, 0,6W, 200MHz		9c, 41c				RN 1227, UN 4224, 2SC3918, 2SC3922
DTD 123 YK		Si-N+R	=DTD 123Y...: SMD		35a(2,9mm)	SOT-23			UN 2224, 2SC3914
DTD133H(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=3,3k, Rbe=10kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				-
DTD 133 HK		Si-N+R	=DTD 133H...: SMD		35a(2,9mm)	SOT-23			-
DTD143E(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=Rbe=4,7kΩ, 50V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				RN 1223, UN 4222, 2SC3917, 2SC 3921
DTD 143 EK		Si-N+R	=DTD 143E...: SMD		35a(2,9mm)	SOT-23			UN 2222, 2SC3913
DTD143T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=4,7kΩ, Rbe=-, 50/40V, 500mA, 0,6W, 200MHz		9c, 41c				DTC 343T...
DTD 143 TK		Si-N+R	=DTD 143T...: SMD		35a(2,9mm)	SOT-23			DTC 343TK
DTD163T(A,F,L,S,V)	Rhm	Si-N+R	S, Rb=6,8kΩ, Rbe=-, 50/40V, 500mA, 0,6W, 200MHz A,F,L,V(ATR,FTR,FTL,ATV): Fig.9c, S(SPT): Fig.41c		9c, 41c				DTC 363T...
DTD 163 TK		Si-N+R	=DTD 163T...: SMD		35a(2,9mm)	SOT-23			DTC 363TK
DTE....DV									
DTE 16 E	Say	Triac	400V, 16A=(Tc=75°), Igt/Ih<80/=30mA		65I				MAC 515A-..., MAC 525A-...
DTF 16 C...G	Say	Triac	200...600V, 16A=(Tc=78°), Igt/Ih<50/<50mA C=200V, E=400V, G=600V		65I				MAC 515(A)-..., MAC 525(A)-...
DTI 2222	Itt	NMOS-IC	CTV, Color Processor		40-DIP				-
DTI 2223	Itt	NMOS-IC	CTV, digital Color Processor		40-DIP		DTI 2223	40-DIP	-
DTM 6 C...G(-N)	Say	Triac	200...600V, 6A=(Tc=70°), Igt/Ih<50/<50mA C=200V, E=400V, G=600V		17I	SOT-186			TAG 420-... (MAC 216-..., T 2500...)[3]
DTM 8 C...G(-N)	Say	Triac	200...600V, 8A=(Tc=83°), Igt/Ih<50/<50mA C=200V, E=400V, G=600V		17I	SOT-186			TAG425-..., TAG451-..., (T2800..., T2850...)[3]
DTM 10 C-N...G-N	Say	Triac	200...600V, 10A=(Tc=83°), Igt/Ih<50/<50mA C-N=200V, E-N=400V, G-N=600V		17I	SOT-186			TAG 456-..., TAG 457-..., (BTA 22-...)[3]
DTM 12 C...G(-N)	Say	Triac	200...600V, 12A=(Tc=73°), Igt/Ih<50/<50mA C=200V, E=400V, G=600V		17I	SOT-186			TAG480-..., TAG481-...,(BTA23-...,BT138-...)[3]
DTP		Si-N	=2SD2391-P (SMD-Marking)		39	SOT-89			›2SD2391
DTQ		Si-N	=2SD2391-Q (SMD-Marking)		39	SOT-89			›2SD2391
DTS 401	Del	Si-N	TV-VA, -/400V, 2A, 75W(Tc=75°)		23a	TO-3	BUW 11 A	18j	2SC1101, 2SC3151, 2SC3533
DTS 402	Del	Si-N	TV-HA, 700/400V, 3,5A, 100W(Tc=75°)		23a	TO-3	BUW 11 A	18j	BU 706, 2SC3484, 2SD1098, 2SD1495,++
DTS 403	Del	Si-N	S P, 400/400V, 3,5A, 100W(Tc=75°)		23a	TO-3	(BUW 11A)	18j	BUW 71, BUX 45, TIP 54, 2SC3083,++
DTS 409	Del	Si-N	S P, 400/400V, 3,5A, 100W(Tc=75°)		23a	TO-3	(BUW 11A)	18j	BUW 71, BUX 45, TIP 54, 2SC3083,++
DTS 410	Del	Si-N	S P, 200/200V, 3,5A, 100W(Tc=75°), 250/750ns		23a	TO-3	(BUW 11A)	18j	BUW 71, BUX 16(A...C), 2SC2908, 2SD1018++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
DTS 411	Del	Si-N	S P, 300/300V, 3,5A, 100W(Tc=75°), 250/750ns		23a	TO-3	(BUW 11A)	18j	BUW 71, BUX 16A...C, TIP 52, 2SC4799,++
DTS 413	Del	Si-N	S P, -/400V, 2A, 75W(Tc=75°), 250/750ns		23a	TO-3	(BUW 11A)	18j	BUX 46(A), BUX 82, 2SC3151, 2SC3533,++
DTV 32-1000A	Tho	Si-Di	CRT-HA, Damper-Di, 1000/1000V, 3A, <72ns		31a	DO-27A	(BYW 96 E)	31a	BYT 56M, (BYW 96E)
DTV 32-1200A	Tho	Si-Di	CRT-HA, Damper-Di, 1000/1200V, 6A(Tc=130°), <600ns		17k	TO-220	BY 329/1200	17k	BY 329/1200, BY 359/1500
DTV 32-1500A		Si-Di	=DTV 32-1200A: 1350/1500V		17k	TO-220	BY 359/1500	17k	BY 359/1500
DTV 32(F)-...B		Si-Di	=DTV 32(F)-...: <175ns		17k	TO-220			-
DTV 32F-...		Si-Di	=DTV 32-...: Iso		17d	TO-220 Iso			-
DTV 64-1200C	Tho	Si-Di	CRT-HA, Damper-Di, 1000/1200V, 6A(Tc=130°), <600ns		17k	TO-220			-
DTV 64F-1200C		Si-Di	=DTV 64-1200C: Iso		17d	TO-220 Iso			-
2.0...36...	Rhm	Z-Di	SMD, 2.0...36V, 0.2W		71(1,7mm)	SOD-323			HZU ..., RD ...S
DU		GaAs-N-FET-d	=3SK241 (SMD-Marking)		44	SOT-143			›3SK241
DU		GaAs-N-FET-d	=3SK272 (SMD-Marking)		44(2mm)	SOT-343			›3SK272
DU		Si-P	=BCW 67RB (SMD-Marking)		35	SOT-23			›BCW 67RB
DU		Si-P	=HQ 1F2Q (SMD-Marking)		39	SOT-89			›HQ 1...
DV 1		Si-N	=2SD596-DV1 (SMD-Marking)		35	SOT-23			›2SD596
DV 2		Si-N	=2SD596-DV2 (SMD-Marking)		35	SOT-23			›2SD596
DV 3		Si-N	=2SD596-DV3 (SMD-Marking)		35	SOT-23			›2SD596
DV 4		Si-N	=2SD596-DV4 (SMD-Marking)		35	SOT-23			›2SD596
DV 5		Si-N	=2SD596-DV5 (SMD-Marking)		35	SOT-23			›2SD596
DV 07	Fui	Hybrid-IC	Kabeltreiber/Cable Driver						-
DV 08	Fui	Hybrid-IC	Kabeltreiber/Cable Driver						-
DV 24	Fui	Hybrid-IC	Hammertreiber/Hammer Driver						-
DVP		Si-N	=2SC4755-P (SMD-Marking)		35(2mm)	SOT-323			›2SC4755
DVP		Si-N	=2SC4782-P (SMD-Marking)		35	SOT-23			›2SC4782
DVQ		Si-N	=2SC4755-Q (SMD-Marking)		35(2mm)	SOT-323			›2SC4755
DVQ		Si-N	=2SC4782-Q (SMD-Marking)		35	SOT-23			›2SC4782
DVR		Si-N	=2SC4755-R (SMD-Marking)		35(2mm)	SOT-323			›2SC4755
DVR		Si-N	=2SC4782-R (SMD-Marking)		35	SOT-23			›2SC4782
DW									
DW		Si-P	=BCW 67RC (SMD-Marking)		35	SOT-23			›BCW 67RC
DW		Z-Di	=SM 6T 15 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
DW 1		Si-N	=2SD780-DW1 (SMD-Marking)		35	SOT-23			›2SD780
DW 2		Si-N	=2SD780-DW2 (SMD-Marking)		35	SOT-23			›2SD780
DW 3		Si-N	=2SD780-DW3 (SMD-Marking)		35	SOT-23			›2SD780
DW 4		Si-N	=2SD780-DW4 (SMD-Marking)		35	SOT-23			›2SD780
DW 5		Si-N	=2SD780-DW5 (SMD-Marking)		35	SOT-23			›2SD780
DW 542/....		Si-Di	≈SKE 4F2/04				SKE 4F2/06	33a	›SKE 4F2/04
DW 6089		Si-P	≈BC 154		8a	TO-106	BC 560	7a	›BC 154
DW 6170		Si-N	≈BC 237		8a	TO-106	BC 546	7a	›BC 237
DW 6208		Si-N	≈BC 237		8a	TO-106	BC 546	7a	›BC 237
DW 6335		Si-N	≈BC 237		8a	TO-106	BC 546	7a	›BC 237
DW 6577		Si-N	≈BF 199		8a	TO-106	BF 199	7d	›BF 199
DW 6618		Si-N	≈BC 337		8a	TO-106	BC 337	7a	›BC 337
DW 6619		Si-P	≈BC 327		8a	TO-106	BC 327	7a	›BC 327
DW 6737		Si-N	≈BC 237		2a	TO-106	BC 546	7a	›BC 237
DW 6969		Si-P	≈BC 307		2a	TO-106	BC 556	7a	›BC 307
DW 7000		Si-N	≈BF 198		2a	TO-106	BF 198	7d	›BF 198
DW 7035		Si-N	≈BC 237		8a	TO-106	BC 546	7a	›BC 237
DW 7039		Si-N	≈BSX 24		2a	TO-105	BF 259	2a	›BSX 24
DW 7050		Si-N	≈BF 199		8a	TO-106	BF 199	7d	›BF 199
DW 7975		Si-P	≈BC 154		8a	TO-106	BC 560	7a	›BC 154
DX....DZ									
DX		Si-P	=BCW 68RF (SMD-Marking)		35	SOT-23			›BCW 68RF
DX		Si-P	=HQ 1A4A (SMD-Marking)		39	SOT-89			›HQ 1...
DX		Z-Di	=SM 6T 15A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
DX 0038 CE		Si-Di	≈RGP 30M				BYW 96 E	31a	›RGP 30M
DX 0048 CE		Si-Di	≈1N4148				1N4148	31a	›1N4148
DX 0055 CE		Si-Di	≈RGP 30M				BYW 96 E	31a	›RGP 30M
DX 0073 CE		Si-Di	≈BA 159				BA 159	31a	›BA 159
DX 0081 TA		Si-Di	≈RGP 30A...M				RGP 30 M	31a	›RGP 30A...M
DX 0086 TA		Si-Di	≈RGP 30G...M				RGP 30 M	31a	›RGP 30G...M
DX 0101 CE		Si-Di	≈BA 157				BA 159	31a	›BA 157...159
DX 0107 TA		Si-Br	Br Rr		33		B380C5000	33	B380C2200, etc.
DX 0113 TA		Si-Di	≈BA 176				BA 159	31a	›BA 176
DX 0115 CE		Si-Di	≈RGP 30M				BYW 96 E	31a	›RGP 30M
DX 0117 TA		Si-Di	≈RGP 30M				RGP 30 M	31a	›RGP 30M
DX 0118 CE		Si-Br	Br Rr		33		B40C3700	33	B40C3300, etc.
DX 0124 TA		Si-Di	≈BY 255				BY 255	31a	›BY 255
DX 0125 CE		Si-Di	≈RGP 30M				BYD 33 M	31a	›RGP 30M
DX 0128 CE		Si-Di	≈RGP 30M		31a		BYW 96 E	31a	›RGP 30M
DY		Si-P	=2SA1201-Y (SMD-Marking)		39	SOT-89			›2SA1201
DY		Si-P	=2SA1620-Y (SMD-Marking)		35	SOT-23			›2SA1620
DY		Si-N	=2SC3397 (SMD-Marking)		35	SOT-23			›2SC3397
DY		Si-P	=BCW 68RG (SMD-Marking)		35	SOT-23			›BCW 68RG
DY		Si-P	=KTA1661-Y (SMD-Marking)		39	SOT-89			›KTA 1661
DZ....		Z-Di			31a		Z-Diode V	31a	
DZ		Si-P	=BCW 68RH (SMD-Marking)		35	SOT-23			›BCW 68RH
DZ		Si-N	=XN 4505 (SMD-Marking)		46	SOT-163			›XN 4505
DZB 6.2...30(C)	Say	Z-Di	6,2...30V, ±10%, C=±5%, 1W		31a	DO-15	Z-Diode V	31a	BZW 22/..., BZX 61/..., BZX 85/..., ZPY...,+
DZD 2.0...24(X,Y,Z)	Say	Z-Di	SMD, 2,0...24V, ±5%, X=-5...0%, Y=±2,5%, Z=0...+5%		35p	SOT-23			BZX 84/...
E									
E		Si-P	=2SA1688 (SMD-Marking)		35	SOT-23			›2SA1688
E 1		Si-P	=2SA1737 (SMD-Marking)		39	SOT-89			›2SA1737
E 1(p)		Si-N	=BFS 17 (SMD-Marking)		35	SOT-23			›BFS 17
E 1		Si-N	=BFS 17W (SMD-Marking)		35(2mm)	SOT-323			›BFS 17W
E 2		Si-P	=2SA1226-2 (SMD-Marking)		35	SOT-23			›2SA1226
E 2		Si-Di	=BAL 99 (SMD-Marking)		35	SOT-23			›BAL 99
E 2(p)		Si-N	=BFS 17A (SMD-Marking)		35	SOT-23			›BFS 17A
E 3		Si-Di	=1SS190 (SMD-Marking)		35	SOT-23			›1SS190

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
E 3		Si-P	=2SA1226-3 (SMD-Marking)		35	SOT-23			›2SA1226
E 3		Si-P	=2SA1256-3 (SMD-Marking)		35	SOT-23			›2SA1256
E 3		Si-Di	=BAR 99 (SMD-Marking)		35	SOT-23			›BAR 99
E 4		Si-P	=2SA1226-4 (SMD-Marking)		35	SOT-23			›2SA1226
E 4		Si-P	=2SA1256-4 (SMD-Marking)		35	SOT-23			›2SA1256
E 4		Si-N	=BFS 17R (SMD-Marking)		35	SOT-23			›BFS 17R
E 5		Si-P	=2SA1256-5 (SMD-Marking)		35	SOT-23			›2SA1256
E 5		Si-N	=BFS 17AR (SMD-Marking)		35	SOT-23			›BFS 17AR
E 6		Si-Di	=ZC 2800E (SMD-Marking)		35	SOT-23			›ZC 2800E
E 7		Si-Di	=ZC 2810E (SMD-Marking)		35	SOT-23			›ZC 2810E
E 8		Si-Di	=ZC 2811E (SMD-Marking)		35	SOT-23			›ZC 2811E
E 9		Si-Di	=ZC 5800E (SMD-Marking)		35	SOT-23			›ZC 5800E
E 15		Si-P	=BF 747 (SMD-Marking)		35	SOT-23			›BF 747
E 16		Si-N	=BF 547W: (SMD-Marking)		35(2mm)	SOT-323			›BF 547W
E 21		N-FET	=2SK932-21 (SMD-Marking)		35	SOT-23			›2SK932
E 22		N-FET	=2SK932-22 (SMD-Marking)		35	SOT-23			›2SK932
E 23		N-FET	=2SK932-23 (SMD-Marking)		35	SOT-23			›2SK932
E 24		N-FET	=2SK932-24 (SMD-Marking)		35	SOT-23			›2SK932
E 100 C,D	Hfo	TTL-Logic	=... 8400 (TTL)		14-DIC,DIP				... 8400... (TTL)
E 0100 AD	Tag	F-Thy	100V, 0,5A(Tc=40°C), 0,8A=, Igt/Ih<0,02/=5mA		2a	TO-18			-
E 0100 FD		F-Thy	=E 0100AD: 60V		2a	TO-18			-
E 0100 YD		F-Thy	=E 0100AD: 30V		2a	TO-18			-
E 0102 AA	Tag	F-Thy	100V, 0,5A(Tc=40°C), 0,8A=, Igt/Ih=0,2/5mA		7n	TO-92	BRX 49	7a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 FA		F-Thy	=E 0102AA: 60V		7n	TO-92	BRX 49	7a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 YA		F-Thy	=E 0102AA: 30V		7n	TO-92	BRX 49	7a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 AB	Tag	F-Thy	100V, 0,5A(Tc=40°C), 0,8A=, Igt/Ih=0,2/5mA		7a	SOT-30	BRX 49	7a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 FB		F-Thy	=E 0102AB: 60V		7a	SOT-30	BRX 49	7a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 YB		F-Thy	=E 0102AB: 30V		7a	SOT-30	BRX 49	7a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 AD	Tag	F-Thy	100V, 0,5A(Tc=40°C), 0,8A=, Igt/Ih=0,2/5mA		2a	TO-18	TAG 103 X	2a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 FD		F-Thy	=E 0102AD: 60V		2a	TO-18	TAG 103 X	2a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 YD		F-Thy	=E 0102AD: 30V		2a	TO-18	TAG 103 X	2a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 AG	Tag	F-Thy	100V, 0,65A(Tc=85°C), 1A=, Igt/Ih=0,2/5mA		2a	TO-39	TAG 103 X	2a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 FG		F-Thy	=E 0102AG: 60V		2a	TO-39	TAG 103 X	2a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 YG(9004)		F-Thy	=E 0102AG: 30V		2a	TO-39	TAG 103 X	2a	BRX 46...47, BRX 51...52, TAG 62...
E 0102 YB	Tag	F-Thy	=BR 103		7a	SOT-30	BRX 49	7a	›BR 103
E 103 C,D	Hfo	TTL-Logic	=... 8403 (TTL)		14-DIC,DIP				... 8403... (TTL)
E 104 C,D	Hfo	TTL-Logic	=... 8404 (TTL)		14-DIC,DIP				... 8404... (TTL)
E 108 C,D	Hfo	TTL-Logic	=... 8408 (TTL)		14-DIC,DIP				... 8408... (TTL)
E 110 C,D	Hfo	TTL-Logic	=... 8410 (TTL)		14-DIC,DIP				... 8410... (TTL)
E 120 C,D	Hfo	TTL-Logic	=... 8420 (TTL)		14-DIC,DIP				... 8420... (TTL)
E 121 C,D	Hfo	TTL-Logic	=... 84121 (TTL)		14-DIC,DIP				... 84121... (TTL)
E 126 C,D	Hfo	TTL-Logic	=... 8426 (TTL)		14-DIC,DIP				... 8426... (TTL)
E 130 C,D	Hfo	TTL-Logic	=... 8430 (TTL)		14-DIC,DIP				... 8430... (TTL)
E 140 C,D	Hfo	TTL-Logic	=... 8440 (TTL)		14-DIC,DIP				... 8440... (TTL)
E 146 C,D	Hfo	TTL-Logic	=... 8446 (TTL)		16-DIC,DIP				... 8446... (TTL)
E 147 C,D	Hfo	TTL-Logic	=... 8447 (TTL)		16-DIC,DIP				... 8447... (TTL)
E 150 C,D	Hfo	TTL-Logic	=... 8450 (TTL)		14-DIC,DIP				... 8450... (TTL)
E 151 C,D	Hfo	TTL-Logic	=... 8451 (TTL)		14-DIC,DIP				... 8451... (TTL)
E 153 C,D	Hfo	TTL-Logic	=... 8453 (TTL)		14-DIC,DIP				... 8453... (TTL)
E 154 C,D	Hfo	TTL-Logic	=... 8454 (TTL)		14-DIC,DIP				... 8454... (TTL)
E 160 C,D	Hfo	TTL-Logic	=... 8460 (TTL)		14-DIC,DIP				... 8460... (TTL)
E 172 C,D	Hfo	TTL-Logic	=... 8472 (TTL)		14-DIC,DIP				... 8472... (TTL)
E 174 C,D	Hfo	TTL-Logic	=... 8474 (TTL)		14-DIC,DIP				... 8474... (TTL)
E 175 C,D	Hfo	TTL-Logic	=... 8475 (TTL)		16-DIC,DIP				... 8475... (TTL)
E 181 C,D	Hfo	TTL-Logic	=... 8481 (TTL)		14-DIC,DIP				... 8481... (TTL)
E 191 C,D	Hfo	TTL-Logic	=... 8491 (TTL)		14-DIC,DIP				... 8491... (TTL)
E 192 C,D	Hfo	TTL-Logic	=... 84192 (TTL)		16-DIC,DIP				... 84192... (TTL)
E 193 C,D	Hfo	TTL-Logic	=... 84193 (TTL)		16-DIC,DIP				... 84193... (TTL)
E 195 C,D	Hfo	TTL-Logic	=... 8495 (TTL)		14-DIC,DIP				... 8495... (TTL)
E 204 C,D	Hfo	TTL-Logic	=... 84H04 (TTL)		14-DIC,DIP				... 84H04... (TTL)
E 274 D	Hfo	TTL-Logic	=... 84H74 (TTL)		14-DIP				... 84H74... (TTL)
E 300	Nsc,Six	N-FET	HF, 25V, Idss=6...30mA, Up=1...6V		8b	TO-106	(BF 245)	7f	BF 256B...C, BF 348, BFT 10A, 2N5397
E 304	Nsc,Six	N-FET	VHF, 30V, Idss=5...15mA, Up=2...6V		8b	TO-106			BFS 80, BFW 11, 2N4416, 2N5245
E 305	Nsc,Six	N-FET	=E 304: Idss=1...8mA, Up=0,5...3V		8b	TO-106			2N5457, 2SK246, 2SK330
E 308	Nsc	N-FET	VHF, 25V, Idss=12...60mA, Up=1...6,5V		8b	TO-106			BFT 10B...C, 2SK125
E 309	Nsc	N-FET	=E 308: Idss=12...30mA, Up=1...4V		8b	TO-106			-
E 310	Nsc	N-FET	=E 308: Idss=24...60m, Up=2...6,5V		8b	TO-106			BFT 10C, 2SK125
E 310 D	Hfo	LIN-IC	Kfz-Blinkgeber/Car Blinking Generator		16-DIP				-
E 311	Nsc	N-FET	=E 308: Idss<30mA, Up<4V		8b	TO-106			-
E 312	Nsc	N-FET	=E 308: Idss<60mA, Up<6,5V		8b	TO-106			BFT 10C, 2SK125
E 345 D	Hfo	TTL-Logic	=D 345D: -25...+85°		16-DIP				-
E 346 D	Hfo	TTL-Logic	=D 346D: -25...+85°		16-DIP				-
E 347 D	Hfo	TTL-Logic	=D 347D: -25...+85°		16-DIP				84LS247 (TTL)
E 348 D	Hfo	TTL-Logic	=D 348D: -25...+85°		16-DIP				84LS247 (TTL)
E 351 D	Hfo	TTL-Logic	=D 351D: -25...+85°		14-DIP				-
E 355 D	Hfo	TTL-Logic	=D 355D: -25...+85°		18-DIP				-
E 356 D	Hfo	TTL-Logic	=D 356D: -25...+85°		18-DIP				-
E 412 D	Hfo	LIN-IC	3x AND-Gate, Treiber/Driver, Tri-State Out		18-DIP				-
E 435 E	Hfo	LIN-IC	Leistungstreiber/Power Driver						(FZL 135S)
E 1007	Aeg	LIN-IC	=TEA 1007		8-DIP				›TEA 1007
E 1156/1201		MOS-IC	Analogarmbanduhr/Analogic Watch		Chip				U 117(X)
E 1617		Si-N	=BD 115		2a	TO-39	BF 259	2a	›BD 115
E 1694		Si-P	=BC 143		2a		BC 161	2a	›BC 143
E 5429		UJT			7d	TO-92			BSV 57B
E 5565		N-FET	=MPF 111		7e	TO-92	BF 245	7f	›MPF 111
E 6008		Si-P	=BC 154				BC 560	7a	›BC 154
E 7133		Si-P	=BF 506				BF 324	7a	›BF 506
E 7134		Si-P	=BF 969				BF 979(S)	24e	›BF 969
E 7140		MOS-N-FET-d	=BF 960		25g		BF 960	25g	›BF 960
E 7142		Si-P	=BF 506						›BF 506
E 7150		Si-P	=BF 970				BF 979(S)	24e	›BF 970
E 7359		MOS-N-FET-d	=BF 966		25g		BF 960	25g	›BF 966
E 7606		Ge-Di	=2x AA 119				2x AA 119	31a	›AA 119

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
E:		Si-P	=2SA1688 (SMD-Marking)		35	SOT-23			›2SA1688
EA....EC									
EA		Si-P/N	=µPA504T (SMD-Marking)		45	SOT-153			›µPA504T
EA		Si-P/N	=µPA574T (SMD-Marking)		45(2mm)	SOT-353			›µPA574T
EA		Si-P	=2SA1022-A (SMD-Marking)		35	SOT-23			›2SA1022
EA		Si-P	=2SA1532-A (SMD-Marking)		35(2mm)	SOT-323			›2SA1532
EA		Si-P	=2SA1790-A (SMD-Marking)		35(1,6mm)	SS Mini			›2SA1790
EA		Si-N	=2SD1420-EA (SMD-Marking)		39	SOT-89			›2SD1420
EA(s)		Si-N	=BCW 65A (SMD-Marking)		35	SOT-23			›BCW 65A
EA		Si-N	=HC 2A4A (SMD-Marking)		39	SOT-89			›HC 2...
EA 961		Si-P	≈2SB681		23a	TO-3	2SA1294	18j	›2SB681
EA 7316	Tos	MOS-IC	Digitaluhr/Digital Clock						-
EA 7317 B	Tos	MOS-IC	Digitaluhr/Digital Clock & Datum/Date						-
EB		Si-P	=2SA1022-B (SMD-Marking)		35	SOT-23			›2SA1022
EB		Si-P	=2SA1532-B (SMD-Marking)		35(2mm)	SOT-323			›2SA1532
EB		Si-P	=2SA1790-B (SMD-Marking)		35(1,6mm)	SS Mini			›2SA1790
EB		Si-P	=2SA1888-B (SMD-Marking)		≈35	(T Mini)			›2SA1888
EB		Si-N	=2SD1420-EB (SMD-Marking)		39	SOT-89			›2SD1420
EB(s)		Si-N	=BCW 65B (SMD-Marking)		35	SOT-23			›BCW 65B
EB P		N-FET	=2SK1842-P: (SMD-Marking)		35	SOT-23			›2SK1842
EB Q		N-FET	=2SK1842-Q: (SMD-Marking)		35	SOT-23			›2SK1842
EB R		N-FET	=2SK1842-R: (SMD-Marking)		35	SOT-23			›2SK1842
EB S		N-FET	=2SK1842-S: (SMD-Marking)		35	SOT-23			›2SK1842
EC		Si-P	=2SA1022-C (SMD-Marking)		35	SOT-23			›2SA1022
EC		Si-P	=2SA1368-C (SMD-Marking)		39	SOT-89			›2SA1368
EC		Si-P	=2SA1532-C (SMD-Marking)		35(2mm)	SOT-323			›2SA1532
EC		Si-P	=2SA1790-C (SMD-Marking)		35(1,6mm)	SS Mini			›2SA1790
EC		Si-P	=2SA1888-C (SMD-Marking)		≈35	(T Mini)			›2SA1888
EC		Si-N	=2SC2732 (SMD-Marking)		35	SOT-23			›2SC2732
EC		Si-N	=2SC4462 (SMD-Marking)		35(2mm)	SOT-323			›2SC4422
EC		Si-N	=2SD1420-EC (SMD-Marking)		39	SOT-89			›2SD1420
EC		MOS-N-FET-d	=3SK247 (SMD-Marking)		44	SOT-143			›3SK247
EC(s)		Si-N	=BCW 65C (SMD-Marking)		35	SOT-23			›BCW 65C
EC 961		Si-N	≈2SD551		23a	TO-3	2SC3263	18j	›2SD551
ECO 0100....9999	Ntn	Si-Di, Z-Di	›0100....9999				›0100....9999		
ED									
ED		Si-P	=2SA1368-D (SMD-Marking)		39	SOT-89			›2SA1368
ED		Si-N	=2SD1421-ED (SMD-Marking)		39	SOT-89			›2SD1421
ED		Si-P	=BCV 28 (SMD-Marking)		39	SOT-89			›BCV 28
ED		Z-Di	=SM 6T 18 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
ED		Si-N/P	=XP 4654 (SMD-Marking)		46(2mm)	SOT-363			›XP 4654
ED 592		Si-N	=BF 254		7d	TO-92	BF 255	7d	›BF 254
ED 1401(A....E)	Nsc	Si-N	≈TED 1402		7e	TO-92	›ED 1402		›TED 1402
ED 1402(A....E)	Nsc	Si-N	≈TED 1402		7e	TO-92	›TED 1402		›TED 1402
ED 1501(A....E)	Nsc	Si-N	≈TED 1502		7e	TO-92	›TED 1502		›TED 1502
ED 1502(A....E)	Nsc	Si-N	≈TED 1502		7e	TO-92	›TED 1502		›TED 1502
ED 1601(A....E)	Nsc	Si-P	≈TED 1602		7e	TO-92	›TED 1602		›TED 1602
ED 1602(A....E)	Nsc	Si-P	≈TED 1602		7e	TO-92	›TED 1602		›TED 1602
ED 1701(K....N)	Nsc	Si-N	≈TED 1702		7e	TO-92	›TED 1702		›TED 1702
ED 1702(K....N)	Nsc	Si-N	≈TED 1702		7e	TO-92	›TED 1702		›TED 1702
ED 1801(K....N)	Nsc	Si-P	≈TED 1802		7e	TO-92	›TED 1802		›TED 1802
ED 1802(K....N)	Nsc	Si-P	≈TED 1802		7e	TO-92	›TED 1802		›TED 1802
ED 2502		Si-N	=BF 255		7a	TO-92	BF 255	7d	›BF 255
ED 8050		Si-N	=SS 8050	{ED8550	7e	TO-92	›SS 8050		›SS 8050
ED 8550		Si-P	=SS 8550	{ED8050	7e	TO-92	›SS 8550		›SS 8550
EE		Si-P	=2SA1368-E (SMD-Marking)		39	SOT-89			›2SA1368
EE		Si-N	=2SD1421-EE (SMD-Marking)		39	SOT-89			›2SD1421
EE		Si-P	=BCV 48 (SMD-Marking)		39	SOT-89			›BCV 48
EE		Z-Di	=SM 6T 18A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
EF									
EF		Si-N	=BCV 29 (SMD-Marking)		39	SOT-89			›BCV 29
EF(s)		Si-N	=BCW 66F (SMD-Marking)		35	SOT-23			›BCW 66F
EF 68HC...	Tho	µC-IC	µComp, Serie 6800...						-
EF 4440	Tho	NMOS-IC	µComp, Peripherie Interface (ARINC)		28-DIP				-
EF 4442	Tho	NMOS-IC	µComp, Peripherie(ARINC) f.6800,6802µC		28-DIP				-
EF 4443 DP	Tho	NMOS-IC	Drehzahlregler/Motor Speed Control		16-DIP				-
EF 6800....6854	Tho	µC-IC	µComp, Serie 6800..., Peripherie etc.						-
EF 6843	Tho	I/O-IC	Floppy Disk Controller		40-DIP				-
EF 6844	Tho	I/O-IC	DMA Controller, 1MByte/s, 4 Channel		40-DIP				-
EF 6845	Tho	I/O-IC	CRT Controller, 1MByte/s, 4 Channel		40-DIP				-
EF 6846(C1)	Tho	MOS-IC	Combo Chip, 2k ROM, Timer		40-DIP				-
EF 6862	Tho	I/O-IC	Digital Modulator, ser., 1200/2400bps		24-DIP				-
EF 7331	Tho	NMOS-IC	Telecom, Zeitmatrix, Register etc.		28-DIP				-
EF 7332	Tho	NMOS-IC	Telecom, Taktgenerierung/Clock Generator, 2,048MHz		16-DIP				-
EF 7333	Tho	NMOS-IC	Telecom, Communication, 2,048MHz		24-DIP				-
EF 7442	Tho	NMOS-IC	Telecom, Zeibasis/Time Base, Multiplexer		16-DIP				-
EF 7445	Tho	NMOS-IC	Telecom, Encoder/Decoder Controller		24-DIP				-
EF 7910	Tho	NMOS-IC	Telecom, Modem, AMD 7910 kompatibel/compatible		28-DIP				-
EF 8307	Tho	A/D-IC	Telecom, A/D Converter, 7 Bit, 20MHz		24-DIP				-
EF 8308	Tho	A/D-IC	Telecom, A/D Converter, 8 Bit, 20MHz		24-DIP				-
EF 8408	Tho	D/A-IC	Telecom, A/D Converter, 8 Bit, 20MHz		16-DIP				-
EF 9241	Tho	NMOS-IC	Demultiplexer (CEEFAX, DIDON, ANTIOPE)		40-DIP				-
EF 9340	Tho	MOS-IC	Semigraphic Display Processor		40-DIP				-
EF 9341	Tho	MOS-IC	Zeichengenerator/Character Generator		40-DIP				-
EF 9345 FN	Tho	MOS-IC	=EF 9345P:		44-PLCC				-
EF 9345 P	Tho	HMOS-IC	Semigraphic Display Processor		40-DIP				-
EF 9364 A	Tho	I/O-IC	Video Controller, 50Hz/625 Zeilen/Lines		24-DIP				-
EF 9364 B	Tho	I/O-IC	=EF 9364A: 60Hz/525 Zeilen/Lines		24-DIP				-
EF 9365	Tho	MOS-IC	Graphic Display Processor		40-DIP				-
EF 9366	Tho	MOS-IC	Graphic Display Processor		40-DIP				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
EF 9367 P, P3	Tho	MOS-IC	Graphic Display Processor		40-DIP				-
EF 9368	Tho	MOS-IC	Graphic Display Processor		64-FLP				-
EF 9369 FN	Tho	MOS-IC	=EF 9369P:		28-PLCC				-
EF 9369 P	Tho	MOS-IC	Color Palette Decoder		28-DIP				-
EF 68000....68901	Tho	µC-IC	µComp, Serie 6800..., Peripherie etc.						-
EF 84108	Tho	D/A-IC	Telecom, A/D Converter, 8 Bit, 5MHz		16-DIP				-
EFB 4443	Tho	NMOS-IC	Drehzahlregler/Motor Speed Control		16-DIP				-
EFB 7189	Tho	CMOS-IC	Telecom, Frequ.-Generator, µComp. Interface		16-DIP				-
EFB 7303	Tho	CMOS-IC	Telecom, ser./par. Converter, 8/8 Bit		16-DIP				-
EFB 7310	Tho	CMOS-IC	Telecom, 4x4x1 Matrix f. analog Signal		16-DIP				-
EFB 7334	Tho	CMOS-IC	Telecom, Demultiplexer f. 8x EF7331, EF7333		24-DIP				-
EFB 7335	Tho	CMOS-IC	Telecom, 1 Kanal/Channel Signalling Controller		24-DIP				-
EFB 7336	Tho	CMOS-IC	Telecom, 8-Kanal/Channel Controller		22-DIP				-
EFB 7356	Tho	CMOS-IC	Telecom, 1 Kanal/Channel Codec		16-DIP				-
EFB 7360	Tho	CMOS-IC	Telecom, 1 Kanal/Channel Codec, Filter		16/18-DIP				-
EFB 7441	Tho	CMOS-IC	Telecom, Zeitbasis/Time Base, Multiplexer		28-DIP				-
EFB 7443	Tho	CMOS-IC	Telecom, Encoder, TMS 3863 kompatibel/compatible		28-DIP				-
EFB 7444	Tho	CMOS-IC	Telecom, Decoder, A-Law		28-DIP				-
EFB 7446	Tho	CMOS-IC	Telecom, Binary ‣ HDB3 Transcoder		16-DIP				-
EFB 7447	Tho	CMOS-IC	Telecom, 1/16-Multiplexer		28-DIP				-
EFB 7510	Tho	CMOS-IC	Telecom, FSK-Modem, 75/1200Baud, V.23		18-DIP				-
EFB 7512	Tho	CMOS-IC	Telecom, FSK-Modem, 75/1200Baud, V.23		22-DIP				-
EFB 7513	Tho	CMOS-IC	Telecom, FSK-Modem, 75/1200Baud, V.23		22-DIP				-
EFB 7910	Tho	NMOS-IC	Telecom, FSK-Modem, CCITT, Bell		28-DIP				-
EFB 7912	Tho	CMOS-IC	Telecom, Filter f. 1 Kanal/Channel Codec		16-DIP				-
EFB 8305 A	Tho	CMOS-IC	Telecom, Programm. Timer		16-DIP				-
EFB 9151	Tho	CMOS-IC	Telecom, Tastwahl/Key Dialing		18-DIP				-
EFB 9158	Tho	CMOS-IC	Telecom, Tastwahl/Key Dialing		22-DIP				-
EFD 108		Ge-Di	=SFD 108		31a		AA 133	31a	‣SFD 108
EFD 7130	Tho	PMOS-IC	Telecom, Telefonnummernbeschränkung, Number Limit.		28-DIP				-
EFG 0	Tho	CMOS-IC	Gate-Arrays, kundenspezifisch/customized		28-DIP				-
EFG 850 XY	Tho	CMOS-IC	Telecom, Switched Capacitor Filter		8/16-DIP				-
EFG 7189(PD)	Tho	CMOS-IC	Telecom, DTMF, ser. Interface		14-DIP				-
EFG 7515	Tho	CMOS-IC	Telecom, DPSK-Modem, V.22, Bell 212A		28-DIP				-
EFG 71891(PD)	Tho	CMOS-IC	Telecom, DTMF, par. Interface		8-DIP				-
EFV 1		Si-Di	=BY 228		31a		BY 228	31a	‣BY 228
EFZ	Tho	ECL/TTL-IC	Gate-Arrays, kundenspezifisch/customized						-
EG....EK									
EG		Si-N	=BCV 49 (SMD-Marking)		39	SOT-89			‣BCV 49
EG(s)		Si-N	=BCW 66G (SMD-Marking)		35	SOT-23			‣BCW 66G
EG 01	Sak	Si-Di	FRr, 400V, 0,7A, Uf<2V(0,7A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26B...E, BYV 36B...E, RGP 10G...M,++
EG 01 A	Sak	Si-Di	FRr, 600V, 0,5A, Uf<2V(0,5A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26C...E, BYV 36C...E, RGP 10J...M,++
EG 01 C	Sak	Si-Di	FRr, 1000V, 0,5A, Uf<3,3V(0,5A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26E, BYV 36E, BYT 52M, RGP 10M,++
EG 01 Y	Sak	Si-Di	FRr, 70V, 1A, Uf<1,2V(1A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26B...E, BYV 36A...E, RGP 10A...M,++
EG 01 Z	Sak	Si-Di	FRr, 200V, 0,7A, Uf<1,9V(0,7A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26B...E, BYV 36A...E, RGP 10D...M,++
EG 1	Sak	Si-Di	FRr, 400V, 0,8A, Uf<1,2V(0,8A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26B...E, BYV 36B...E, RGP 10G...M,++
EG 1 A	Sak	Si-Di	FRr, 600V, 0,6A, Uf<2V(0,6A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26C...E, BYV 36C...E, RGP 10J...M,++
EG 1 Y	Sak	Si-Di	FRr, 70V, 1,1A, Uf<1,2V(1,1A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26B...E, BYV 36A...E, RGP 10A...M,++
EG 1 Z	Sak	Si-Di	FRr, 200V, 0,8A, Uf<1,7V(0,8A), 100ns		31a	SOD-22	BYD 33 M	31a	BYV 26B...E, BYV 36A...E, RGP 10D...M,++
EGL 27 A...G	Gie	Si-Di	=BYM 32/....						‣BYM 32/...
EGL 34 A...G	Gie	Si-Di	=BYM 07/....						‣BYM 07/...
EGL 41 A...G	Gie	Si-Di	=BYM 12/....						‣BYM 12/...
EGP 10 A....G	Gie	Si-Di	FRr, 50...400V, 1A, Uf<0,95V(1A), <50ns A=50, B=100, C=150, D=200, F=300, G=400V		31a	DO-41	BYV 27/200 f. EGP 10A...D	31a	BYV 26B...E, FE 1A...D
EGP 20 A....G	Gie	Si-Di	FRr, 50...400V, 2A, Uf<0,95V(2A), <50ns A=50, B=100, C=150, D=200, F=300, G=400V		31a	DO-15	BYV 27/200 f. EGP 20A...D	31a	BYD 74A...G, BYV 27/..., FE 2A...D
EGP 30 A....G	Gie	Si-Di	FRr, 50...400V, 3A, Uf<0,95V(3A), <50ns A=50, B=100, C=150, D=200, F=300, G=400V		31a	DO-27A	BYV 28/200 f. EGP 30A...D	31a	BYV 28/..., FE 3A...D
EGP 50 A....G	Gie	Si-Di	FRr, 50...400V, 5A, Uf<0,95V(5A), <50ns A=50, B=100, C=150, D=200, F=300, G=400V		31a	DO-27A			BYV 61...63, FE 5A...D, FE 6A...D
EH		Si-P	=2SB1027-EH (SMD-Marking)		39	SOT-89			‣2SB1027
EH(s)		Si-N	=BCW 66H (SMD-Marking)		35	SOT-23			‣BCW 66H
EH		Z-Di	=SM 6T 22 (SMD-Marking)		71a(6x4mm)	SOD-6			‣SM 6T....
EH 1(A,Z)	Sak	Si-Di	Rr, 200...600V, 0,6A, Uf<1,35V(0,6A), 4µs EH 1=400V, A=600V, Z=200V		31a	SOD-22	1N4007	31a	BY 126...127, BY 133...134, 1N4003...07,++
EHD-RD 3053 N,NA	Mat	Hybrid-Z-IC	-5V, 1A						-
EHD-RD 3053 PA	Mat	Hybrid-Z-IC	+5V, 1A						-
EHD-RD 3053 R,RA	Mat	Hybrid-Z-IC	+5V, 1A						-
EHD-RD 3053 S	Mat	Hybrid-Z-IC	+5V, 1A						-
EHD-RD 3053 V	Mat	Hybrid-Z-IC	+5V, 3A						-
EHD-RD 3093 PA	Mat	Hybrid-Z-IC	+9V, 1A						-
EHD-RD 3093 R,RA	Mat	Hybrid-Z-IC	+9V, 1A						-
EHD-RD 3093 S	Mat	Hybrid-Z-IC	+9V, 1A						-
EHD-RD 3123 N,NA	Mat	Hybrid-Z-IC	-12V, 1A						-
EHD-RD 3123 PA	Mat	Hybrid-Z-IC	+12V, 1A						-
EHD-RD 3123 R,RA	Mat	Hybrid-Z-IC	+12V, 1A						-
EHD-RD 3123 S	Mat	Hybrid-Z-IC	+12V, 1A						-
EHD-RD 3123 V	Mat	Hybrid-Z-IC	+12V, 3A						-
EHD-RD 3153 N,NA	Mat	Hybrid-Z-IC	-15V, 1A						-
EHD-RD 3153 PA	Mat	Hybrid-Z-IC	+15V, 1A						-
EHD-RD 3153 R,RA	Mat	Hybrid-Z-IC	+15V, 1A						-
EHD-RD 3153 S	Mat	Hybrid-Z-IC	+15V, 1A						-
EHD-RD 3183 PA	Mat	Hybrid-Z-IC	+18V, 1A						-
EHD-RD 3183 R,RA	Mat	Hybrid-Z-IC	+18V, 1A						-
EHD-RD 3183 S	Mat	Hybrid-Z-IC	+18V, 1A						-
EHD-RD 3243 N,NA	Mat	Hybrid-Z-IC	-24V, 1A						-
EHD-RD 3243 PA	Mat	Hybrid-Z-IC	+24V, 1A						-
EHD-RD 3243 R,RA	Mat	Hybrid-Z-IC	+24V, 1A						-
EHD-RD 3243 S	Mat	Hybrid-Z-IC	+24V, 1A						-
EI		MOS-N-FET-d	=3SK182 (SMD-Marking)		44	SOT-143			‣3SK182
EI		Si-P+R	=UN 211M (SMD-Marking)		35	SOT-23			‣UN 211M
EI		Si-P+R	=UN 511M (SMD-Marking)		35(2mm)	SOT-323			‣UN 511M

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
EJ		Si-P	=2SB1027-EJ (SMD-Marking)	39	SOT-89			›2SB1027
EJ 4		N-FET	=3SK181-4 (SMD-Marking)	44	SOT-143			›3SK181
EJ 5		N-FET	=3SK181-5 (SMD-Marking)	44	SOT-143			›3SK181
EJ 6		N-FET	=3SK181-6 (SMD-Marking)	44	SOT-143			›3SK181
EJ 5027		Si-N	=2N3055	23a	TO-3	2N3055	23a	›2N3055
EK		Si-P	=2SB1027-EK (SMD-Marking)	39	SOT-89			›2SB1027
EK		Si-N	=2SD1001-EK (SMD-Marking)	39	SOT-89			›2SD1001
EK(s)		Si-N	=BCX 41 (SMD-Marking)	35	SOT-23			›BCX 41
EK		Z-Di	=SM 6T 22A (SMD-Marking)	71a(6x4mm)	SOD-6			›SM 6T....
EK		Si-P+R	=XN 111M (SMD-Marking)	45	SOT-153			›XN 111M
EK 03	Sak	Si-Di	Schottky FRr, 30V, 1A, Uf<0,55V(1,5A), 200ns	31a	SOD-22	1N5822	31a	BYV 10-30, SB 130...160, 1N5818...19
EK 04	Sak	Si-Di	Schottky FRr, 40V, 1A, Uf<0,55V(1,5A), 200ns	31a	SOD-22	1N5822	31a	BYS 21-45, BYV 10-40, SB140...160, 1N5819
EK 06	Sak	Si-Di	Schottky FRr, 60V, 0,7A, Uf<0,62V(0,7A), 100ns	31a	SOD-22			BYS 21-90, BYV 10-60, SB 160, MBR 160
EK 09	Sak	Si-Di	Schottky FRr, 90V, 0,7A, Uf<0,81V(0,7A), 100ns	31a	SOD-22			BYS 21-90, HRP 32
EK 13	Sak	Si-Di	Schottky, FRr, 30V, 1,5A, Uf<0,55V(2A), 200ns	31a	SOD-22	1N5822	31a	BYS 22-45, BYS 26-45, 1N5821...22
EK 14	Sak	Si-Di	Schottky, FRr, 40V, 1,5A, Uf<0,55V(2A), 200ns	31a	SOD-22	1N5822	31a	BYS 22-45, BYS 26-45, 1N5822
EK 16	Sak	Si-Di	Schottky, FRr, 60V, 1,5A, Uf<0,62V(1,5A), 100ns	31a	SOD-22			BYS 22-90, BYS 26-90, HRP 34, MBR 360
EK 19	Sak	Si-Di	Schottky, FRr, 90V, 1,5A, Uf<0,81V(1,5A), 100ns	31a	SOD-22			BYS 22-90, BYS 26-90
EL								
EL		Si-P	=2SA1344 (SMD-Marking)	35	SOT-23			›2SA1344
EL		Si-P	=2SA1678 (SMD-Marking)	35(2mm)	SOT-323			›2SA1678
EL		Si-P	=2SB1028-EL (SMD-Marking)	39	SOT-89			›2SB1028
EL		Si-N	=2SD1001-EL (SMD-Marking)	39	SOT-89			›2SD1001
EL		Z-Di	=SM 6T 24 (SMD-Marking)	71a(6x4mm)	SOD-6			›SM 6T....
EL		Si-N+R	=UN 221M (SMD-Marking)	35	SOT-23			›UN 221M
EL		Si-N+R	=UN 521M (SMD-Marking)	35(2mm)	SOT-323			›UN 521M
EL 1 Z	Sak	Si-Di	FRr, 200V, 1,5A, Uf<0,98V(1,5A), 50ns	31a	SOD-22	BYV 27/200	31a	BYD 73D...G, EGP 10D, FE 1D
EL 133		N-FET	=BF 245	7f	TO-92	BF 245	7f	›BF 245
EL 220/7128		Si-N	=2N3856			BC 546	7a	›2N3856
EL 692		Si-P	=BC 393			MPS-U60	13m	›BC 393
EM								
EM		Si-P	=2SB1028-EM (SMD-Marking)	39	SOT-89			›2SB1028
EM		Si-N	=2SD1001-EM (SMD-Marking)	39	SOT-89			›2SD1001
EM		Z-Di	=SM 6T 24A (SMD-Marking)	71a(6x4mm)	SOD-6			›SM 6T....
EM		Si-N+R	=XN 121M (SMD-Marking)	45	SOT-153			›XN 121M
EM 01(A,Y,Z)	Sak	Si-Di	Rr, 100...600V, 1A, Uf<0,97V(1A) EM 01=400V, A=600V, Y=100V, Z=200V	31a	SOD-22	1N4007	31a	BY 126...127, BY 133...134, 1N4002...07,++
EM 1(A,B,C,Y,Z)	Sak	Si-Di	Rr, 100...1000V, 1A, Uf<0,97V(1A) EM 1=400V, A=600V, B=800V, C=1000V, Y=100V, Z=200V	31a	SOD-22	1N4007	31a	BY 126...127, BY 133...134, 1N4002...07,++
EM 2(A,B)	Sak	Si-Di	Rr, 400...800V, 1,2A, Uf<0,92V(1,2A) EM 2=400V, A=600V, B=800V	31a	SOD-22	BYD 33 M	31a	BY 226...227, BYW 53...56, GP 15G...M,++
EM 502	Itt	Si-Di	=1N4003	31a	DO-15	1N4007	31a	›1N4003
EM 504	Itt	Si-Di	=1N4004	31a	DO-15	1N4007	31a	›1N4004
EM 506	Itt	Si-Di	=1N4005	31a	DO-15	1N4007	31a	›1N4005
EM 508	Itt	Si-Di	=1N4006	31a	DO-15	1N4007	31a	›1N4006
EM 510	Itt	Si-Di	=1N4007	31a	DO-15	1N4007	31a	›1N4007
EM 513	Itt,Tho	Si-Di	=1N4007: Itt: 1300V, Tho: 1600V	31a	DO-15	BY 228	31a	BY 228, BY 231/1500, DM 513, GP 10Y
EM 516	Itt	Si-Di	=1N4007: Itt: 1600V, Tho: 1800V	31a	DO-15	(BY 228)[7]	31a	RGP 15-18, (BY 228, DM 516, GP 10Y)[7]
EN								
EN		Z-Di	=SM 6T 27 (SMD-Marking)	71a(6x4mm)	SOD-6			›SM 6T....
EN		Si-N	=XN 4506 (SMD-Marking)	46	SOT-163			›XN 4506
EN 697	Fch,Nsc	Si-N	=2N697: 0,3W	8a	TO-106			›2N697
EN 706	Fch	Si-N	=2N706: 0,2W	8a	TO-106			›2N706
EN 708	Fch	Si-N	=2N708: 0,2W	8a	TO-106			›2N708
EN 718 A	Fch	Si-N	=2N718A: 0,22W	8a	TO-106			›2N718 A
EN 722	Fch,Nsc	Si-P	=2N722: 0,2W	8a	TO-106			›2N722
EN 744	Fch	Si-N	=2N744: 0,2W	8a	TO-106			›2N744
EN 870	Fch	Si-N	=2N870: 0,22W	8a	TO-106			›2N870
EN 871	Fch	Si-N	=2N871: 0,22W	8a	TO-106			›2N871
EN 914	Fch	Si-N	=2N914: 0,2W	8a	TO-106			›2N914
EN 915	Fch	Si-N	=2N915: 0,2W	8a	TO-106			›2N915
EN 916	Fch	Si-N	=2N916: 0,2W	8a	TO-106			›2N916
EN 918	Fch,Nsc	Si-N	=2N918: 0,2W	8a	TO-106			›2N918
EN 930	Fch,Nsc,Mic	Si-N	=2N930: 0,2W	8a	TO-106			›2N930
EN 956	Fch,Nsc	Si-N	=2N956: 0,22W	8a	TO-106			›2N956
EN 1132	Fch,Nsc	Si-P	=2N1132: 0,3W	8a	TO-105			›2N1132
EN 1613	Fch	Si-N	=2N1613: 0,3W	8a	TO-105			›2N1613
EN 1711	Fch	Si-N	=2N1711: 0,3W	8a	TO-105			›2N1711
EN 2218	Fch	Si-N	=2N2218: 0,35W	8a	TO-105			›2N2218
EN 2219	Fch	Si-N	=2N2219: 0,35W	8a	TO-105			›2N2219
EN 2221	Fch	Si-N	=2N2221: 0,2W	8a	TO-106			›2N2221
EN 2222	Fch,Nsc	Si-N	=2N2222: 0,2W	8a	TO-106			›2N2222
EN 2369 A	Fch	Si-N	=2N2369A: 0,2W	8a	TO-106			›2N2369A
EN 2484	Fch,Nsc	Si-N	=2N2484: 0,2W	8a	TO-106			›2N2484
EN 2894 A	Fch	Si-P	=2N2894A: 0,2W	8a	TO-106			›2N2894A
EN 2904	Fch	Si-P	=2N2904: 0,3W	8a	TO-105			›2N2904
EN 2905	Fch,Nsc	Si-P	=2N2905: 0,3W	8a	TO-105			›2N2905
EN 2906	Fch	Si-P	=2N2906: 0,2W	8a	TO-106			›2N2906
EN 2907	Fch,Nsc	Si-P	=2N2907: 0,2W	8a	TO-106			›2N2907
EN 3009	Fch	Si-N	=2N3009: 0,2W	8a	TO-106			›2N3009
EN 3011	Fch	Si-N	=2N3011: 0,2W	8a	TO-106			›2N3011
EN 3013	Fch	Si-N	=2N3013: 0,2W	8a	TO-106			›2N3013
EN 3014	Fch	Si-N	=2N3014: 0,2W	8a	TO-106			›2N3014
EN 3250	Fch	Si-P	=2N3250: 0,2W	8a	TO-106			›2N3250
EN 3502	Fch,Nsc	Si-P	=2N3502: 0,3W	8a	TO-105			›2N3502
EN 3504	Fch,Nsc	Si-P	=2N3504: 0,2W	8a	TO-106			›2N3504
EN 3903	Fch	Si-N	=2N3903: 0,31W	8a	TO-106			›2N3903
EN 3904	Fch	Si-N	=2N3904: 0,31W	8a	TO-106			›2N3904
EN 3905	Fch	Si-P	=2N3905: 0,31W	8a	TO-106			›2N3905
EN 3906	Fch	Si-P	=2N3906: 0,31W	8a	TO-106			›2N3906

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
EN 3962	Fch	Si-P	=2N3962: 0,2W		8a	TO-106			›2N3962
EN 4123	Fch	Si-N	=2N4123: 0,2W		8a	TO-106			›2N4123
EN 4124	Fch	Si-N	=2N4124: 0,2W		8a	TO-106			›2N4124
EN 4125	Fch	Si-P	=2N4125: 0,2W		8a	TO-106			›2N4125
EN 4126	Fch	Si-P	=2N4126: 0,2W		8a	TO-106			›2N4126
EN 5172	Fch	Si-N	=2N5172: 0,2W		8a	TO-106			›2N5172
EO		Si-N	=2SC2882-O (SMD-Marking)		39	SOT-89			›2SC2882
EO		Si-N	=2SC3265-O (SMD-Marking)		35	SOT-23			›2SC3265
EO		Si-N	=2SC5097-O (SMD-Marking)		44	SOT-143			›2SC5097
EO		Si-N	=KTC4374-O (SMD-Marking)		39	SOT-89			›KTC 4374
EP		Si-P	=2SB789A-P (SMD-Marking)		39	SOT-89			›2SB789A
EP		Z-Di	=SM 6T 27A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
EP		Si-N	=XN 4556 (SMD-Marking)		46	SOT-163			›XN 4556
EP 01 C	Sak	Si-Di	FRr, 1000V, 0,2A, Uf<4V(0,2A), 200ns		31a	SOD-22	BA 159	31a	BA 159, BYT 11/1000, BYT 52M, BYV 26E
EQ									
EQ		Si-P	=2SB789A-Q (SMD-Marking)		39	SOT-89			›2SB789A
EQ		Z-Di	=SM 6T 30 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
EQ		N-FET	=XP 1D874 (SMD-Marking)		45(2mm)	SOT-353			›XP 1D874
EQA 01-05....-35	Fjd	Z-Di	5...35V, 0,5W		31a	SOD-22	Z-Diode V	31a	BZX55/..., BZX83/..., ZPD..., 1N5231...58,++
EQB 01-05....-35	Fjd	Z-Di	5...35V, 1W		31a	(7,5x4mmØ)	Z-Diode V	31a	BZW22/..., BZX61/..., ZPY..., 1N5918...38,++
ER									
ER 0082		EAROM-IC	128x1 Bit		18-DIP				MN 1213
ER		Si-P	=2SB789A-R (SMD-Marking)		39	SOT-89			›2SB789A
ER		Si-N	=2SC5097-R (SMD-Marking)		44	SOT-143			›2SC5097
ER		Z-Di	=SM 6T 30A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
ER		Si-N/P	=XP 4683 (SMD-Marking)		46(2mm)	SOT-363			›XP 4683
ER 900	Tra	Diac	=BDW 32		31l				A 9903, D 32
ER 1400	Gie	EAROM-IC	100x14 Bit		14-DIP				M5G1400, PCB 1400
ERB 06-13	Aeg,Sie	Si-Di	TV-Rr, 1300, 1A, Uf<1,5V(4A), <4µs		31a	DO-15	BY 228	31a	BY 231/1400, BY 350/1300, BY 400, ++
ERB 12-01....-10		Si-Di	Rr, Uni, 100...1000V, 1A		31a		1N4007	31a	BY 126...127, BY 133...135, 1N4002...07, ++
ERB 24-04C....06C		Si-Di	FRr, 400...600V, 1A, <700ns		31a		BYD 33 M	31a	BYX 55/600, MR 814...818, RGP 10G...M, ++
ERB 24-04D....06D		Si-Di	FRr, 400...600V, 0,7A, <1µs		31a		BYD 33 M	31a	BYX 55/600, MR 814...818, RGP 10G...M, ++
ERC 01-06	Aeg,Sie	Si-Di	Rr, Uni, 600V, 1,5A, Uf<1,1V(4A)		31a	(7,5x6mmØ)	BYD 33 M	31a	BYD 13J...M, BY 227...227, GP 15J...M, ++
ERC 01-10		Si-Di	=ERC 01-06: 1000V		31a		BYD 33 M	31a	BYD 13M, BY 227, GP 15M, RGP 15M, ++
ERC 05-08	Aeg,Sie	Si-Di	Rr, Uni, 800V, 1,2A, Uf<1V(4A)		31a	(7,5x4mmØ)	BYD 33 M	31a	BYD 13K...M, BY 227, GP 15K...M, ++
ERC 06-13	Aeg,Sie	Si-Di	Rr, Uni, 1300V, 1,5A, Uf<1,5V(4A), <4µs		31a	(7,5x6mmØ)	BY 228	31a	BY 231/1400, BY 350/1300, BY 400, ++
ERC 06-15		Si-Di	=ERC 06-13: 1500V		31a	(7,5x6mmØ)	BY 228	31a	BY 231/1500, BY 350/1500, BY 448, ++
ERD 29-06	Aeg,Sie	Si-Di	TV-Rr, 600, 2,5A, <400ns		31a	(10x7,5Ø)	BYW 95 C	31a	BYW 14/600, BYW 95C, RGP 30J...M, ++
ES									
ES		Si-P	=2SA1745 (SMD-Marking)		35(2mm)	SOT-323			›2SA1745
ES		Si-P	=2SA1753 (SMD-Marking)		35	SOT-23			›2SA1753
ES		Si-P	=2SB789A-S (SMD-Marking)		39	SOT-89			›2SB789A
ES		Si-N+Di	=2SD1974 (SMD-Marking)		39	SOT-89			›2SD1974
ES		Si-N	=BCX 41R (SMD-Marking)		35	SOT-23			›BCX 41R
ES		Z-Di	=SM 6T 33 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
ES 1,01(A,Z)	Sak	Si-Di	Rr, 200...600V, 0,7A, Uf<2,5V(0,8A), 1,5µs ES 1,01=400V, A=600V, Z=200V		31a	SOD-22	1N4007	31a	BY 126...127, BY 133...134, 1N4003...07,++
ES 1 F	Sak	Si-Di	FRr, 1500V, 0,5A, Uf<2V(0,5A), <400ns		31a	SOD-22	BY 228	31a	BY 269, BY 231/1500, RGP 15-16
ESAB 01-....		Si-Di	Dual, 100V, 1,5A				2x 1N4007	31a	
ESAB 03-....		Si-Br					B250C1500	8	
ESK 1/....		Si-Di			27c		BY 255	31a	
ESM									
ESM 22-100...600(N)	Tho	Triac	100...600V, 2,5A=(Tc=75°), Igt/Ih<40/<30mA		2m	TO-39			T 2303..., TAG 208-...
ESM 23-100....600	Tho	Triac	100...600V, 6A=(Tc=75°), Igt<80mA		22m	TO-66			TAG 260-..., TAG 265-..., T 4700...
ESM 28	Tho	Si-N	LF P, 30/30V, 4A, 25W, 3MHz	{ESM29	17j	TO-220	BD 243 C	17j	BD 243, BD 533, BD 539, BD 947, ++
ESM 29	Tho	Si-P	LF P, 30/30V, 4A, 25W, 3MHz	{ESM28	17j	TO-220	BD 244 C	17j	BD 244, BD 534, BD 540, BD 948, ++
ESM 168	Tho	LIN-IC	Prellschutz-Flipflop/Chatter Supressor, 3...30V		5	TO-72			-
ESM 188M/450....750	Tho	F-Thy	TV-HA, 450...750V, 5A=(Tc=60°), Igt<60mA, <2,7µs		22a	TO-66	17088[1] *	17f	S 3703..., (BStCC01...H, TD3F...H)[1]
ESM 189M/450....750	Tho	F-Thy	TV-HA, 450...750V, 5A=(Tc=60°), Igt<60mA, <5µs		22a	TO-66	17089[1] *	17f	S 6080C..., (BStCC01...R, TD3F...R)[1]
ESM 206 EV	Tho	CMOS-IC	Schrittmotorsteuerung/Stepper Motor Control, 4 Ph.		14-DIP				-
ESM 217	Tho	Si-N-Darl	LF P, 60/60V, 10A, 70W, >4MHz, hFE>1000	{ESM261	17j	TO-220	BDW 93 C	17j	BDT 63(A...C), BDW 93A...C, BDX 33A...D, ++
ESM 218	Tho	Si-N-Darl	=ESM 217: 80/80V	{ESM262	17j	TO-220	BDW 93 C	17j	BDT 63A...C, BDW 93B...C, BDX 33B...D, ++
ESM 222 R	Tho	LIN-IC	=TDA 1042: profess. Version		23/8Pin	=TO-3			-
ESM 227(A)	Tho	LIN-IC	Motorregler/Speed Ctrl., 3,8...18V, 1,8A		14-QIP				UL 1901
ESM 227 N	Tho	LIN-IC	=ESM 227: Fig. ›		14-QIP+d				-
ESM 228M/450....750	Tho	F-Thy+Di	TV-HA, 450...750V, 5A, Igt<60mA, <2,7µs		22a	TO-66	17088*	17f	BStCC01...H, TD3F...H, TD4F...H
ESM 229M/450....750	Tho	F-Thy+Di	TV-HA, 450...750V, 5A, Igt<60mA, <5µs		22a	TO-66	17089*	17f	BStCC01...R, TD3F...R, TD4F...R
ESM 231(N)	Tho	LIN-IC	LF Out, 15W(18V/4Ω)		14-QIP+d				TBA 790, TCA 150, TDA 1042
ESM 249R/500	Tho	F-Thy+Di	500V, 5A, Igt<60mA, <25µs		22a	TO-66	TD 3FP 800H*	17f	TD3F500H, TD4F500H, S 6087B
ESM 261	Tho	Si-P-Darl	LF P, 60/60V, 10A, 70W, >4MHz, hFE>1000	{ESM217	17j	TO-220	BDW 94 C	17j	BDT 62(A...C), BDW 94A...C, BDX 34A...D, ++
ESM 262	Tho	Si-P-Darl	=ESM 261: 80/80V	{ESM218	17j	TO-220	BDW 94 C	17j	BDT 62A...C, BDW 94B...C, BDX 34B...D, ++
ESM 273	Tho	LIN-IC	=TDA 1104(SP)		17-SQL				TDA 1104(SP)
ESM 302 EV	Tho	CMOS-IC	Rhythmus-Generator/Rhythm Generator		16-DIP				-
ESM 303	Tho	LIN-IC	Motor Control						-
ESM 310(BP)	Tho	LIN-IC	=TDA 1100(SP)		11-SIL				TDA 1100(SP)
ESM 312	Tho	LIN-IC	Motorregler/Speed Control, 3...18V, 1A		8-DIP+b				-
ESM 313/....R	Tho	F-Thy	100...600V, 40A, Igt/Ih<150/<200mA, <5µs		23a	TO-3			-
ESM 352	Tho	LIN-IC	=TEA 1000		14-DIP				TEA 1000
ESM 374	Tho	Z-IC	+12V, 140mA		7c	TO-92	78L12/TO-92	7b	-
ESM 375....	Tho	LIN-IC	=TEA 1035....		....-DIP				TEA 1035....
ESM 400(A)	Tho	Si-N	TV-VA, 170V, 1,5A, 20W, 1MHz		17j	TO-220	2SD1138	17j	BD 239E, 2SD386, 2SD578, 2SD1138, ++
ESM 416	Tho	LIN-IC	=SAY 115: Fig. ›		14-DIP				(SAY 115)
ESM 427	Tho	LIN-IC	Ionisations-Rauchmelder/Smoke Detector		14-DIP				-
ESM 432	Tho	LIN-IC	=ESM 432C: Fig. ›		14-QIP				-
ESM 432 C	Tho	LIN-IC	=ESM 532 C: 30V, 3,5A, 20W(28V/4Ω)		11-SIL				ESM 532 C, TDA 1111
ESM 432 N	Tho	LIN-IC	=ESM 432C: Fig. ›		14-QIP+d				-
ESM 463	Tho	LIN-IC	=TEA 1001		17-SQL				TEA 1001
ESM 504/....	Tho	50Hz-Thy	50...600V, 4A=(Tc=75°), Igt/Ih<20/<50mA, 25µs		17e	TO-220	TAG 626-600	17e	TAG 630-..., TAG 620-..., TIC 116..., ++
ESM 508/....	Tho	50Hz-Thy	50...600V, 8A=(Tc=75°), Igt/Ih<40/<60mA		17e	TO-220	TAG 626-600	17e	TAG 655-..., 2N6394...6399, BStD10..., ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
ESM 509/....	Tho	50Hz-Thy	50...600V, 10A=(Tc=75°), Igt/Ih<40/<60mA		17e	TO-220			2N6394...6399, BStD10..., BT 152/..., ++
ESM 532	Tho	LIN-IC	=ESM 532C: Fig. ›		14-QIP				-
ESM 532 C	Tho	LIN-IC	LF Out, 32V, 3,5A, 20W(28V/4Ω)		11-SIL				TDA 1111(SP)
ESM 532 N	Tho	LIN-IC	=ESM 532C: Fig. ›		14-QIP+d				-
ESM 566	Tho	LIN-IC	=TEB 1013: ohne Basisvorwdst./wo. Base Resistor		11-SIL				(L 702SP, TEB 1013)
ESM 567	Tho	LIN-IC	=TEA 1034		16-DIP				TEA 1034
ESM 568 A	Tho	LIN-IC	=TEA 2015A		13-SQL				TEA 2015A
ESM 573 C	Tho	LIN-IC	=TEA 1020(SP)		17-SQL				TEA 1020(SP)
ESM 585	Tho	IC	Teletext-Demodulator (Antiope)						-
ESM 586	Tho	IC	Teletext-Demodulator (Antiope)						-
ESM 620	Tho	LIN-IC	=TDA 1099		11-SIL				TDA 1099
ESM 621	Tho	LIN-IC	=TDA 1098		14-DIP				TDA 1098
ESM 631 CM	Tho	LIN-IC	Näherungsschalter/Proximity Detector, 4...35V		TO-99				-
ESM 631 DP	Tho	LIN-IC	=ESM 631CM: Fig. ›		8-DIP				-
ESM 631 FP	Tho	LIN-IC	=ESM 631CM: SMD		8-MDIP				-
ESM 632 C	Tho	LIN-IC	=ESM 532 C: 26V, 3,5A, 14W(24V/4Ω)		11-SIL				ESM 532 C, TDA 1111
ESM 700	Tho	Z-IC	=TCA 700		14d				›TCA 700
ESM 707	Tho	LIN-IC	Tacho-Generator		8-DIP				-
ESM 732 C	Tho	LIN-IC	=ESM 532 C: 18V, 3,5A, 8W(14V/4Ω)		11-SIL				ESM 532 C, TDA 1111
ESM 740(G)	Tho	Thy	asym. -5...300V, 10A, Igt<50mA, <15µs		30b	(TO-220MF)	ESM 740*	30b	-
ESM 900	Tho	LIN-IC	=TCA 900: Fig. ›		5	TO-72			-
ESM 901	Tho	LIN-IC	=TCA 900: Fig. ›		4-DIP+b				-
ESM 910	Tho	LIN-IC	=TCA 910: Fig. ›		5	TO-72			-
ESM 911	Tho	LIN-IC	=TCA 910: Fig. ›		4-DIP+b				-
ESM 1231 C	Tho	LIN-IC	=TDA 1103(SP)		11-SIL				TDA 1103(SP)
ESM 1350 P	Tho	LIN-IC	TV IF, AM/FM IF		8-DIP				MC 1350
ESM 1406	Tho	Z-IC	+6V, 0,78A		14b	TO-126	7806/TO-220	17b	... 78N06 (TO-126)
ESM 1410	Tho	Z-IC	+10V, 0,68A		14b	TO-126	7810/TO-220	17b	... 78N10 (TO-126)
ESM 1532 C	Tho	LIN-IC	=TDA 1102(SP)		11-SIL				TDA 1102(SP), TDA 1111(SP)
ESM 1600 B	Tho	KOP-IC	Quad, Pegelumsetzer/Level Shift		14-DIP				-
ESM 1600 BFP	Tho	KOP-IC	=ESM 1600B: SMD		14-MDIP				-
ESM 1601	Tho	LIN-IC	=TDE 1064, TDF 1064						TDE 1064, TDF 1064
ESM 1602 B	Tho	KOP-IC	Quad, Pegelumsetzer/Level Shift		14-DIP				-
ESM 1631 CM	Tho	LIN-IC	=ESM 631CM: 4...20V		TO-99				ESM 631CM
ESM 1631 DP	Tho	LIN-IC	=ESM 631DP: 20V		8-DIP				ESM 631DP
ESM 1631 FP	Tho	LIN-IC	=ESM 631FP: 20V		8-MDIP				ESM 631FP
ESM 1637	Tho	KOP-IC	50V, 1A		TO-99/6Pin				-
ESM 2633	Tho	Si-N	=2N3055		23a	TO-3	2N3055	23a	›2N3055
ESM 2666	Tho	Si-N	S P, 1500/600V, 6A, 75W(Tc=95°), sat<5V(5A)		23a	TO-3	BU 508 A	18j	BU 508A, 2SD350A, 2SD649, 2SD821,++
ESM 2667	Tho	Si-N	=ESM2666: 1500/700V		23a	TO-3	BU 508 A	18j	BU 508A, 2SD350A, 2SD821, 2SD649,++
ESM 2668	Tho	Si-N	=BU 526		23a	TO-3	›BU 526		›BU 526
ESM 2725	Tho	Si-N	=BF 459				BF 459	14h	›BF 459
ESM 2731	Tho	Si-N	=BU 526		23a	TO-3	›BU 526		›BU 526
ESM 2808	Tho	Si-N+Di	=BU 800		23a	TO-3	BU 208 D	23a	›BU 800
ESM 4629	Tho	Thy			17	TO-220			-
ESM 7040	Tho	MOS-IC	8x Latch & Driver, 50V, 0,5A		24-DIP				-
ET....EZ									
ET		Si-N	=2SC4120 (SMD-Marking)		35	SOT-23			›2SC4120
ET		Si-N-Darl	=2SD1471-ET (SMD-Marking)		39	SOT-89			›2SD1471
ET		GaAs-N-FET-d	=3SK273 (SMD-Marking)		44	SOT-143			›3SK273
ET		Si-N	=BCW 65RA (SMD-Marking)		35	SOT-23			›BCW 65RA
ET		Z-Di	=SM 6T 33A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
ET 2128(J,N)....	Tho	sRAM-IC	2k x 8Bit, 150...200ns		24-DIP				... 4016...
ET 2147 H....	Tho	sRAM-IC	4k x 1Bit, 35...70ns		18-DIP				... 2147...
ET 2716 Q....	Tho	EPROM-IC	2k x 8Bit, 350...450ns, 525/132mW		24-DIP				... 2716...
ET 2764 Q....	Tho	EPROM-IC	8k x 8Bit, 150...450ns, 525/132mW		28-DIP				... 2764...
ET 4116 J,N....	Tho	dRAM-IC	16k x 1Bit, 150...200ns		16-DIP				... 4116...
ET 4164 J,N....	Tho	dRAM-IC	64k x 1Bit, 150...200ns		16-DIP				... 4164...
ET 93...	Tho	µC-IC	8-Bit µComp.						-
ET 94...	Tho	µC-IC	4-Bit µComp.						-
ET 27128 Q....	Tho	EPROM-IC	16k x 8Bit, 150...450ns, 525/105mW		28-DIP				... 27128...
ET 90400	Tho	µC-IC	4-Bit µComp.						-
ETC 2716 Q....	Tho	EPROM-IC	2k x 8Bit, 350...450ns		24-DIP				... 2716...
ETC 2732 Q....	Tho	EPROM-IC	4k x 8Bit, 350...450ns		24-DIP				... 2732...
ETC 5040	Tho	CMOS-IC	Telecom, PCM Codec-Filter		16-DIP				M 5912, KT 3040, TP 3040, µA 5912, 2912
ETC 5051	Tho	CMOS-IC	Telecom, 1-Kanal/Channel µ-Law Par.-Combo		20-DIP				-
ETC 5054	Tho	CMOS-IC	Telecom, 1-Kanal/Channel µ-Law Ser.-Combo		16-DIP				-
ETC 5054	Tho	CMOS-IC	›KT 3030, KT 8554		16-DIC				KT 3030, TP 3054, µA 3054, 2916
ETC 5056	Tho	CMOS-IC	Telecom, 1-Kanal/Channel A-Law Par.-Combo		20-DIP				-
ETC 5057	Tho	CMOS-IC	Telecom, A-Law Combo Codec		16-DIP				KT 3032, TP 3057, µA 3057, 2917
ETC 5064	Tho	CMOS-IC	Telecom, µ-Law Combo Codec		20-DIP				KT 3031, KT 3064, TP 3064
ETC 5067	Tho	CMOS-IC	Telecom, A-Law Combo Codec		20-DIP				KT 3033, TP 3067
ETC 92...	Tho	µC-IC	16-Bit µComp.						-
ETC 93...	Tho	µC-IC	8-Bit µComp.						-
ETC 94...	Tho	µC-IC	4-Bit µComp.						-
ETL 2128(J,N)....	Tho	sRAM-IC	2k x 8Bit, 150...200ns		24-DIP				... 4016...
ETL 2147 H....	Tho	sRAM-IC	4k x 1Bit, 55...70ns		18-DIP				... 2147...
ETL 93...	Tho	µC-IC	8-Bit µComp.						-
ETL 94...	Tho	µC-IC	4-Bit µComp.						-
EU		Si-N	=BCW 65RB (SMD-Marking)		35	SOT-23			›BCW 65RB
EU		Z-Di	=SM 6T 36 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
EU (0)1(A,Z)	Sak	Si-Di	FRr, 200...600V, 0,25A, Uf<2,5V(0,25A), 400ns EU(0)1=400V, A=600V, Z=200V		31a	SOD-22	BA 159	31a	BA 157...159, BY 204/..., BYX 57/...
EU (0)2(A,Z)	Sak	Si-Di	FRr, 200...600V, 1A, Uf<1,4V(1A), 400ns EU(0)2=400V, A=600V, Z=200V		31a	SOD-22	BYD 33 M	31a	BYD 33J...M, BYT 11/600, BYT 52J...M,++
EU 2 YX	Sak	Si-Di	FRr, 100V, 1,2A, Uf<0,9V(1,2A), 200ns		31a	SOD-22	BYD 33 M	31a	BYD 33D...M, BYT 11/600, BYT 52B...M,++
EV		PIN-Di	=1SV241 (SMD-Marking)		45	SOT-153			›1SV241
EV		Z-Di	=SM 6T 36A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
EW		Si-N	=BCW 65RC (SMD-Marking)		35	SOT-23			›BCW 65RC
EW		Z-Di	=SM 6T 39 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
EX		Si-N	=2SD2402-EX (SMD-Marking)		39	SOT-89			›2SD2402
EX		Si-N	=BCW 66RF (SMD-Marking)		35	SOT-23			›BCW 66RF

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
EX		Z-Di	=SM 6T 39A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
EX 0022 TA		Z-Di	11,5V		31a		Z-Diode 11V	31a	
EX 0048 CE		Z-Di	6,2V		31a		Z-Diode 6,2V	31a	
EX 0074 CE		Z-Di	115V		31a		Z-Diode 110V	31a	
EXB 919	Fjd	Hybrid-Z-IC	Z-IC, +100V, 0,2A						-
EY		Si-N	=2SC2882-Y (SMD-Marking)		39	SOT-89			›2SC2882
EY		Si-N	=2SC3265-Y (SMD-Marking)		35	SOT-23			›2SC3265
EY		Si-N	=2SC3398 (SMD-Marking)		35	SOT-23			›2SC3398
EY		Si-N	=2SC4398 (SMD-Marking)		35(2mm)	SOT-323			›2SC4398
EY		Si-N	=2SD2402-EY (SMD-Marking)		39	SOT-89			›2SD2402
EY		Si-N	=BCW 66RG (SMD-Marking)		35	SOT-23			›BCW 66RG
EY		Si-N	=KTC3265-Y (SMD-Marking)		35	SOT-23			›KTC 3265
EY		Si-N	=KTC4374-Y (SMD-Marking)		39	SOT-89			›KTC 4374
EYV-320(D)		Si-Di	=BA 127		31a		1N4148	31a	›BA 127
EZ		Si-N	=2SD2402-EZ (SMD-Marking)		39	SOT-89			›2SD2402
EZ		Si-N	=BCW 66RH (SMD-Marking)		35	SOT-23			›BCW 66RH
EZ-055....-372	Njr	Z-Di	5...37V, 0,4W		31a	DO-41	Z-Diode V	31a	BZX55/..., BZX83/..., ZPD..., 1N5231...58,++
F									
F		Si-N	=2SC4399 (SMD-Marking)		35(2mm)	SOT-323			›2SC3499
F 1		Si-N	=2SC1009-F1 (SMD-Marking)		35	SOT-23			›2SC1009
F 1(p)		Si-N	=BFS 18 (SMD-Marking)		35	SOT-23			›BFS 18
F 1 E23	Shi	MOS-N-FET-e	=2SK1195						
F 1 E50	Shi	MOS-N-FET-e	=2SK1672						
F 1 E90	Shi	MOS-N-FET-e	=2SK1533						
F10		Si-P	=KSA 1182-O (SMD-Marking)		35	SOT-23			›KSA 1182
F1Y		Si-P	=KSA 1182-Y (SMD-Marking)		35	SOT-23			›KSA 1182
F 2		Si-N	=2SC1009-F2 (SMD-Marking)		35	SOT-23			›2SC1009
F 2		Si-N	=2SC2814-F2 (SMD-Marking)		35	SOT-23			›2SC2814
F 2(p)		Si-N	=BFS 19 (SMD-Marking)		35	SOT-23			›BFS 19
F02		N-FET	=SO 4091 (SMD-Marking)		35	SOT-23			›SO 4091
F 3		Si-Di	=1SS193 (SMD-Marking)		35	SOT-23			›1SS193
F 3		Si-N	=2SC1009-F3 (SMD-Marking)		35	SOT-23			›2SC1009
F 3		Si-N	=2SC2814-F3 (SMD-Marking)		35	SOT-23			›2SC2814
F 3		Si-N	=BF 840 (SMD-Marking)		35	SOT-23			›BF 840
F03		N-FET	=SO 4391 (SMD-Marking)		35	SOT-23			›SO 4391
F 3 T		Si-Di	=1PS193 (SMD-Marking)		35	SOT-23			›1PS193
F 3 V50	Shi	MOS-N-FET-e	=2SK1244						
F 3 V90	Shi	MOS-N-FET-e	=2SK1534						
F 3 W90	Shi	MOS-N-FET-e	=2SK1536						
F 4		Si-N	=2SC1009-F4 (SMD-Marking)		35	SOT-23			›2SC1009
F 4		Si-N	=2SC2814-F4 (SMD-Marking)		35	SOT-23			›2SC2814
F 4		Si-N	=BFS 18R (SMD-Marking)		35	SOT-23			›BFS 18R
F 5		Si-Di	=1SS250 (SMD-Marking)		35	SOT-23			›1SS250
F 5		Si-Di	=1SS370 (SMD-Marking)		35(2mm)	SOT-323			›1SS370
F 5		Si-N	=2SC1009-F5 (SMD-Marking)		35	SOT-23			›2SC1009
F 5		Si-N	=2SC2814-F5 (SMD-Marking)		35	SOT-23			›2SC2814
F 5		Si-N	=BFS 19R (SMD-Marking)		35	SOT-23			›BFS 19R
F 05 E23	Shi	MOS-N-FET-e	=2SK1194						
F 5 V50	Shi	MOS-N-FET-e	=2SK1246						
F 5 W50	Shi	MOS-N-FET-e	=2SK1537						
F 6		Si-N	=2SC2223-F6 (SMD-Marking)		35	SOT-23			›2SC2223
F 6 V25	Shi	MOS-N-FET-e	=2SK1391						
F 7		Si-Di	=HSM 83 (SMD-Marking)		35	SOT-23			›HSM 83
F07		N-FET	=SO 4392 (SMD-Marking)		35	SOT-23			›SO 4392
F 7 W90	Shi	MOS-N-FET-e	=2SK1538						
F 8(p)		Si-P	=BF 824 (SMD-Marking)		35	SOT-23			›BF 824
F08		N-FET	=SO 4393 (SMD-Marking)		35	SOT-23			›SO 4393
F 9		Si-Di	=1SS321 (SMD-Marking)		35	SOT-23			›1SS321
F09		N-FET	=SO 3966 (SMD-Marking)		35	SOT-23			›SO 3966
F10		N-FET	=SO 4092 (SMD-Marking)		35	SOT-23			›SO 4092
F 10 V25	Shi	MOS-N-FET-e	=2SK1393						
F 10 W50	Shi	MOS-N-FET-e	=2SK1248						
F 10 W90	Shi	MOS-N-FET-e	=2SK1539						
F 11		N-FET	=SO 4093 (SMD-Marking)		35	SOT-23			›SO 4093
F 12		Si-N	=2SC2223-F12(SMD-Marking)		35	SOT-23			›2SC2223
F 12		Si-N	=2SC4178-F12 (SMD-Marking)		35(2mm)	SOT-323			›2SC4178
F 12		N-FET	=SO 245B (SMD-Marking)		35	SOT-23			›SO 245
F 13		Si-N	=2SC2223-F13(SMD-Marking)		35	SOT-23			›2SC2223
F 13		Si-N	=2SC4178-F13 (SMD-Marking)		35(2mm)	SOT-323			›2SC4178
F 13		N-FET	=BFR 30R (SMD-Marking)		35	SOT-23			›BFR 30R
F 14		N-FET	=BFR 31R (SMD-Marking)		35	SOT-23			›BFR 31R
F 14		Si-N	=2SC2223-F14(SMD-Marking)		35	SOT-23			›2SC2223
F 14		Si-N	=2SC4178-F14 (SMD-Marking)		35(2mm)	SOT-323			›2SC4178
F 14 A....J	Nec	Si-Di	Rr, Uni, 100...1000V, 1A, Uf<1V(1A), A=100, B=200V, C=300, D=400, E=500, F=600, H=800, J=1000V		31a	SOD-57	1N4007	31a	BY 126...127, BY 133...135, 1N4002...07, ++
F15		N-FET	=SO 5432 (SMD-Marking)		35	SOT-23			›SO 5432
F 15 W50	Shi	MOS-N-FET-e	=2SK1249						
F16		N-FET	=SO 5432R (SMD-Marking)		35	SOT-23			›SO 5432R
F17		N-FET	=SO 5433 (SMD-Marking)		35	SOT-23			›SO 5433
F18		N-FET	=SO 5433R (SMD-Marking)		35	SOT-23			›SO 5433R
F19		N-FET	=SO 5434 (SMD-Marking)		35	SOT-23			›SO 5433R
F20		N-FET	=SO 245BR (SMD-Marking)		35	SOT-23			›SO 245
F 20 W25	Shi	MOS-N-FET-e	=2SK1395						
F 20 W50	Shi	MOS-N-FET-e	=2SK1250						
F21		N-FET	=SO 245A (SMD-Marking)		35	SOT-23			›SO 245
F22		N-FET	=SO 4091R (SMD-Marking)		35	SOT-23			›SO 4091R
F23		N-FET	=SO 4391R (SMD-Marking)		35	SOT-23			›SO 4391R
F24		N-FET	=SO 245AR (SMD-Marking)		35	SOT-23			›SO 245AR
F25		N-FET	=SO 245C (SMD-Marking)		35	SOT-23			›SO 245C
F26		N-FET	=SO 245CR (SMD-Marking)		35	SOT-23			›SO 245CR
F27		N-FET	=SO 4392R (SMD-Marking)		35	SOT-23			›SO 4392R
F28		N-FET	=SO 4393R (SMD-Marking)		35	SOT-23			›SO 4393R